



UVA

SCHOOL *of* ENGINEERING
& APPLIED SCIENCE

Changing the nature and behavior of electron and phonon thermal transport with nanoscale interfaces



Patrick E. Hopkins

Professor

Dept. Mech. & Aero. Eng.

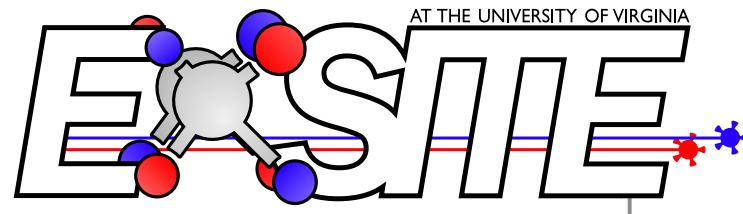
Dept. Mat. Sci. & Eng.

Dept. Physics

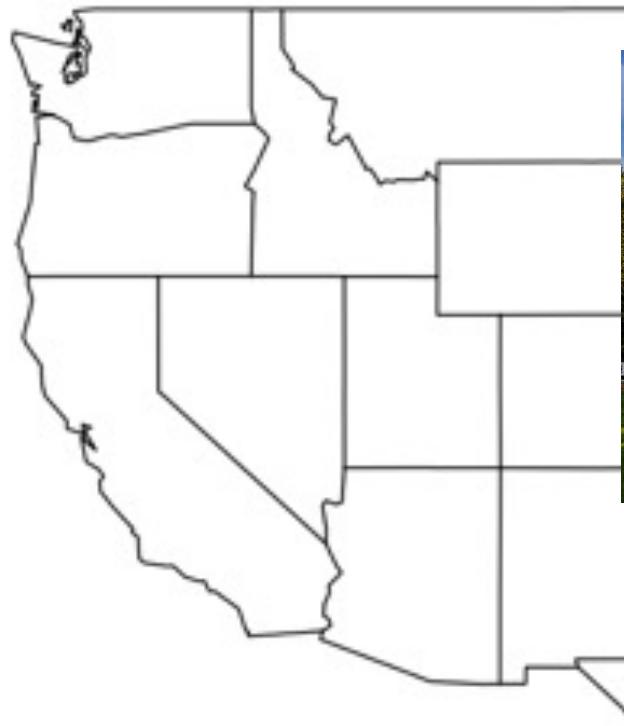
University of Virginia

phopkins@virginia.edu

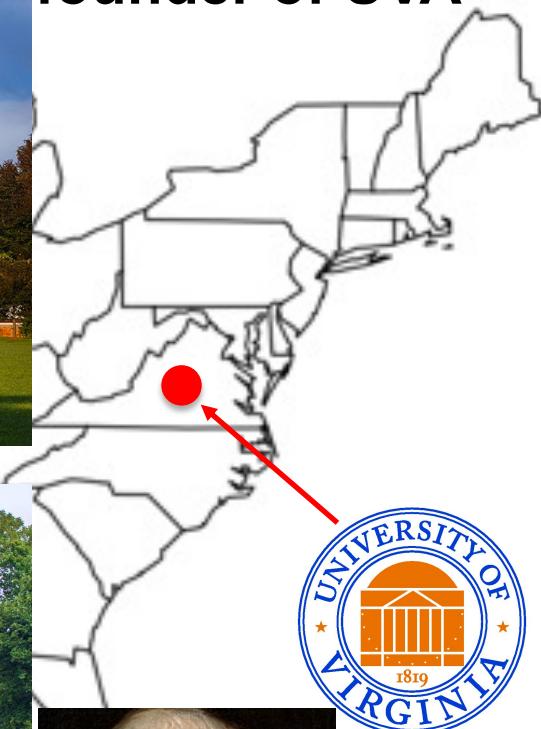
patrickehopkins.com



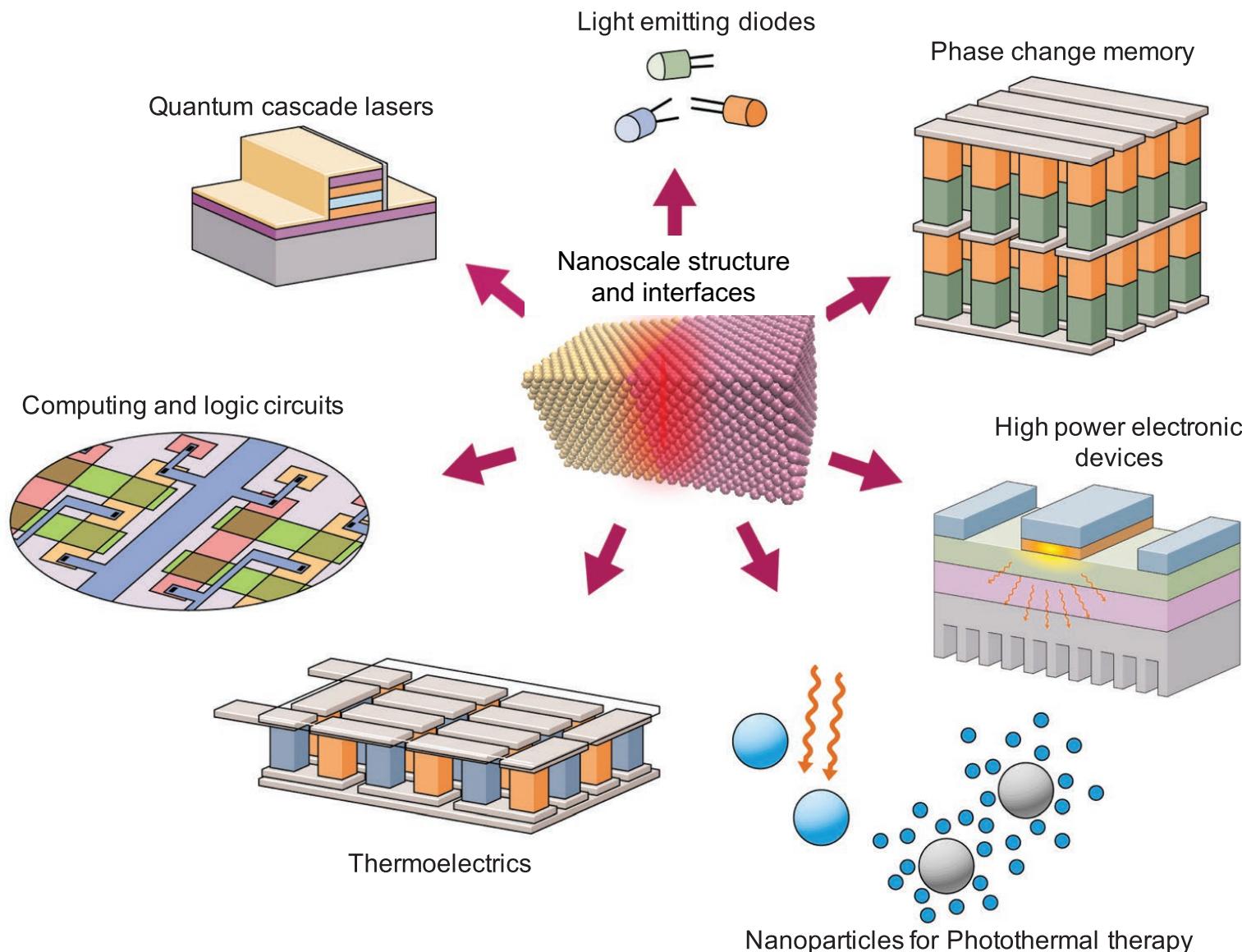
University of Virginia, Charlottesville, VA



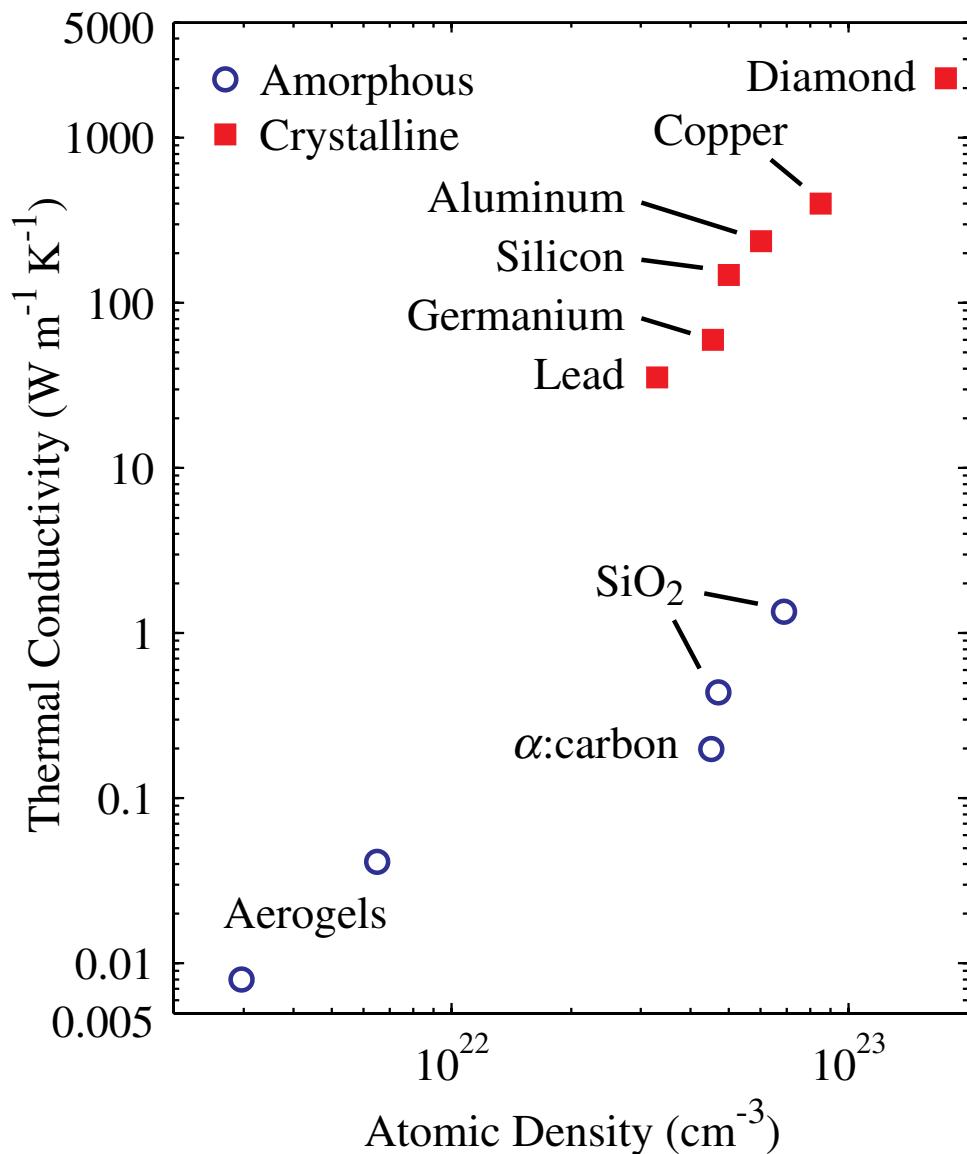
**Home to Thomas Jefferson
3rd US president
founder of UVA**



ExSiTE Lab: Experiments & Simulations in Thermal Engineering

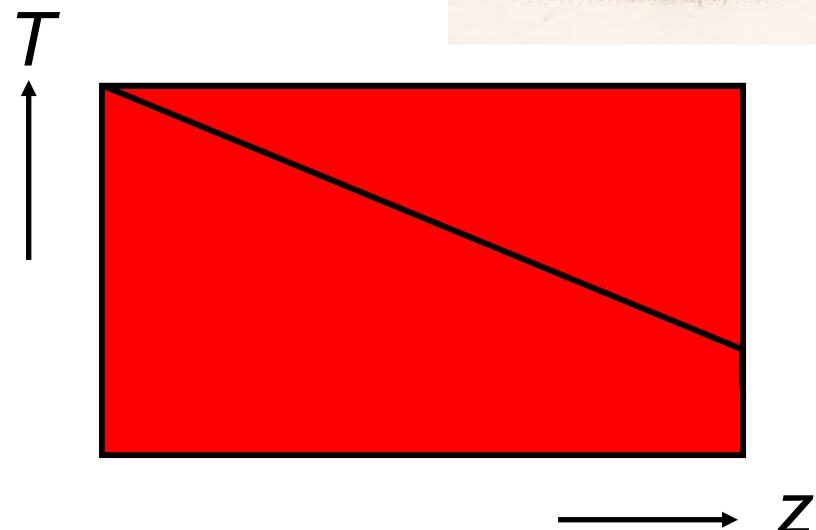


Thermal conductivity of materials – Macro/Microscopic

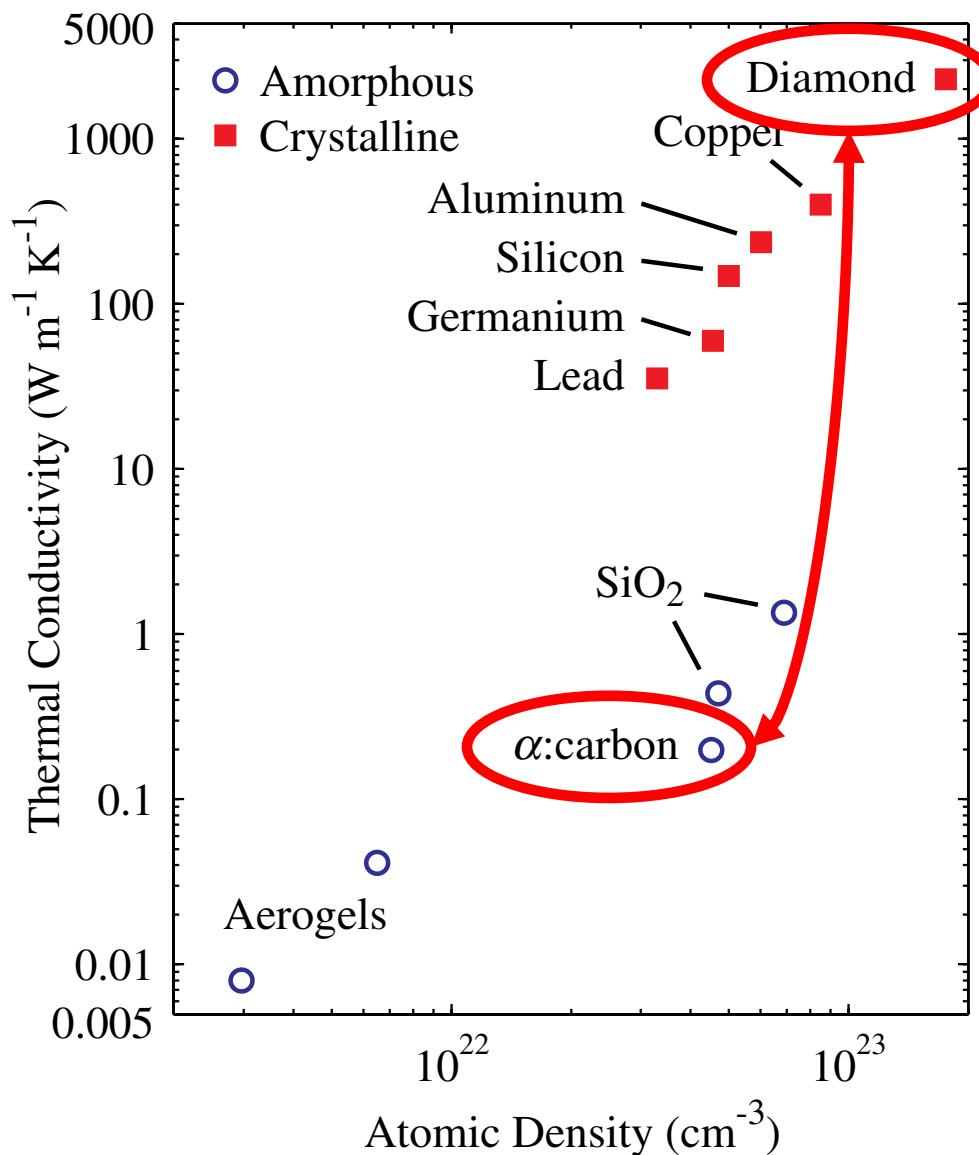


The Fourier Law

$$q = -\kappa \frac{\partial T}{\partial z}$$



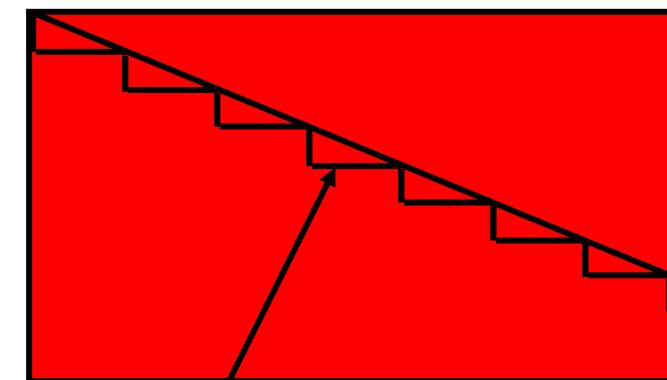
Thermal conductivity of materials – Macro/Microscopic



PRL 110, 015902 (2013)

The Fourier Law

$$q = -\kappa \frac{\partial T}{\partial z}$$



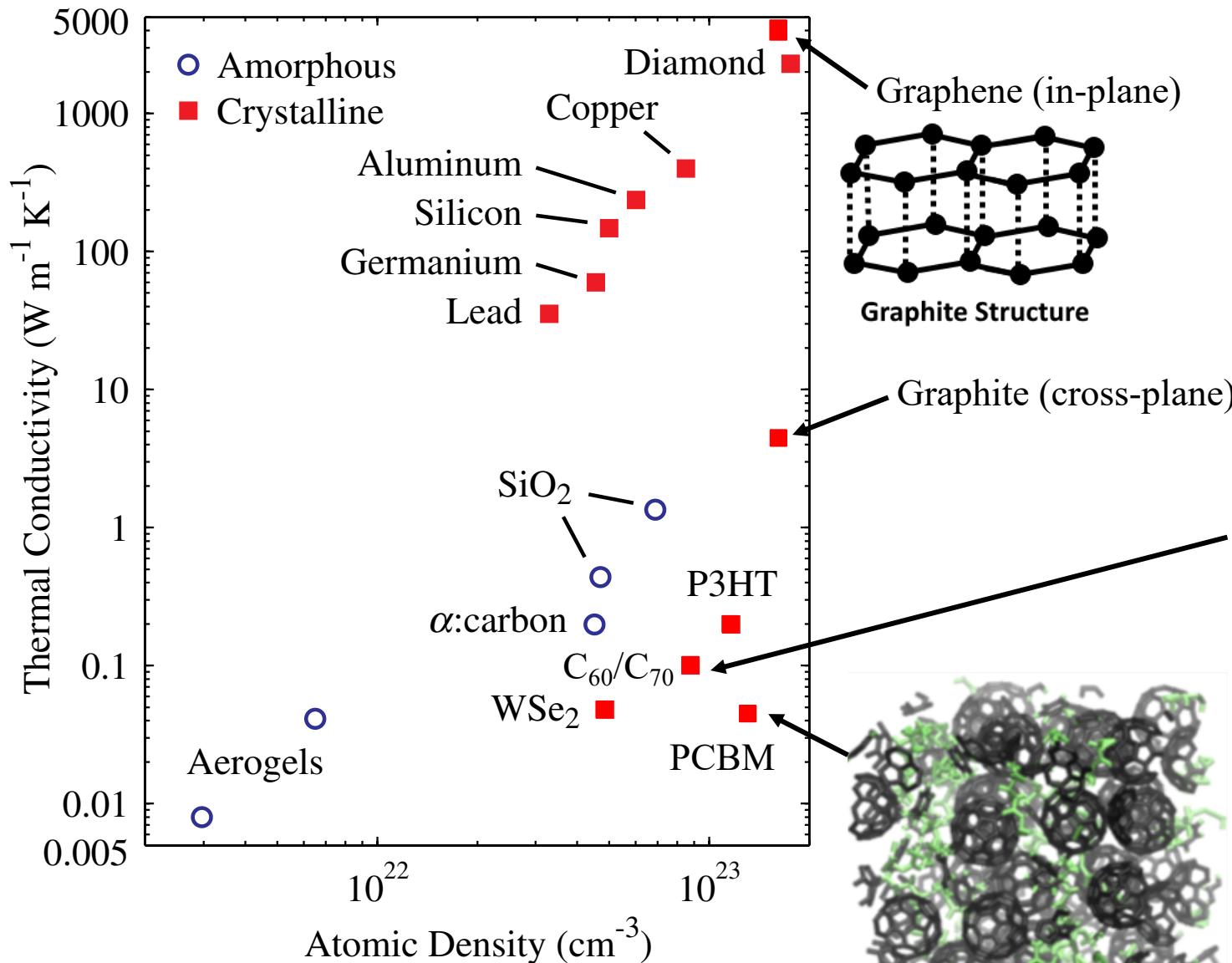
λ = Mean free path

$$\kappa = \frac{1}{3} Cv \lambda = \frac{1}{3} Cv_g^2 \tau$$

Heat capacity

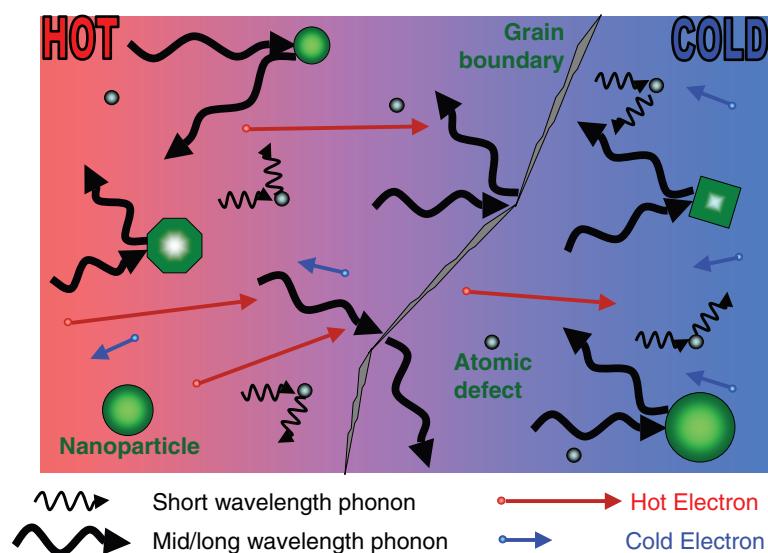
Velocity

Thermal conductivity of materials – Nanoscopic



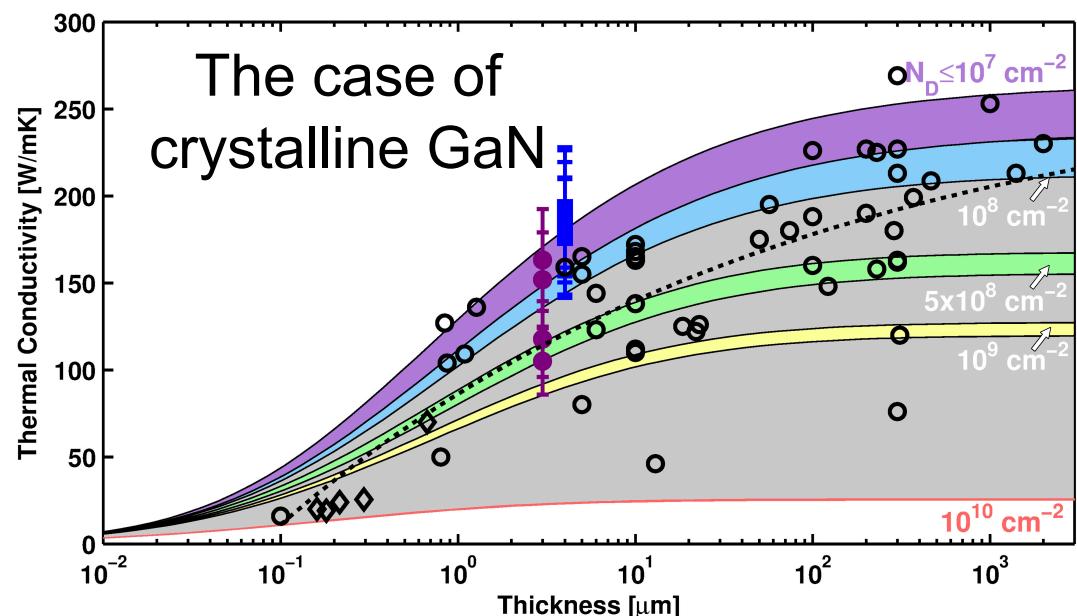
Thermal conductivity of materials – Nanoscale behavior

Well controlled and prescribed inclusions, defects, or **interfaces** change thermal conductivity based on manipulating the behavior of electrons and phonons



Adv. Mat. 22, 3970

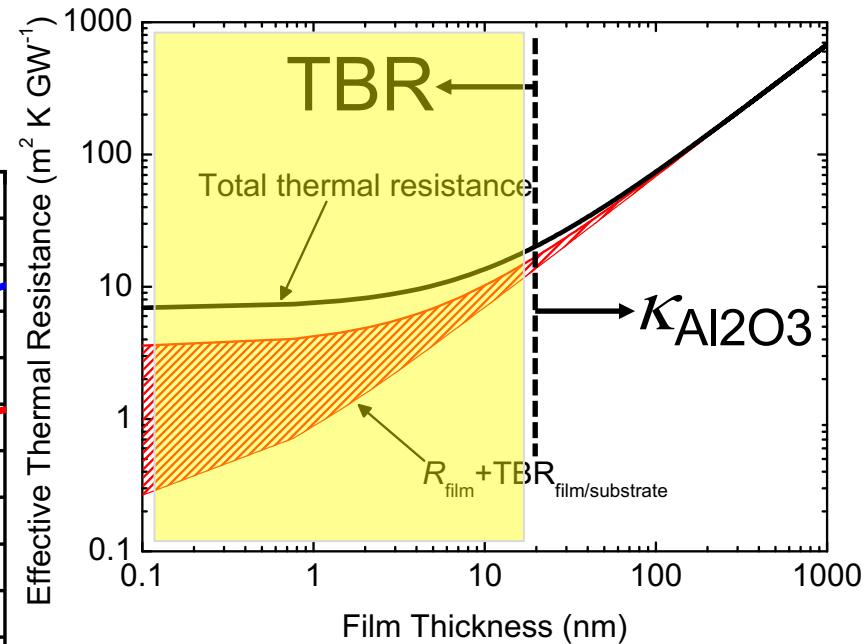
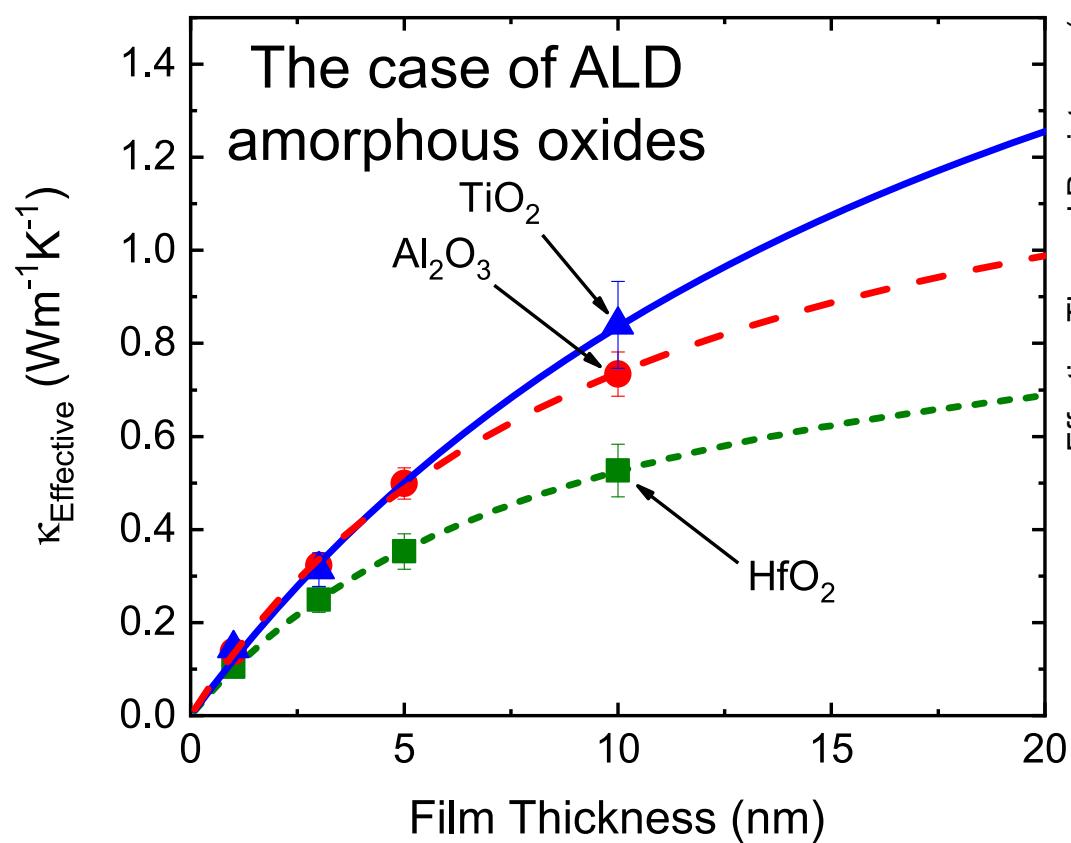
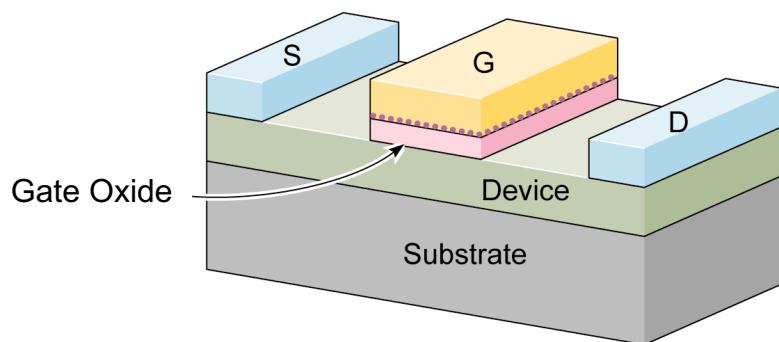
$$\kappa = \frac{1}{3} C v \lambda$$



J. Appl. Phys. 120, 095104

Interfaces critical when
thickness $< \lambda$

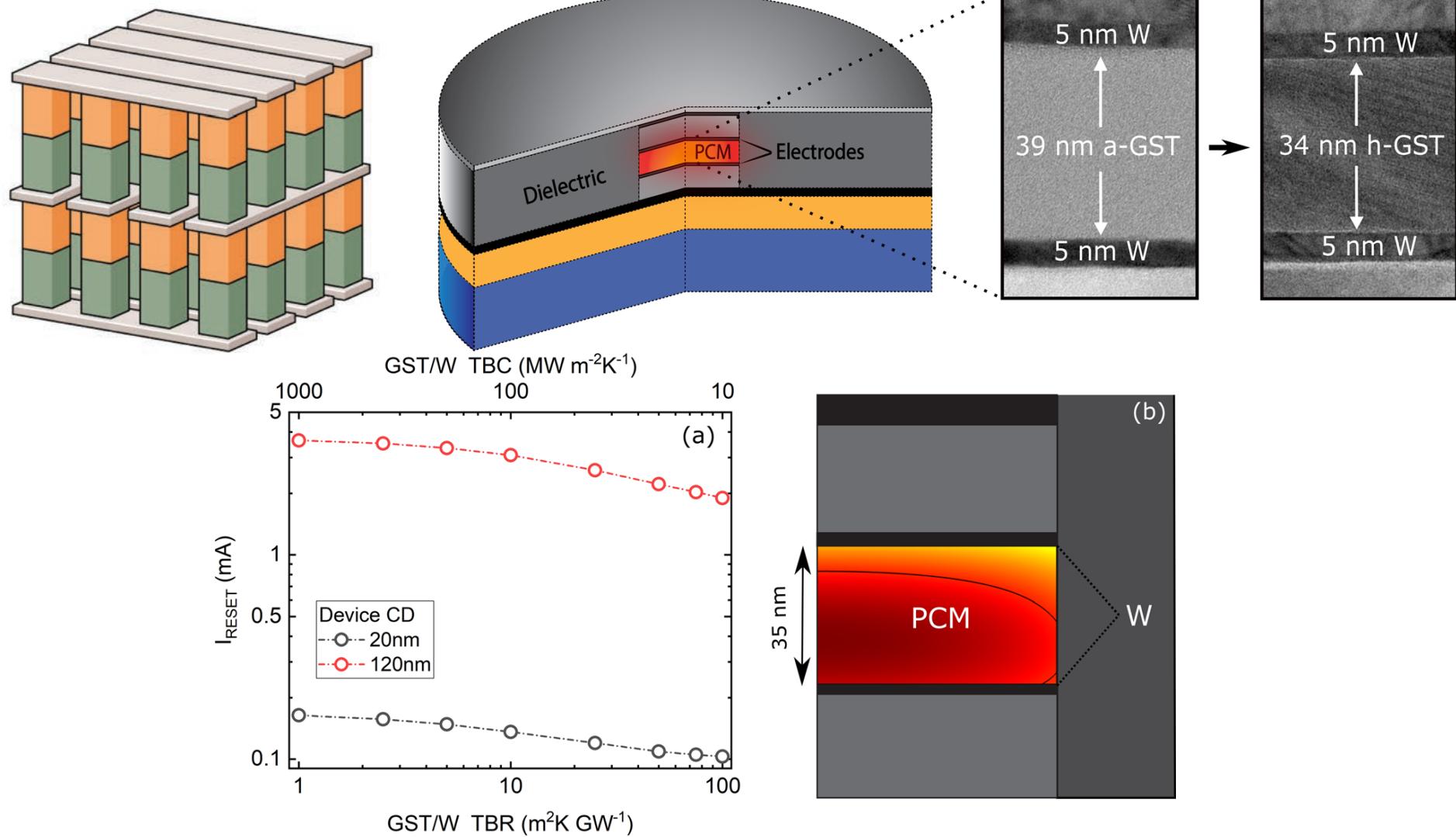
Thermal conductivity of materials – Nanoscale behavior



APL Materials 6, 058302

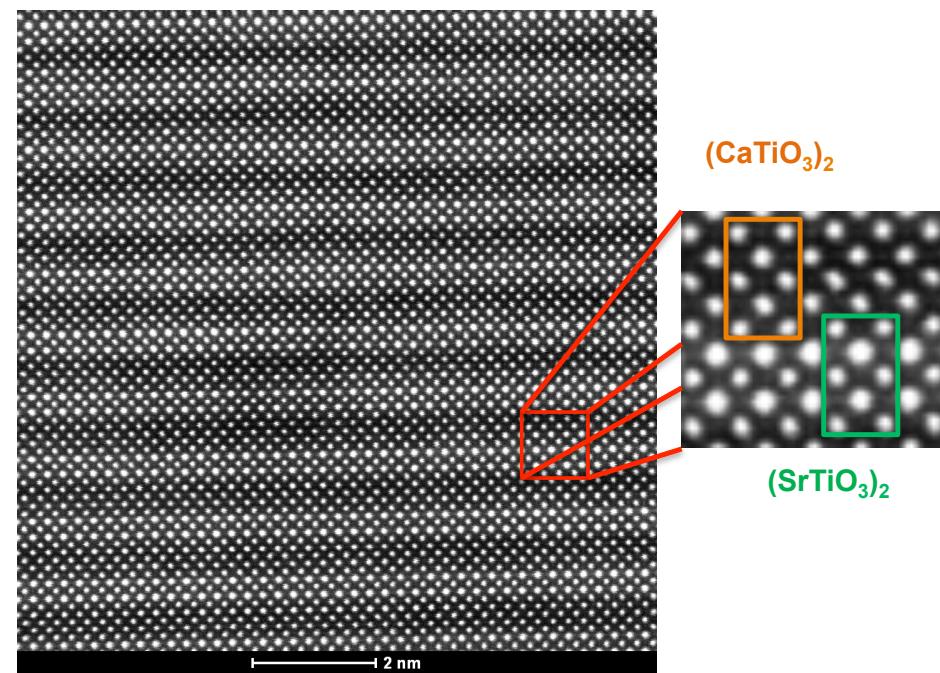
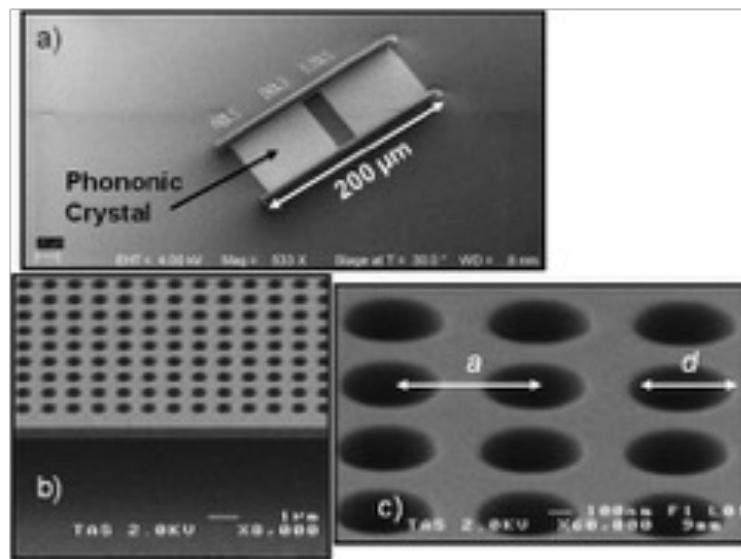
Nanoscale behavior impacts device functionality

Phase change memory



Thermal conductivity of materials – Nanoscale nature

Well controlled and ordered inclusions, defects, or interfaces change thermal conductivity based on manipulating the wave nature of electrons and phonons

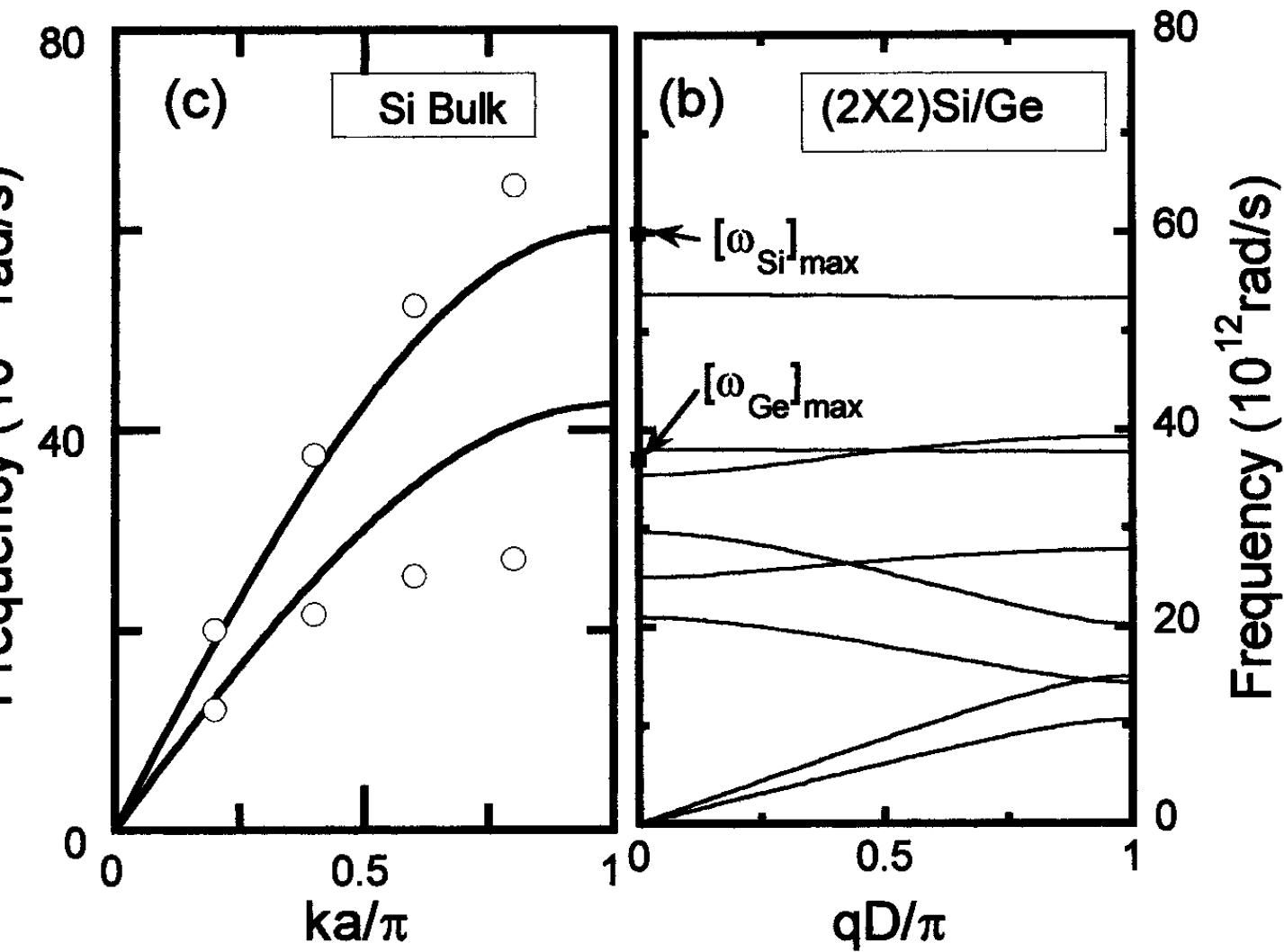
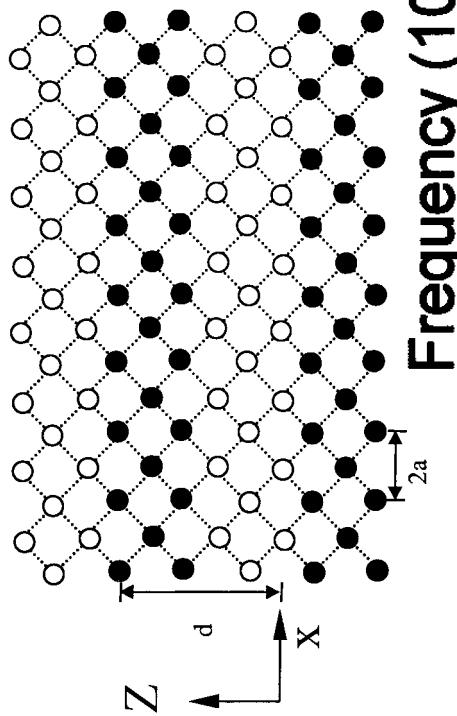


Nano Lett. 11, 107 (2011)

Nature Materials 13, 168 (2013)

Thermal conductivity of materials – Nanoscale nature

Ex: SLs can change phonon dispersions



Yang and Chen, *Microscale Thermophysical Engineering* 5, 107 (2001)

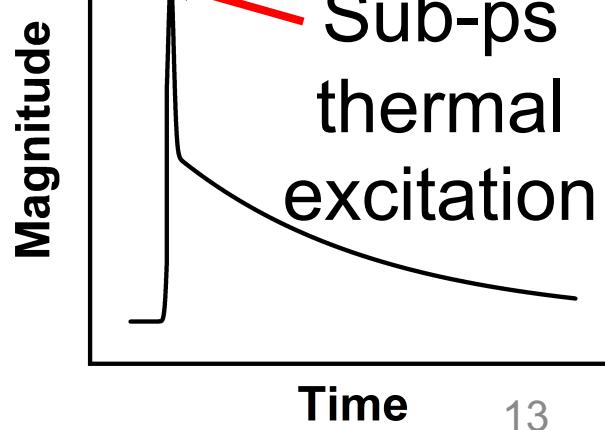
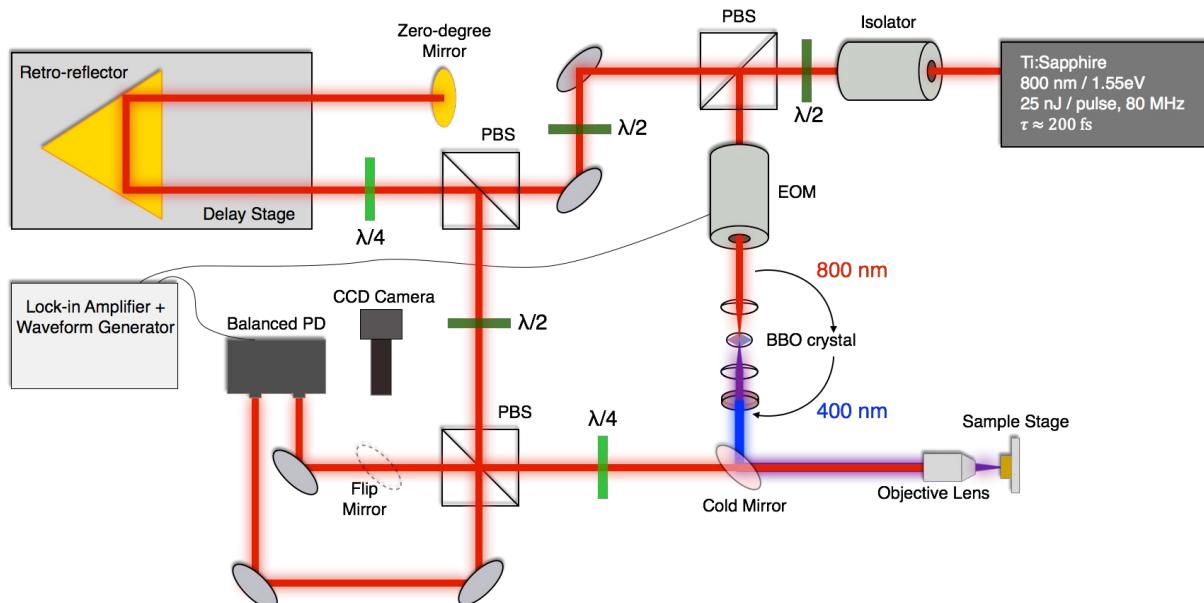
Outline

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- Thermal boundary conductance
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How do we measure the thermal properties? TDTR

Thin film or “near surface” measurements

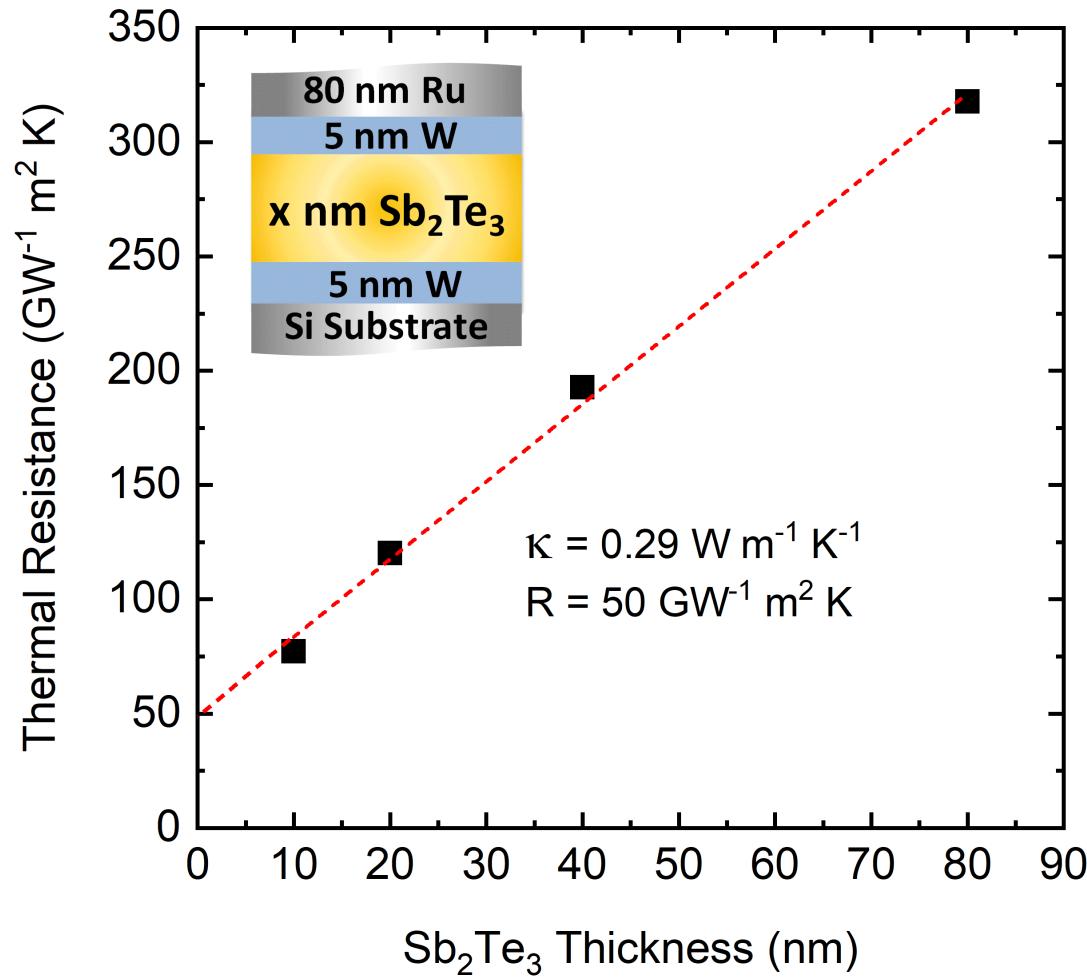
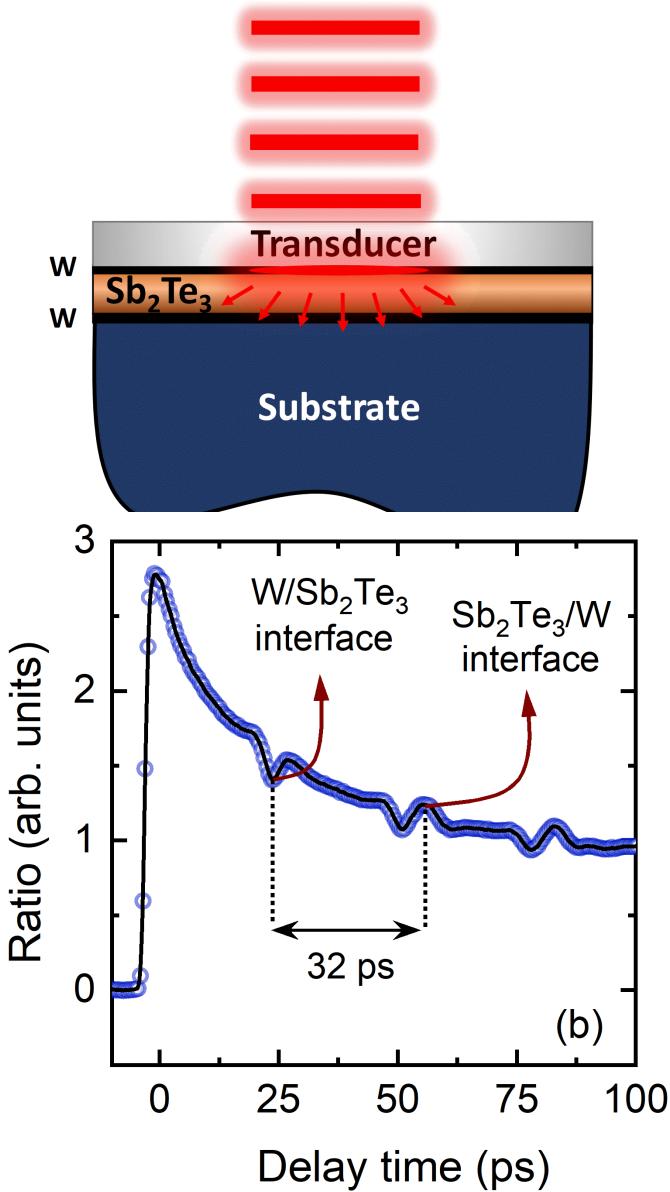


TDTR Reviews and Analyses

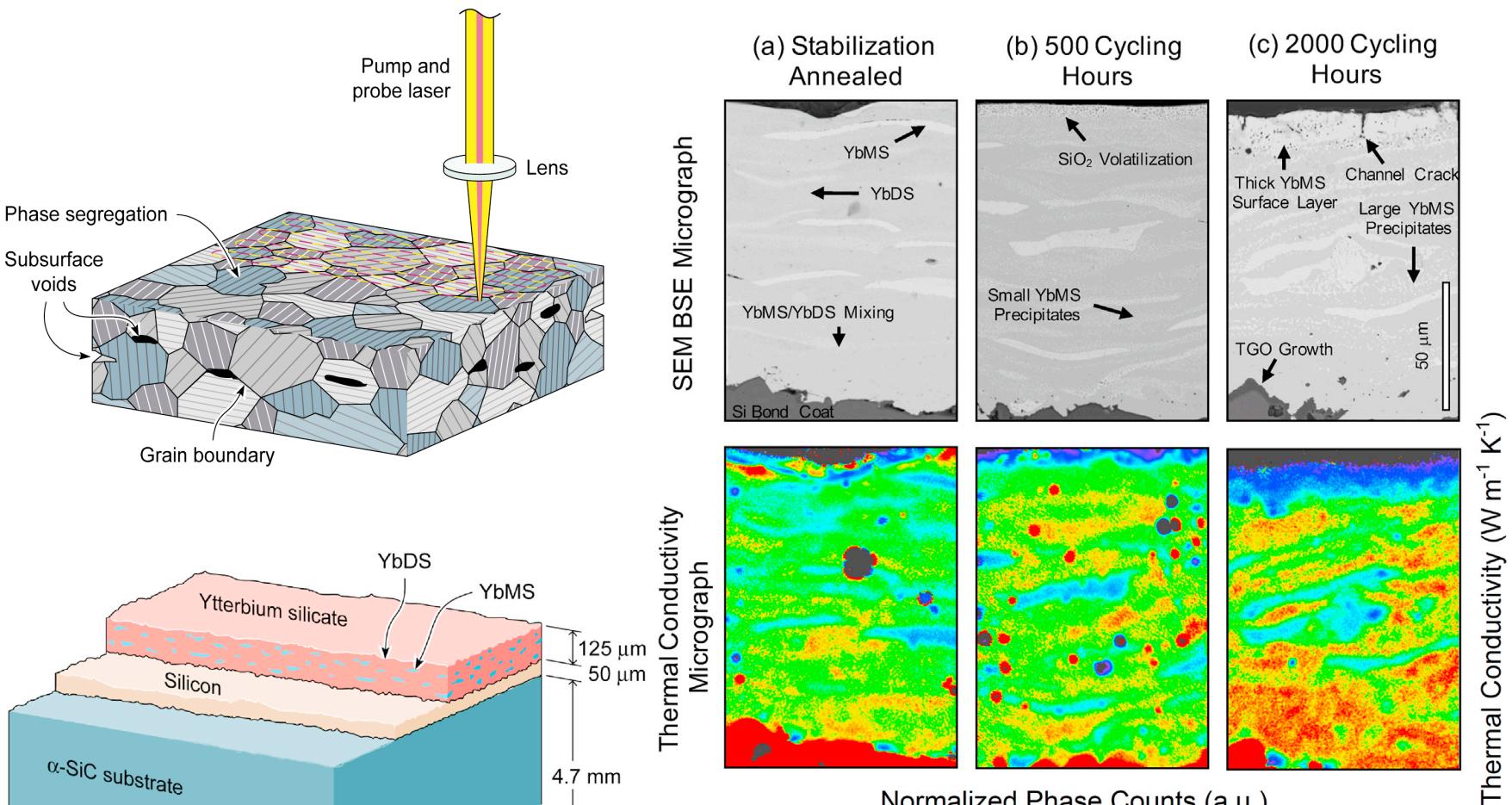
Rev. Sci. Instr. **75**, 5119;
Rev. Sci. Instr. **79**, 114902
J. Heat Trans. **132**, 081302;
Ann. Rev. Heat Trans. **16**, 159

Thermal conductivity ultrathin films

Collaboration w/ Van Dyck and Detavernier

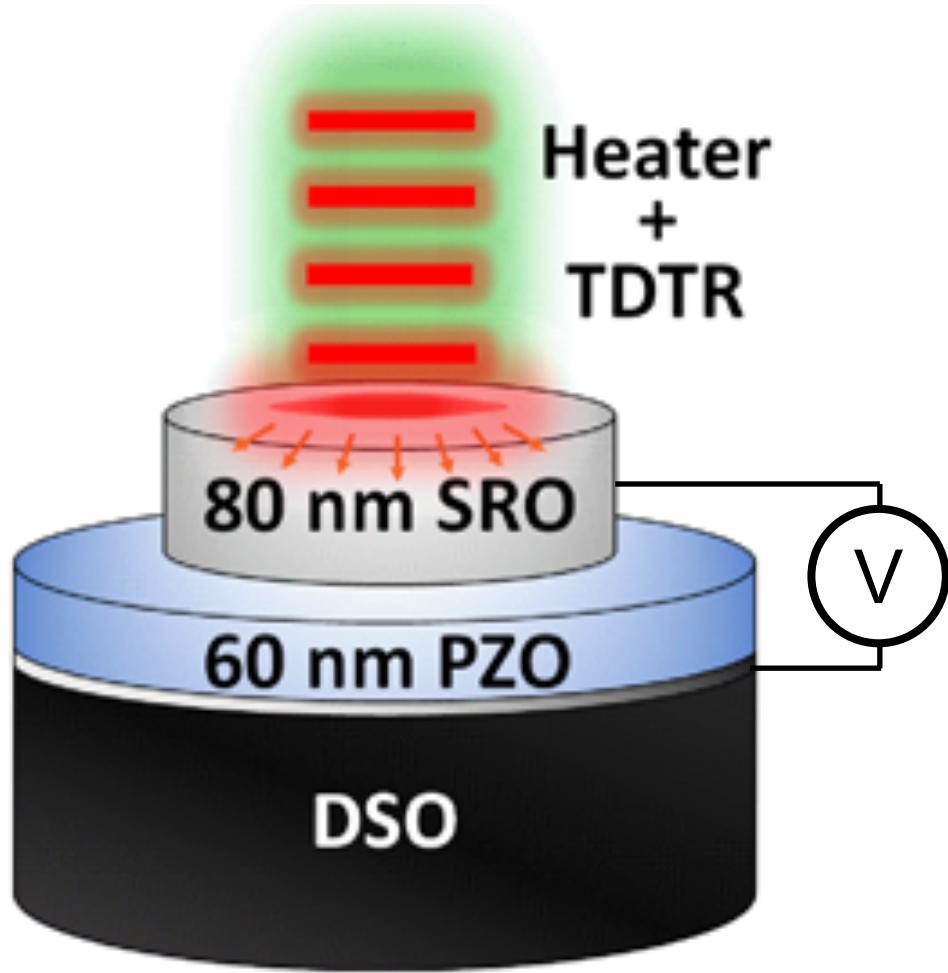


Local thermal conductivity measurements and spatial maps

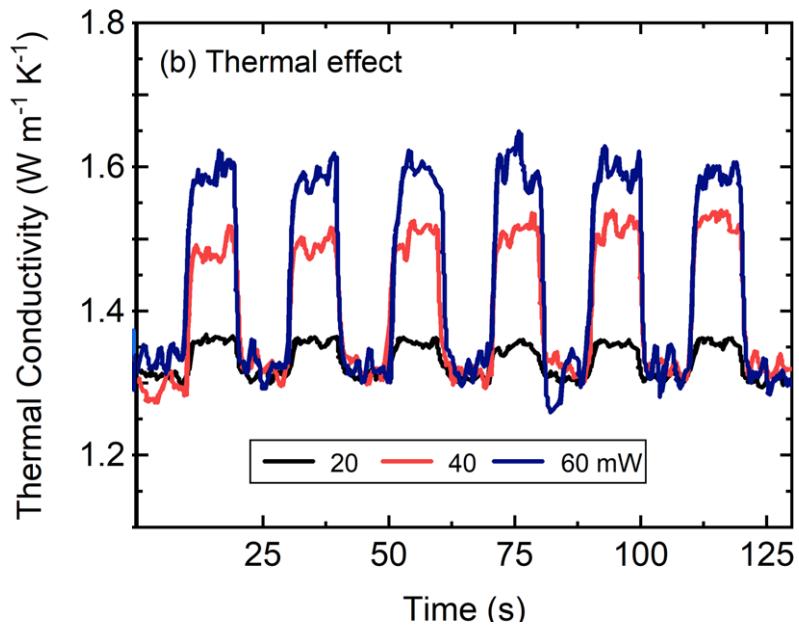
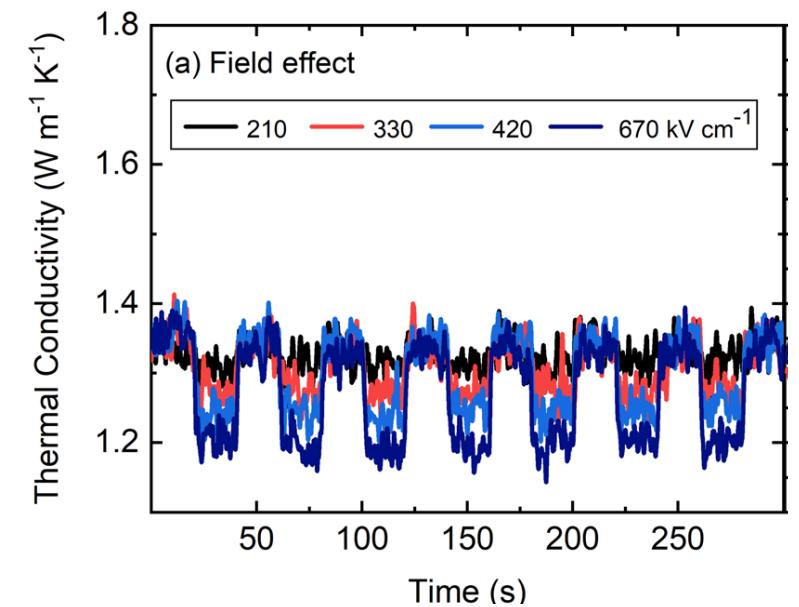


Olson *et al.*, *Materials Today Phys.*
17, 100304 (2021)

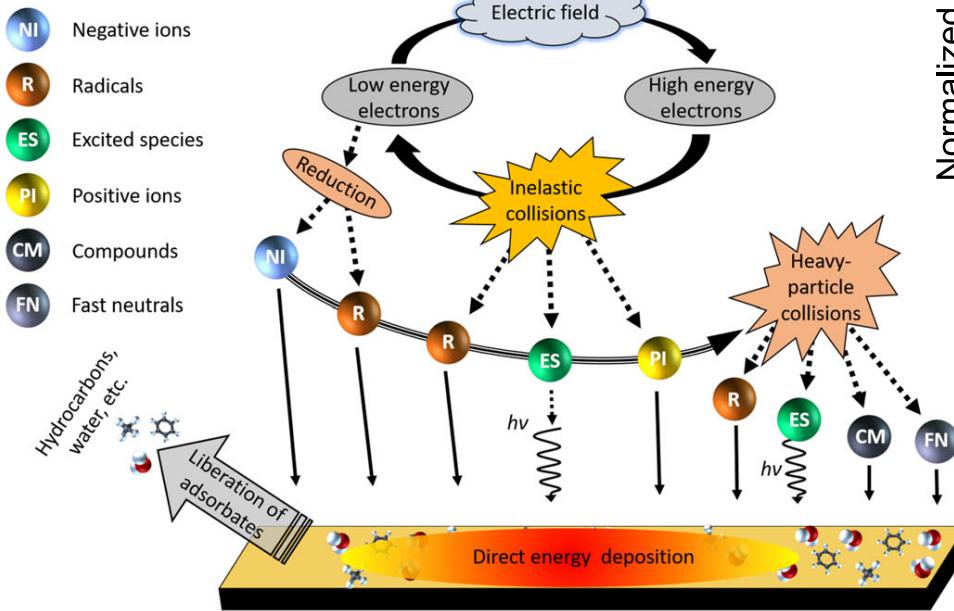
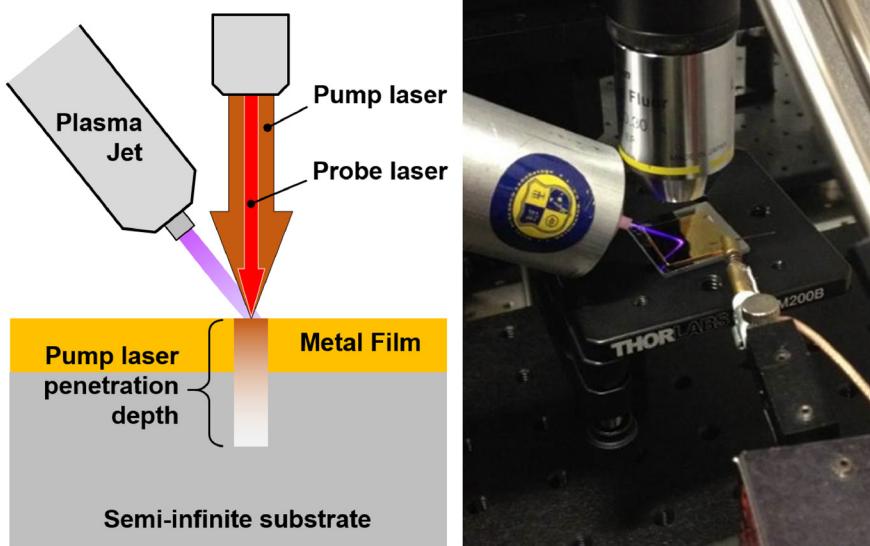
Actively switching thermal conductivity w/ FE/AFE domains



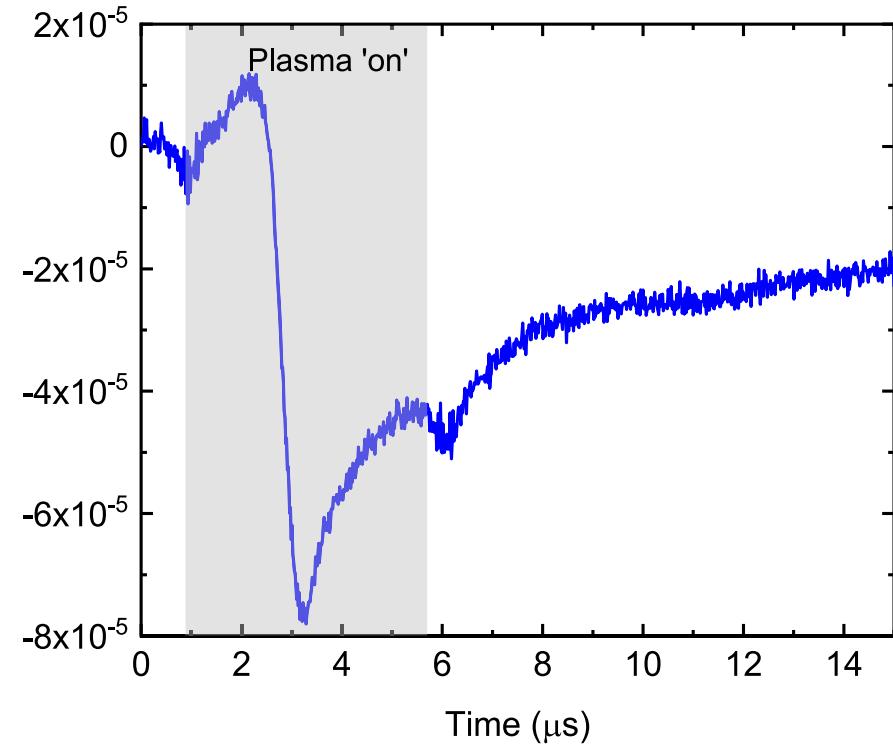
Aryana *et al.*, *Nat. Comm.*
13, 1573 (2022)



Plasma-surface interactions and heat transfer

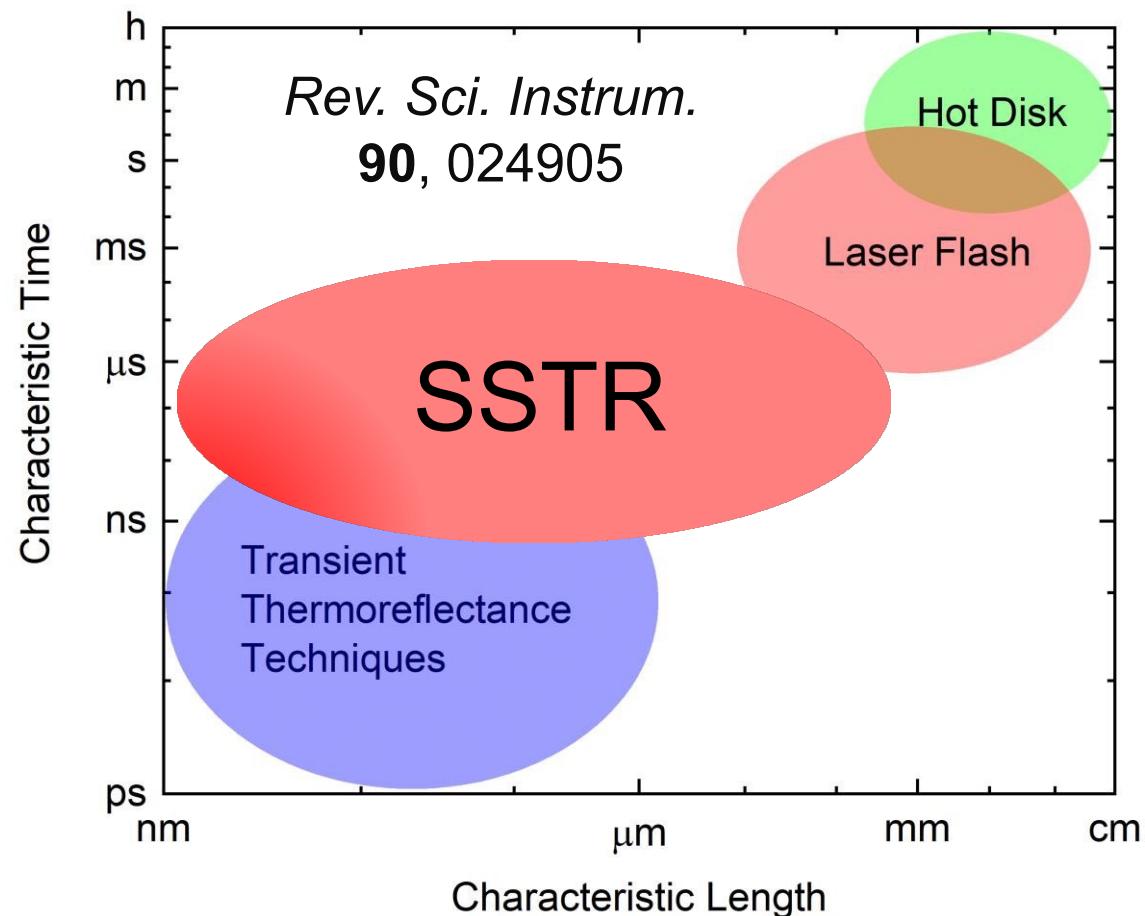
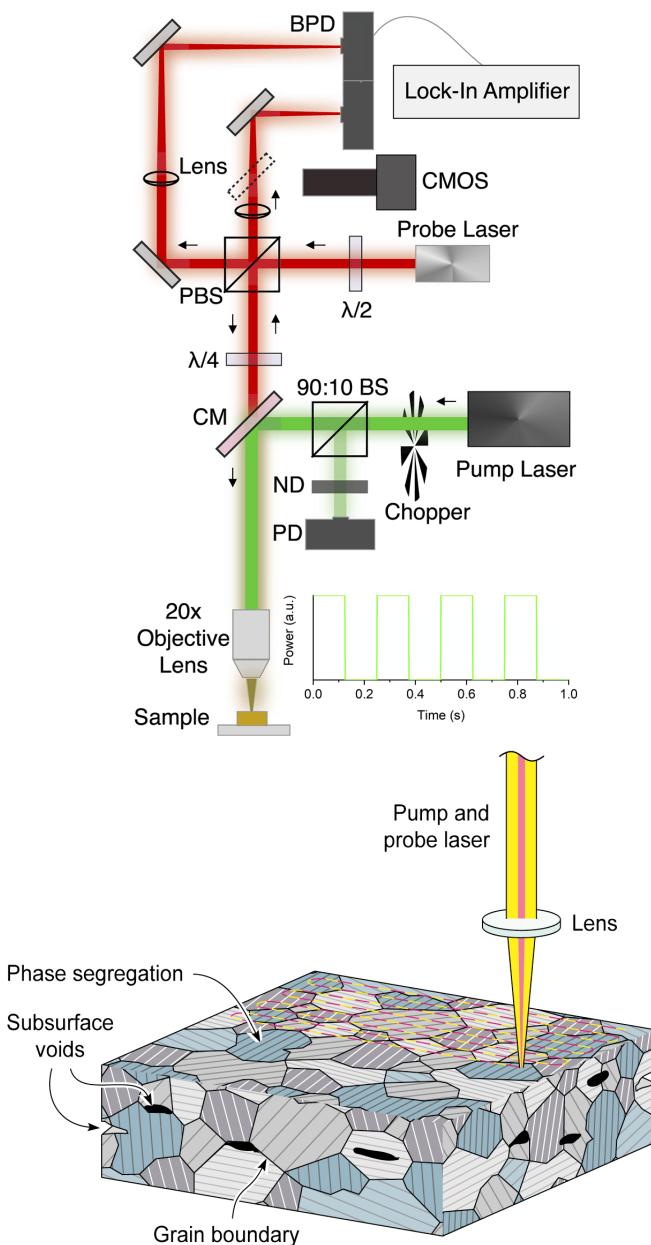


Plasma cooling!



Tomko et al., *Nat. Comm.*
13, 2623 (2022)

But how do we measure nano to macro HX processes?



Spatially resolved thermoreflectance techniques for thermal conductivity measurements from the nanoscale to the mesoscale 

Cite as: J. Appl. Phys. 126, 150901 (2019); doi: 10.1063/1.5120310

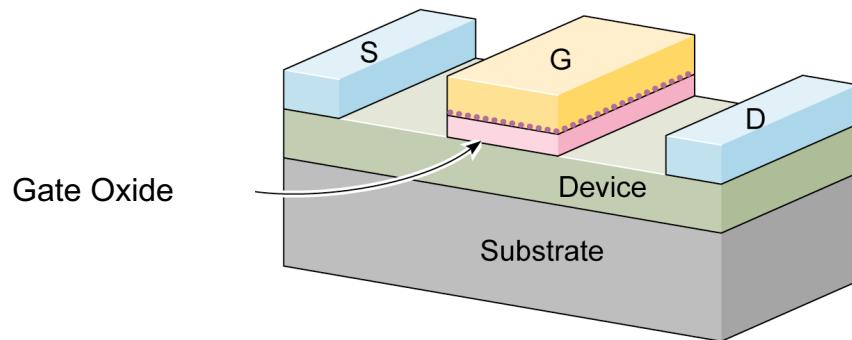
Submitted: 17 July 2019 · Accepted: 29 September 2019 ·

Published Online: 16 October 2019

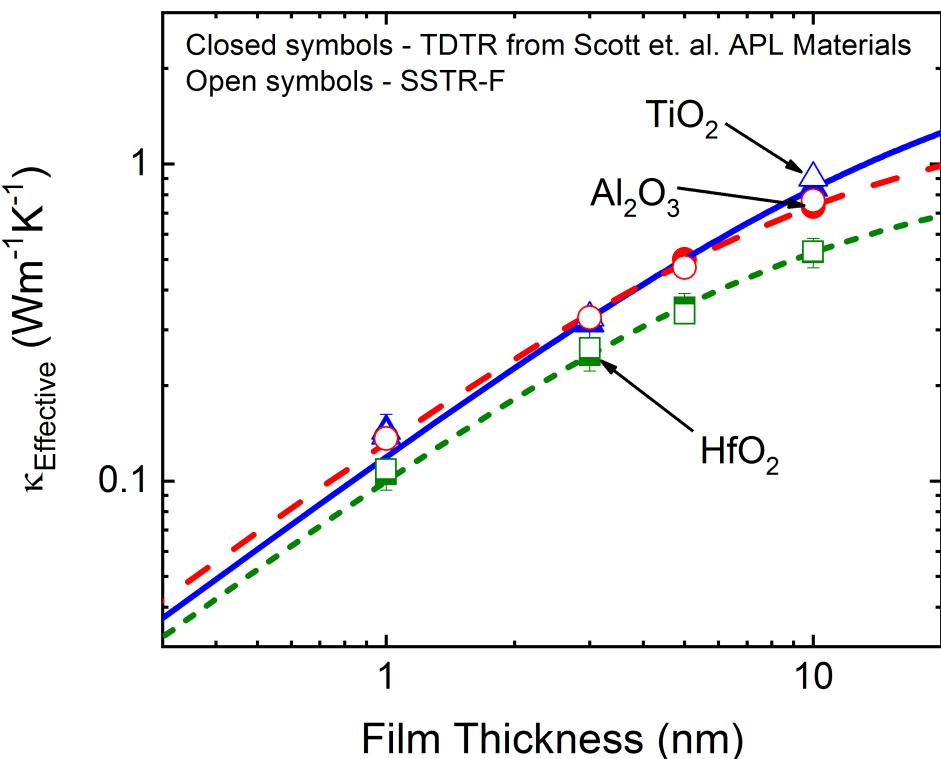
David H. Olson,¹  Jeffrey L. Braun,¹  and Patrick E. Hopkins^{1,2,3,a} 

SSTR: Capabilities for thermal conductivity measurements

Thermal conductivity of dielectric films as thin as 1 nm



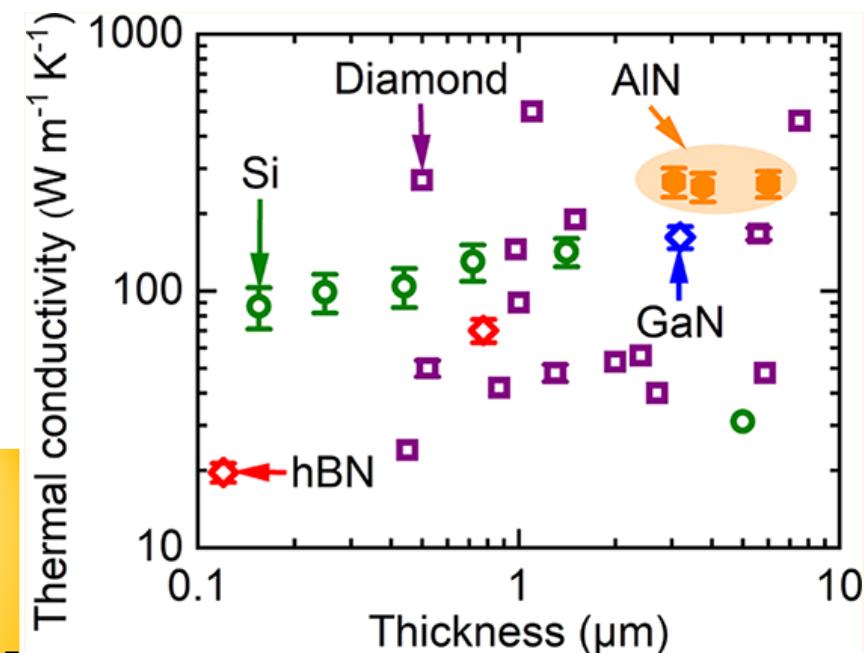
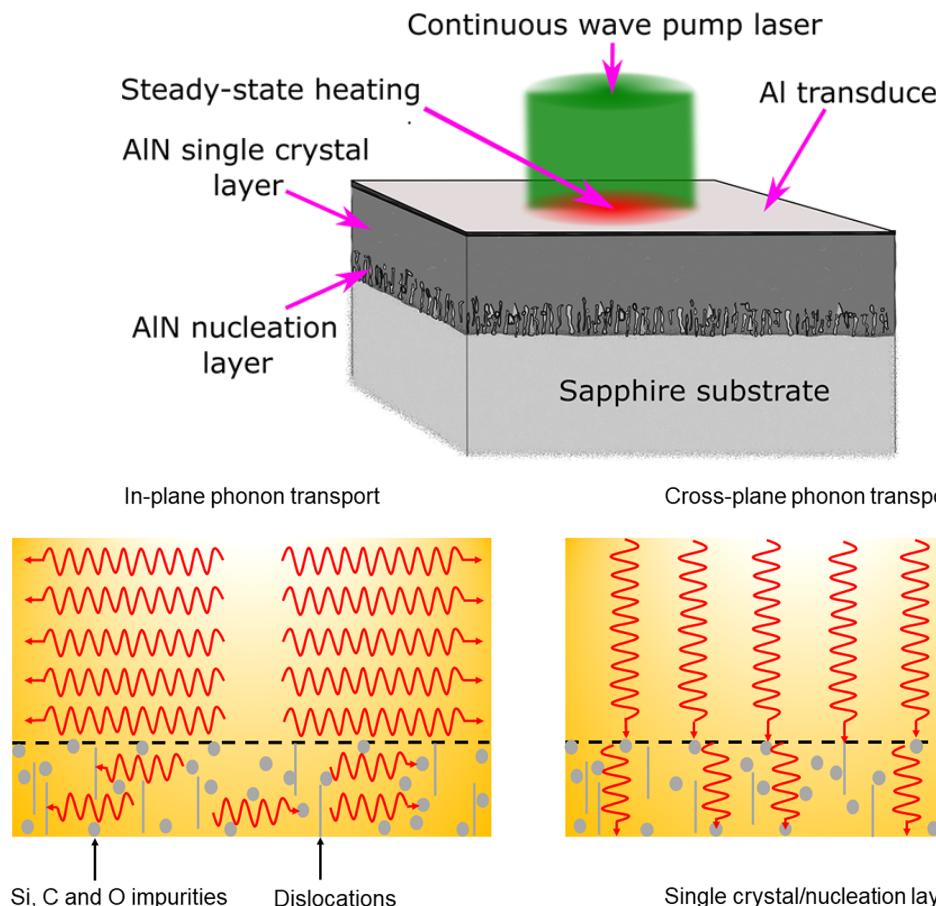
- Verified over three materials systems using SSTR-F



- Matches existing TDTR measurements
- Measuring resistance from interfaces and from material resistance in this case

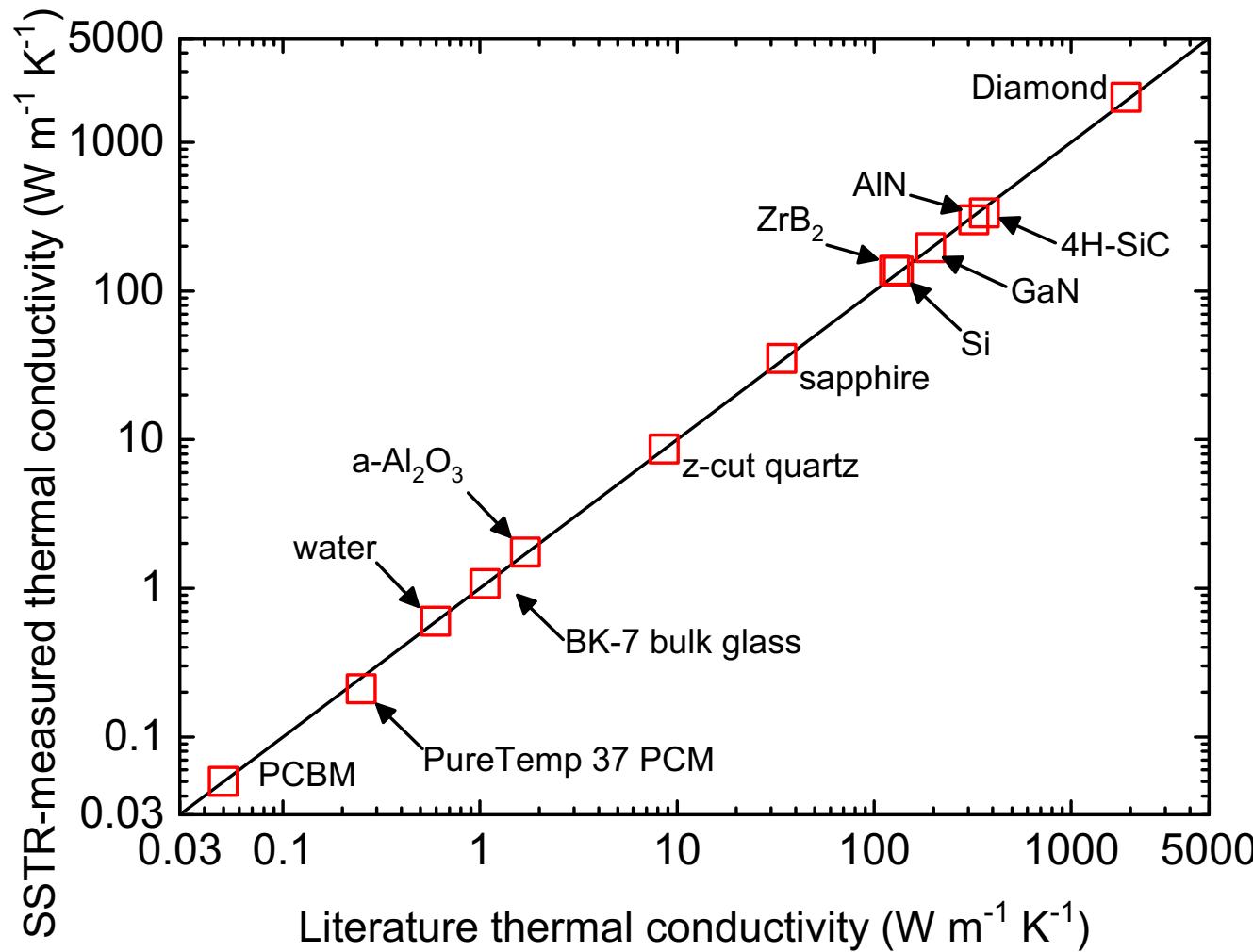
SSTR: Capabilities for thermal conductivity measurements

In-plane thermal conductivity of thin films i.e., anisotropy effects in AlN thin films



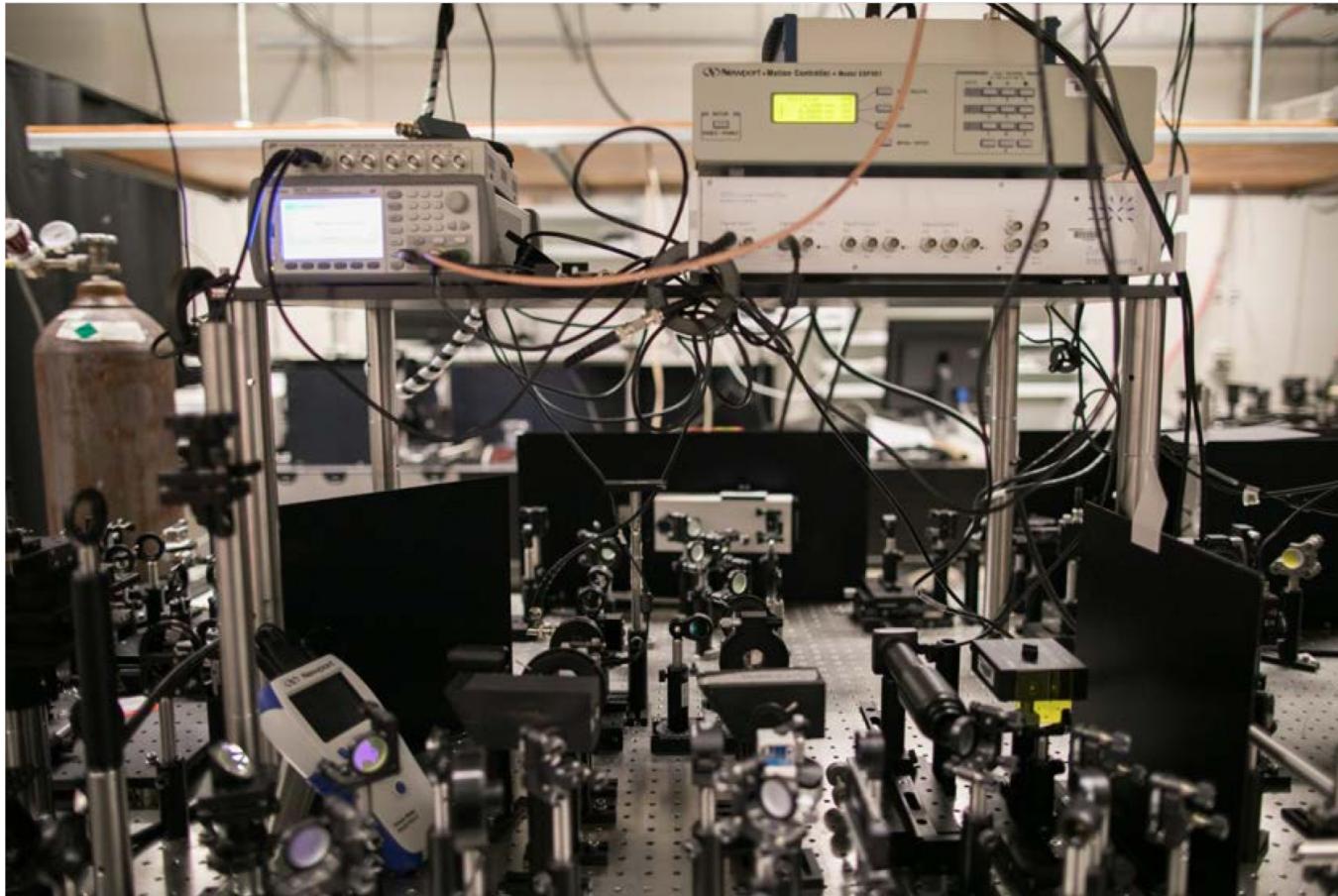
SSTR: Capabilities for thermal conductivity measurements

Extremely conductive (diamond) and insulative (PCBM) materials



SSTR-F: Recently commercialized for turn-key, fiber-optically integrated thermal conductivity microscope

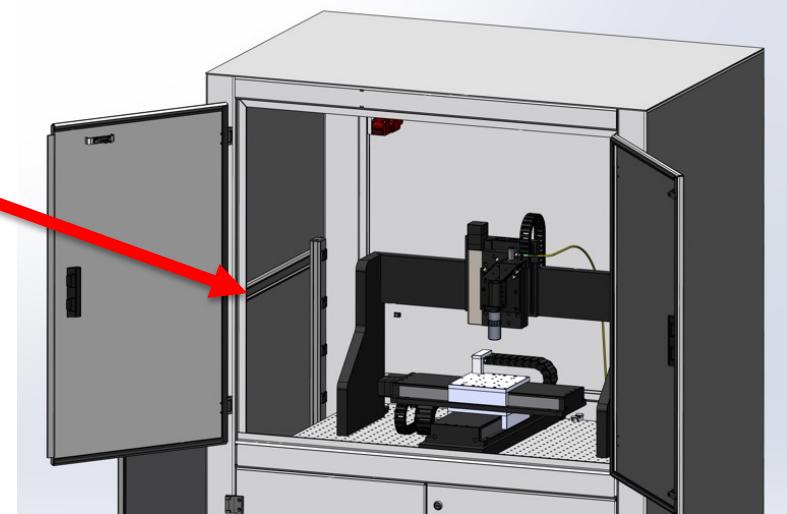
The typical thermoreflectance set up



A LOT of optics, upkeep and expertise for analysis

SSTR-F: Commercialized for turn-key thermal conductivity microscope for bulk materials, thin films and interfaces

<https://Laserthermal.com>



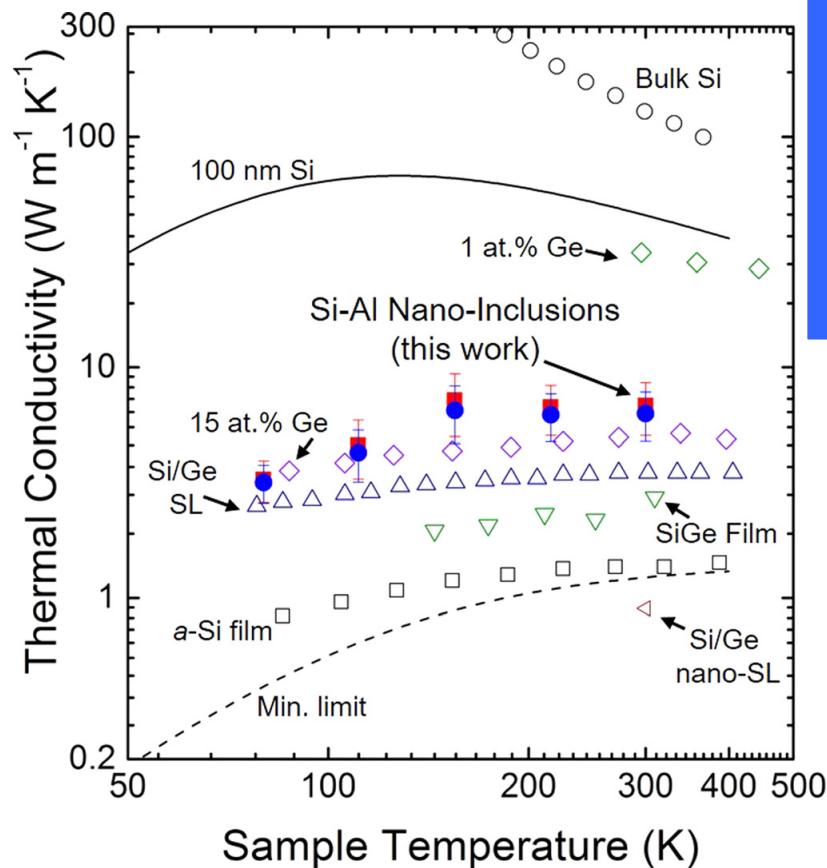
**Laser Thermal, Inc. will be exhibiting
at ALD/ALE 2022 next month!**

Outline

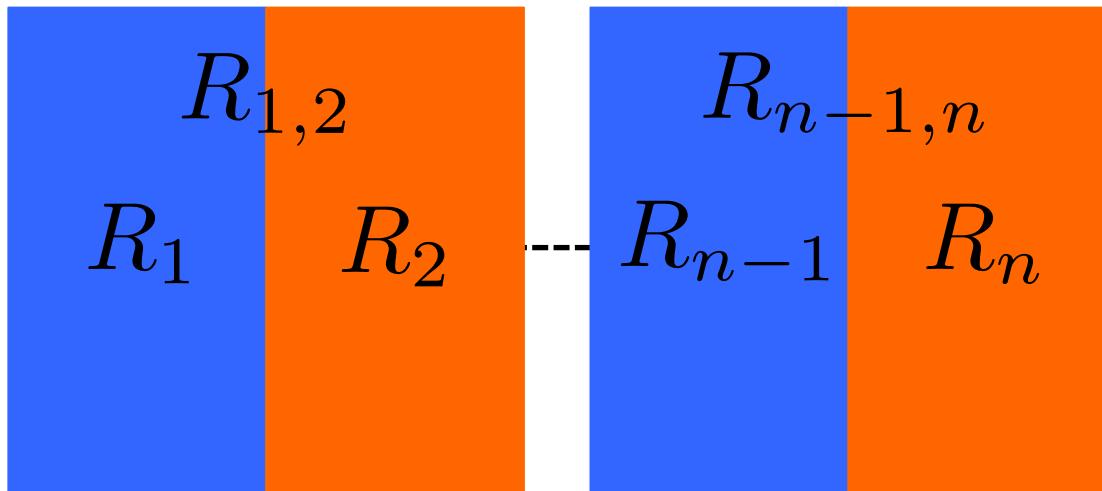
Theme: Atomic properties at interfaces can change the nature and behavior of heat transfer via phonons, electrons and photons

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Phonon thermal conductivity in superlattices: incoherent



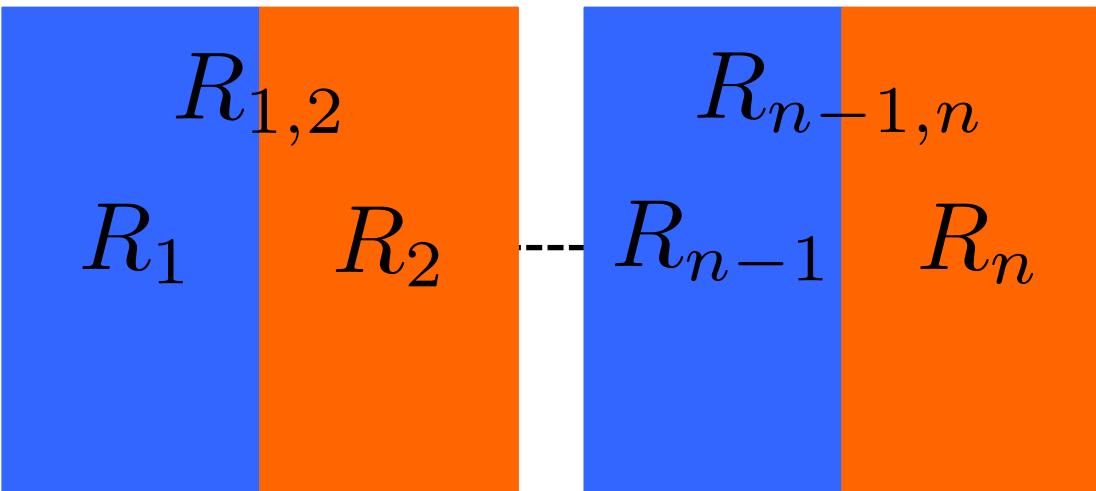
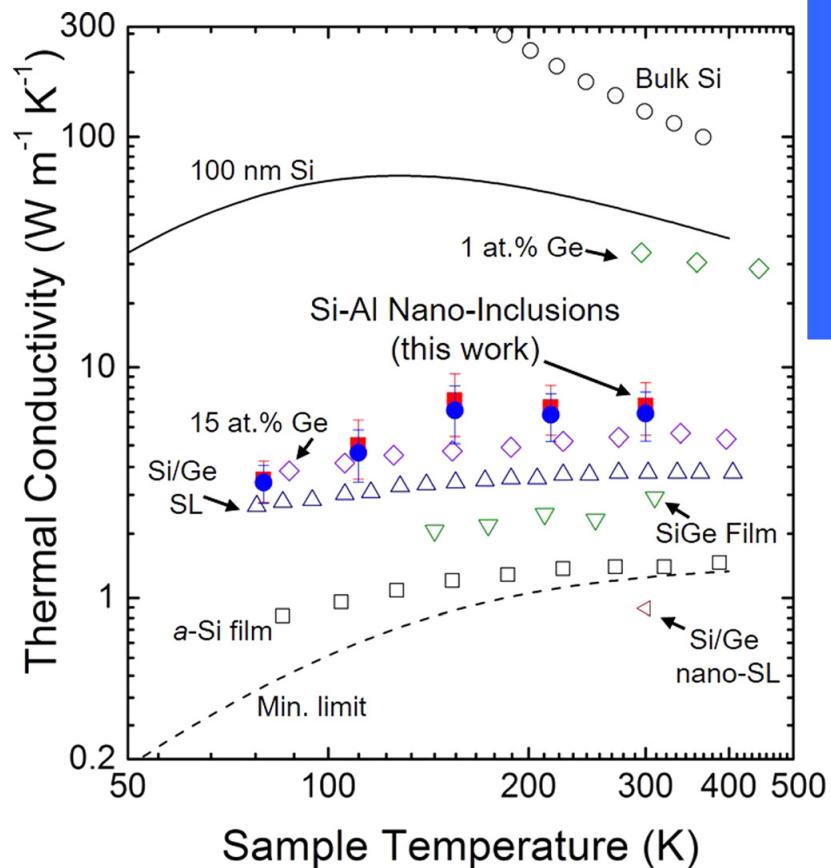
APL 112, 213103



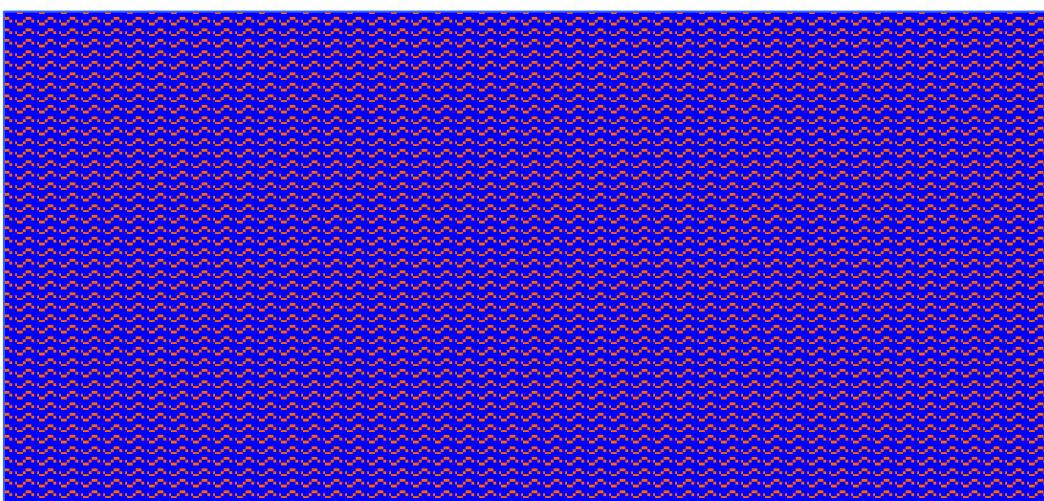
$$1/\kappa \propto 1/h = \sum_n R_j$$

Phonons scatter at every interface, and thus each interface offers a resistance to the overall thermal conductivity

Phonon thermal conductivity in superlattices: coherent



What if layers are “linked”?
– coherent transport



The minimum thermal conductivity of superlattices

PHYSICAL REVIEW B

VOLUME 25, NUMBER 6

15 MARCH 1982

VOLUME 84, NUMBER 5

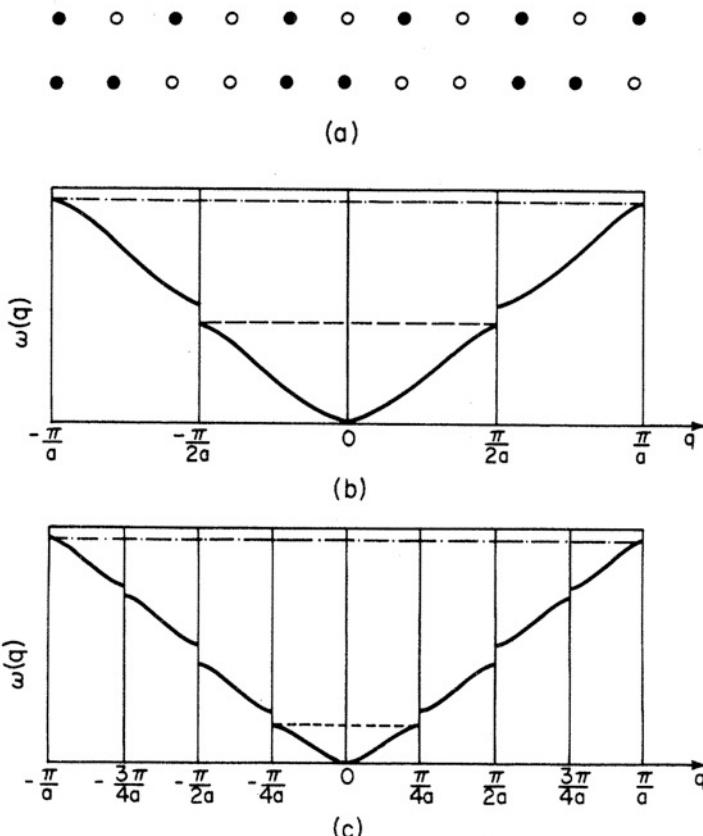
PHYSICAL REVIEW LETTERS

31 JANUARY 2000

Thermal conductivity of superlattices

Shang Yuan Ren* and John D. Dow

Department of Physics and Coordinated Science Laboratory, University of Illinois at Urbana-Champaign, Urbana, Illinois 61801
(Received 21 September 1981)

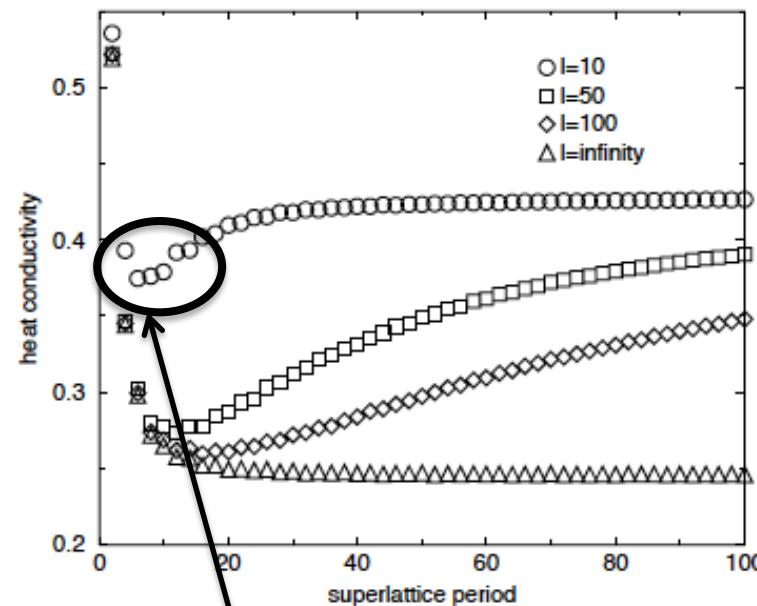


Interfacial periodicity can lead to “mini-band” formation

Minimum Thermal Conductivity of Superlattices

M. V. Simkin and G. D. Mahan

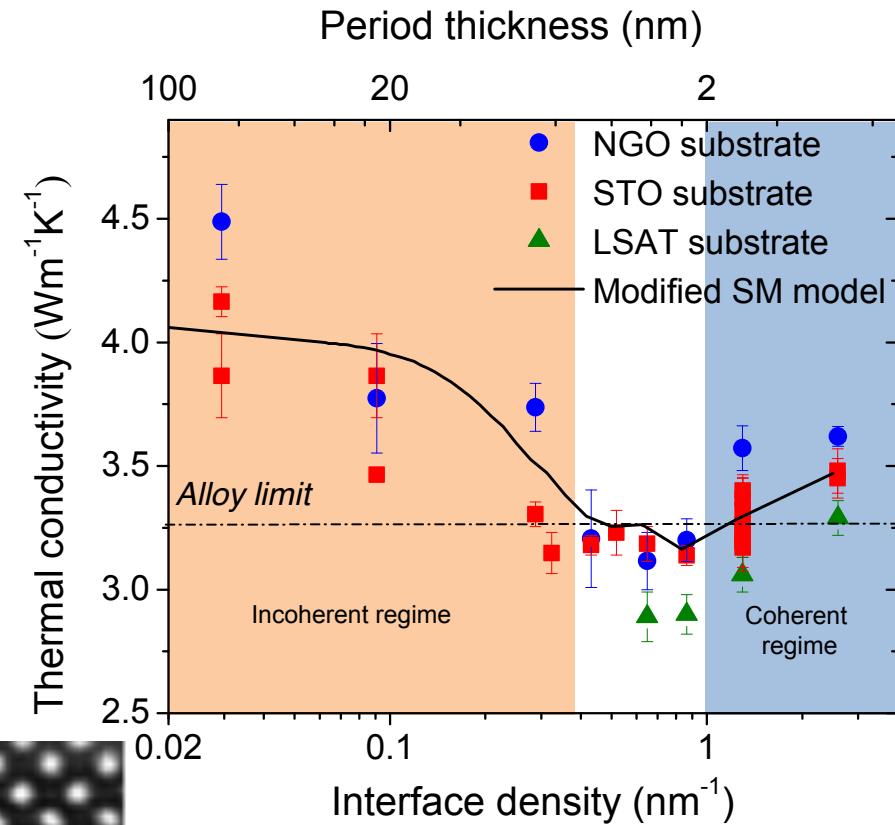
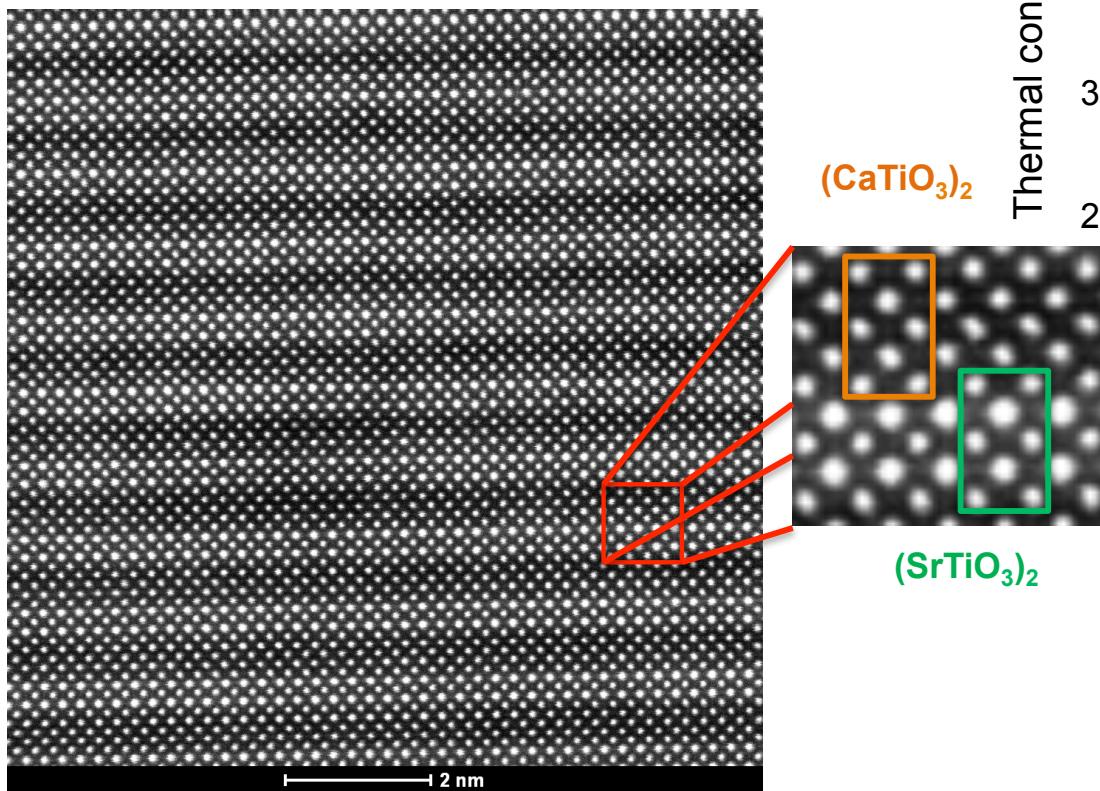
Department of Physics and Astronomy, University of Tennessee, Knoxville, Tennessee 37996-1200
and Solid State Division, Oak Ridge National Laboratory, P.O. Box 2008, Oak Ridge, Tennessee 37831
(Received 23 July 1999)



Mini-band formation leads to a minimum in the superlattice thermal conductivity

Experimental evidence of minimum thermal conductivity

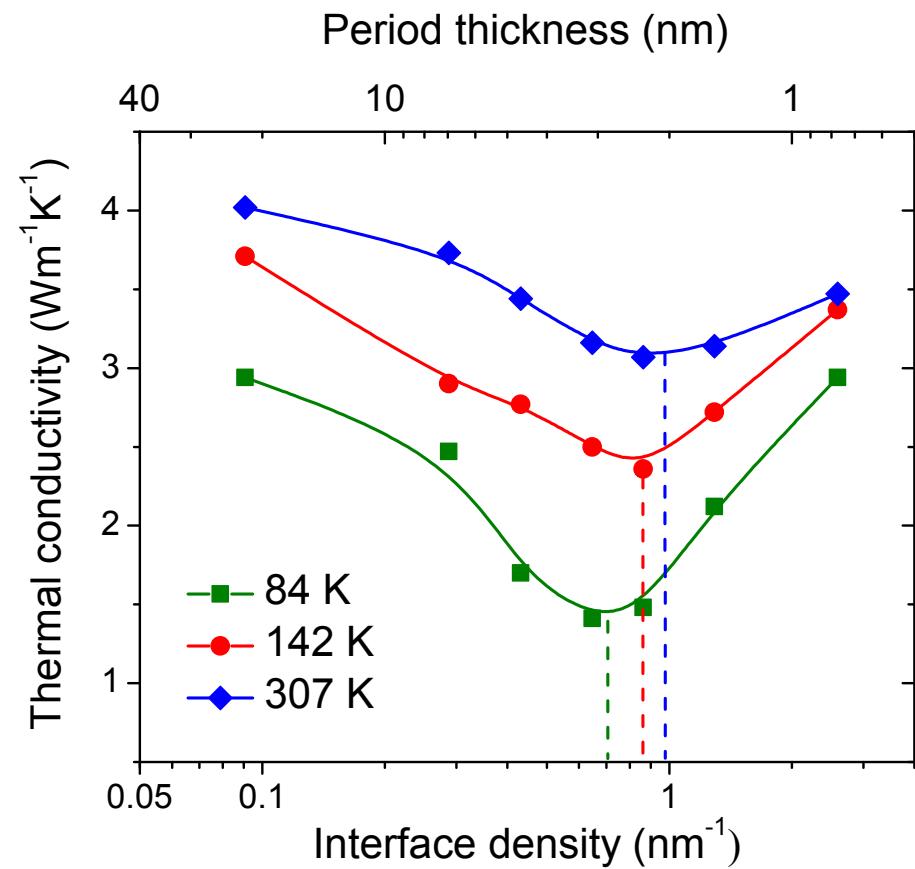
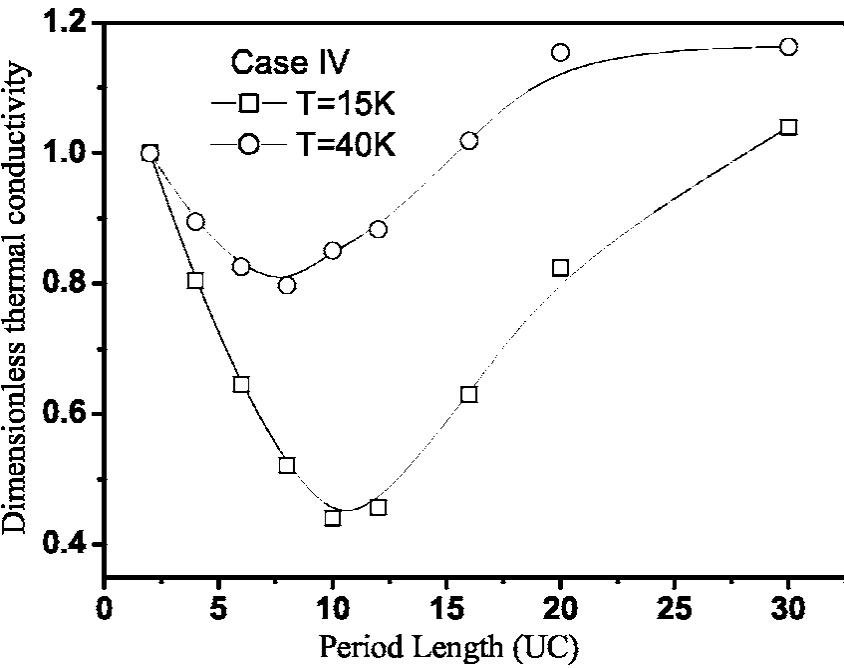
Nature Materials 13,
168 (2013)



Growth PLD:
J. Ravichandran
A. Yadav
R. Ramesh
A. Majumdar

Experimental evidence of minimum thermal conductivity

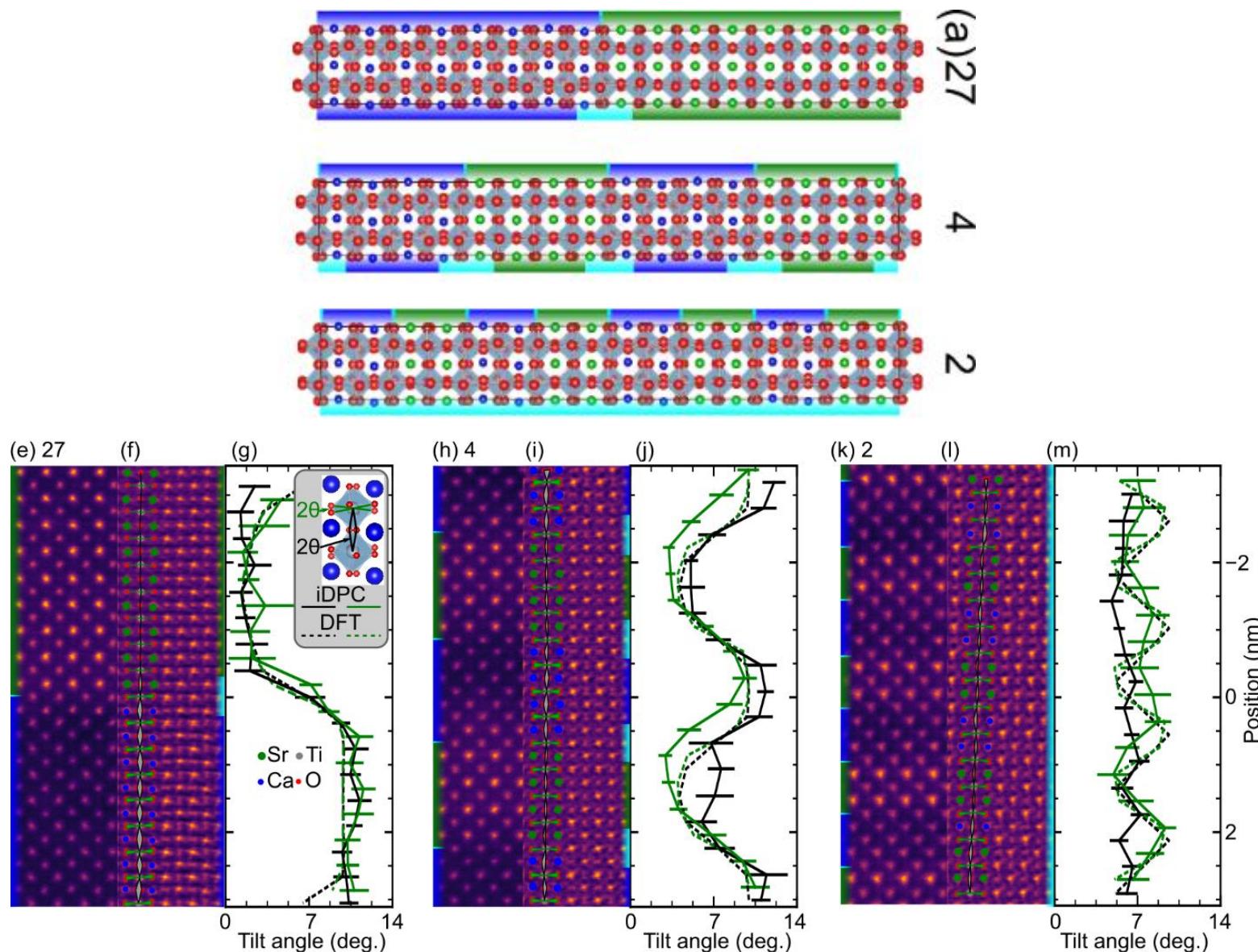
- More pronounced minimum at low T, thermal conductivity measurements show trends of mini-band formation
- MD simulation (left), mini-band = phonon bandgap (PRB **72**, 174302)



SL design to manipulate coherent phonon transport

Ravichandran *et al.* *Nature Materials* **13**, 168 (2013)

Experimental evidence of phonon coherence

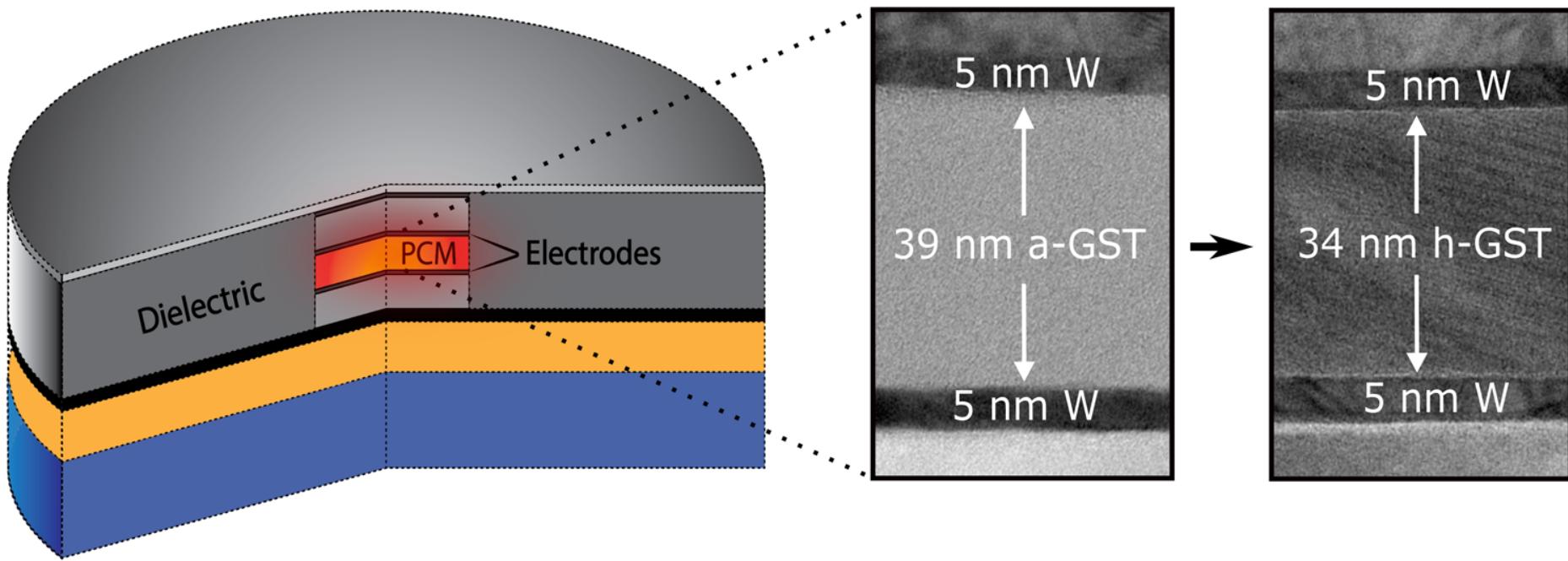


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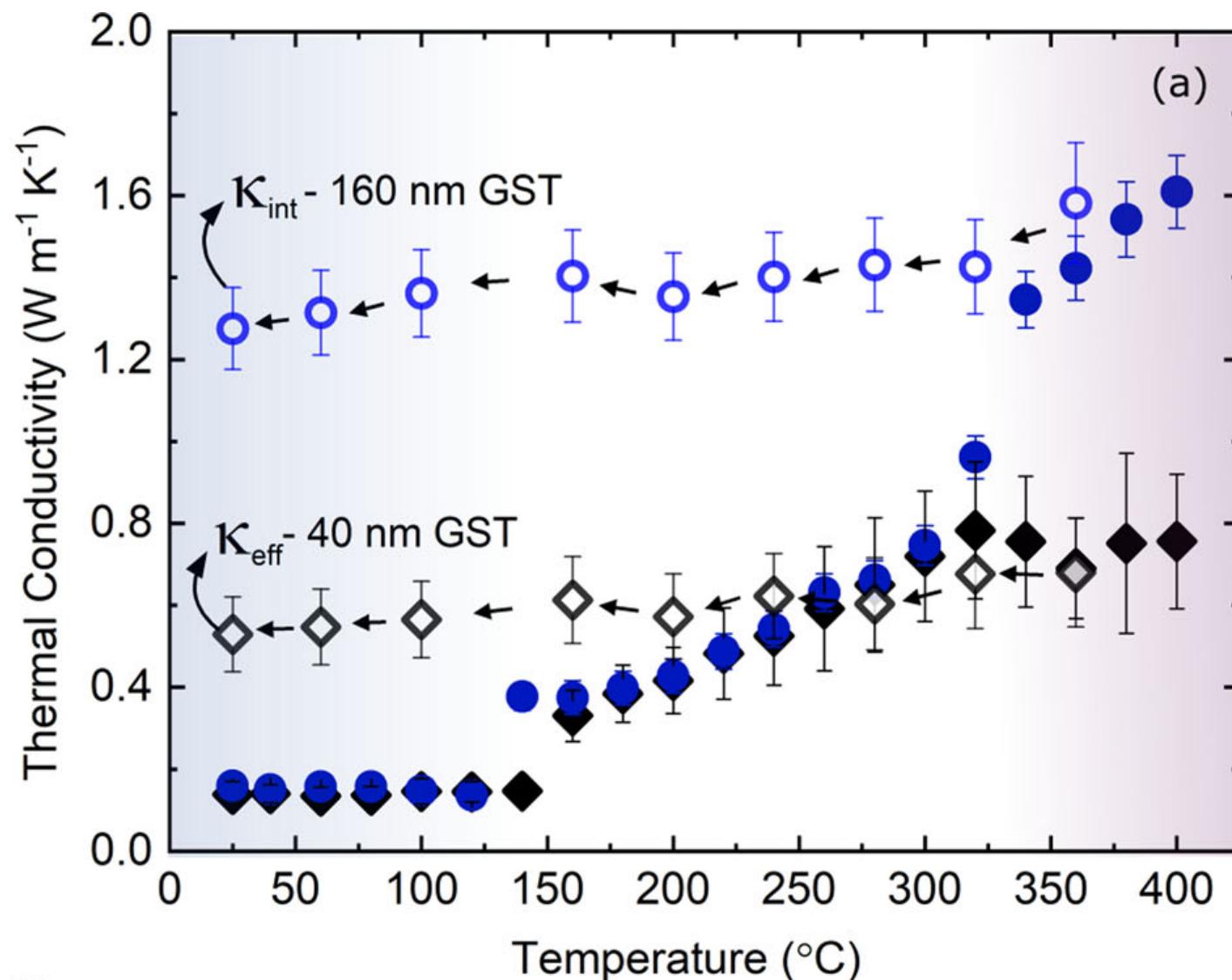
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Heat conduction processes in ultrathin GST

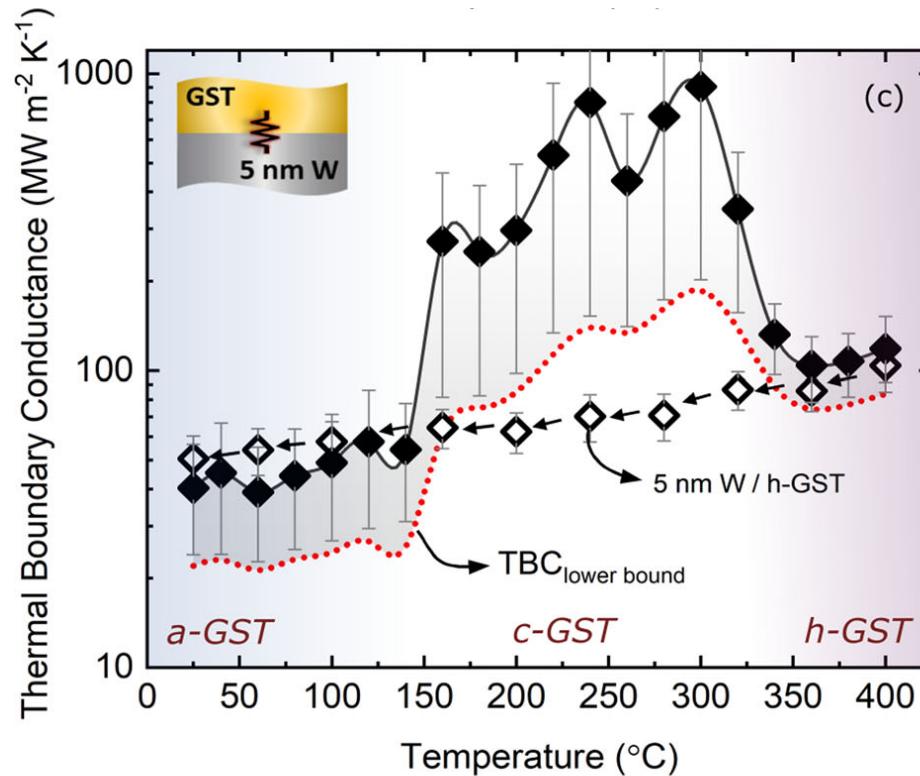


What happens as the thickness of the GST decreases down to length scales of electron and phonon mean free paths?

Heat conduction processes in ultrathin GST

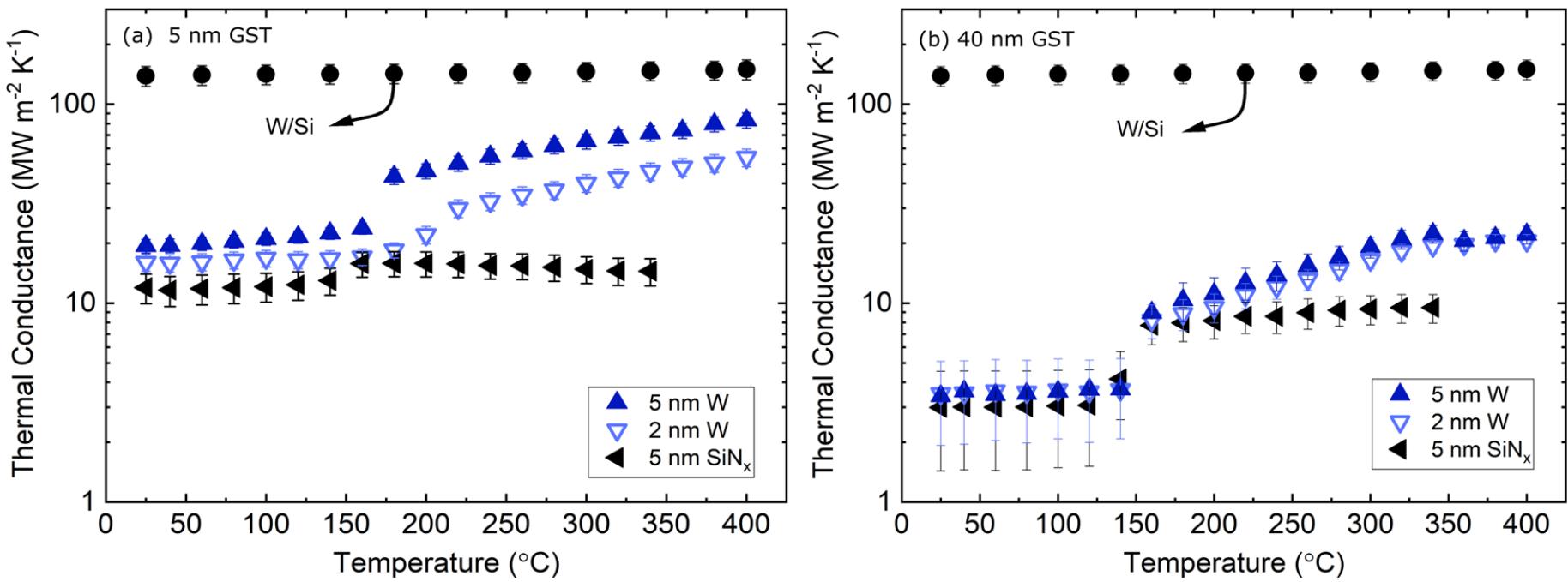


Phase dependence thermal boundary conductance



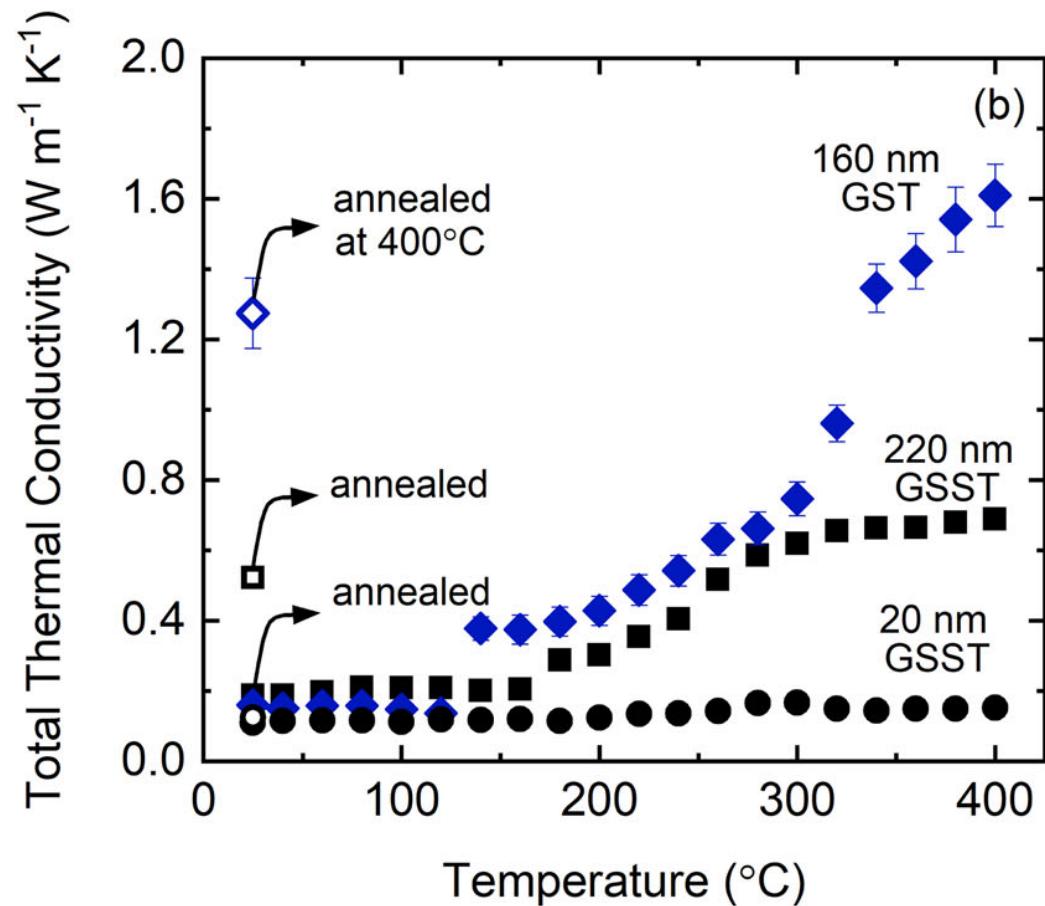
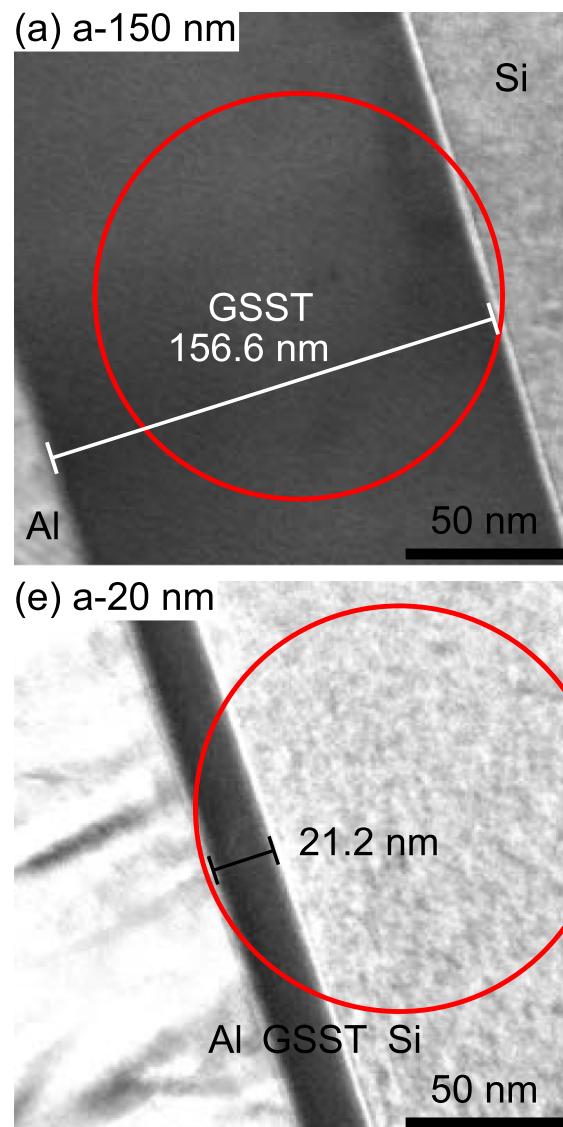
- Thermal boundary conductance across contact interfaces drive overall thermal transport as thickness decreases
- TBC dependent on GST phase, much like κ

Ballistic electron transport across GST



- Overall conductance *higher* for thin GST film (5 nm)
- Ballistic thermal conductance of electrons from contact to contact (i.e., the electrons don't "see" the GST and it's just a metal/metal TBC)

Suppressing electron transport: Add in Se! (GSST)

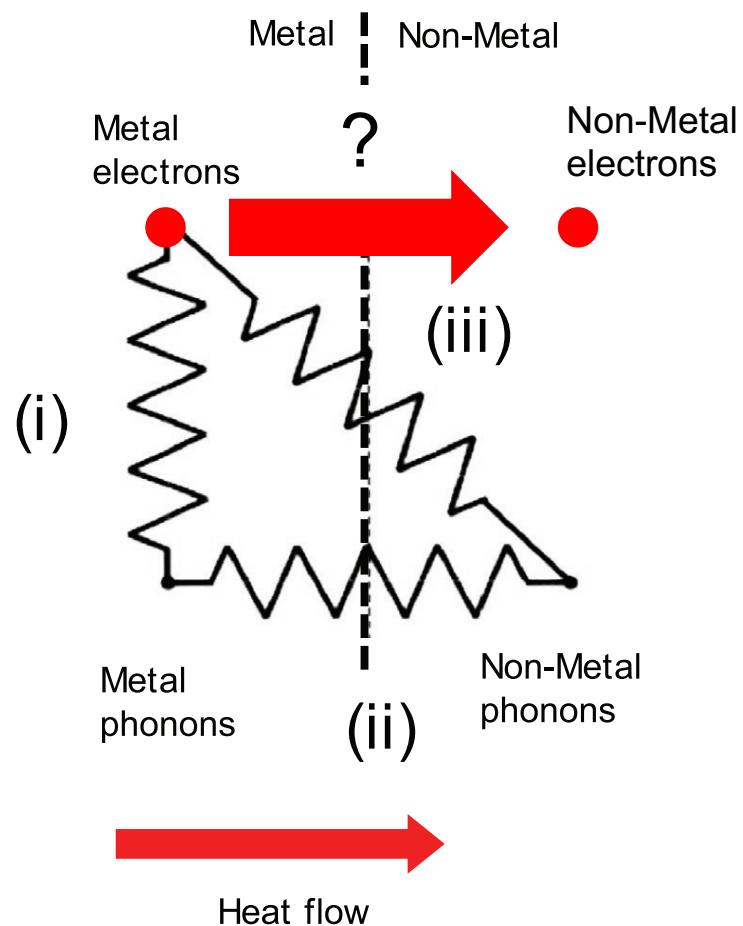


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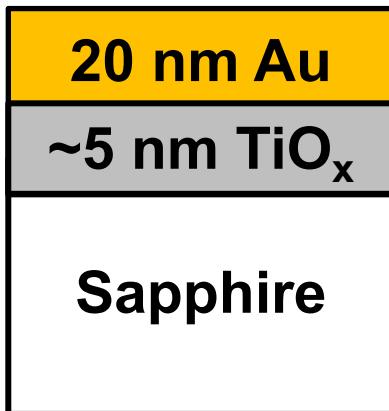
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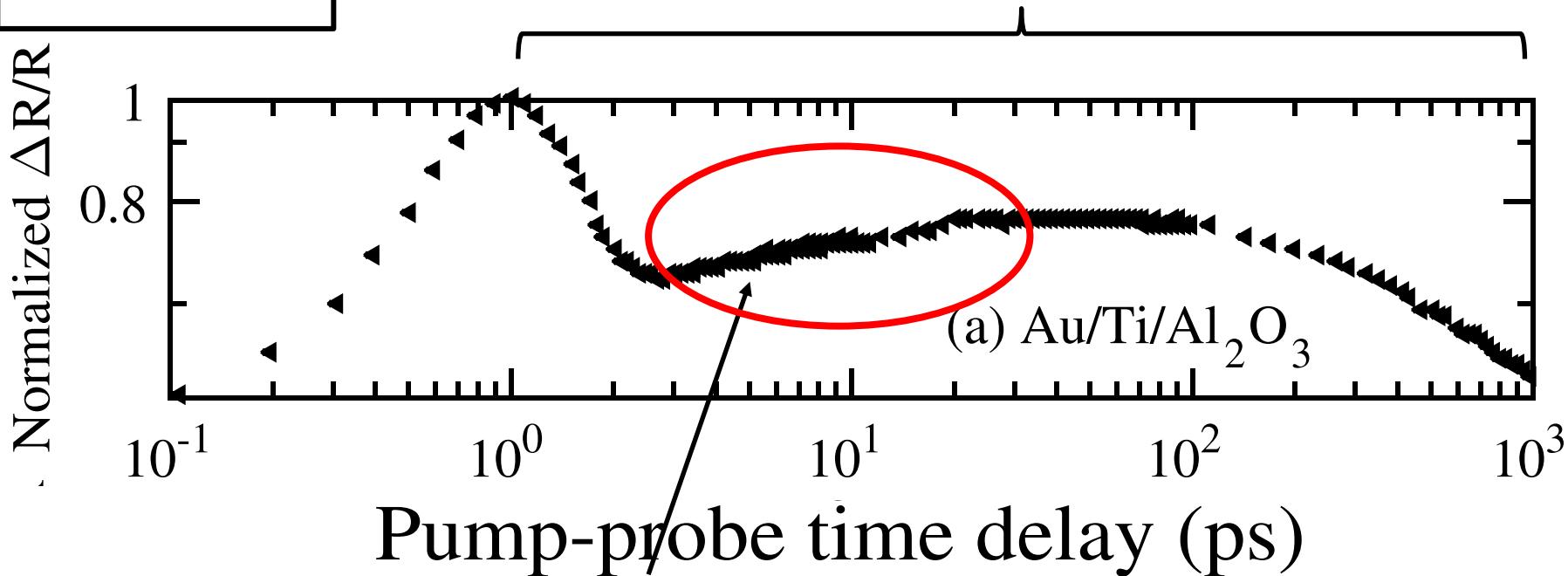
Electron energy transfer at metal/nonmetal interfaces



Ultrafast pump-probe to measure EP coupling



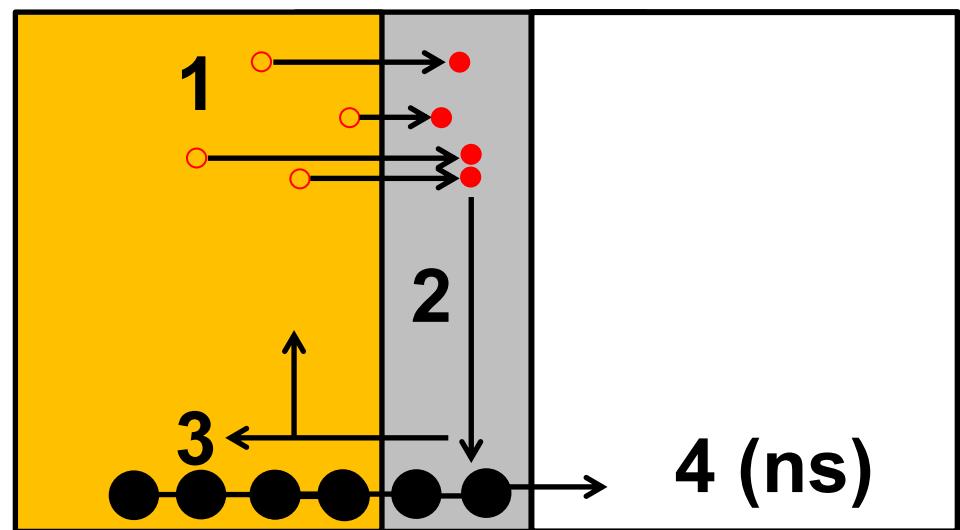
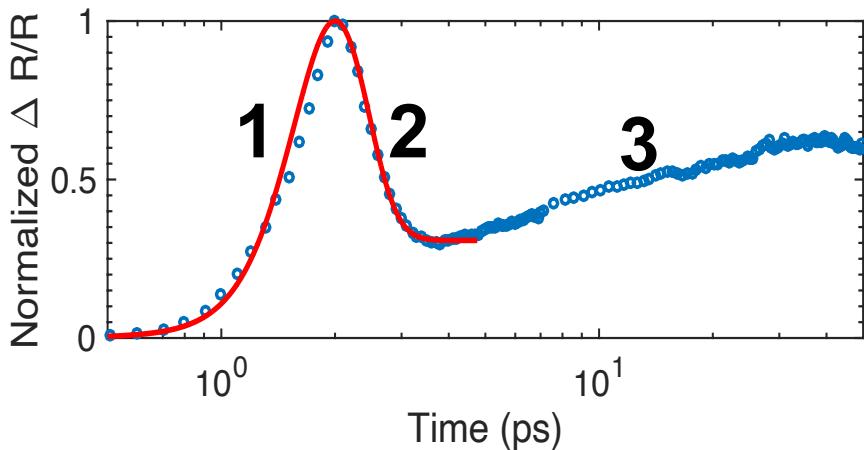
Energy no longer deposited in system



So why does temperature at surface increase when no energy is deposited in the system?

Ballistic thermal injection

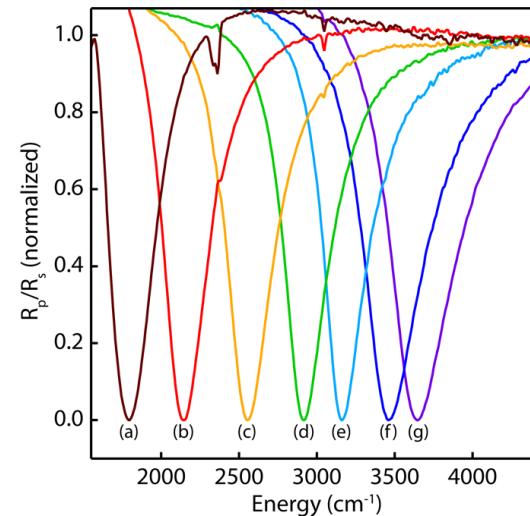
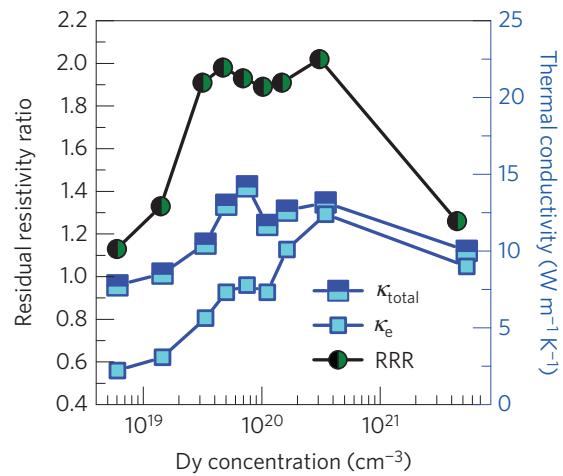
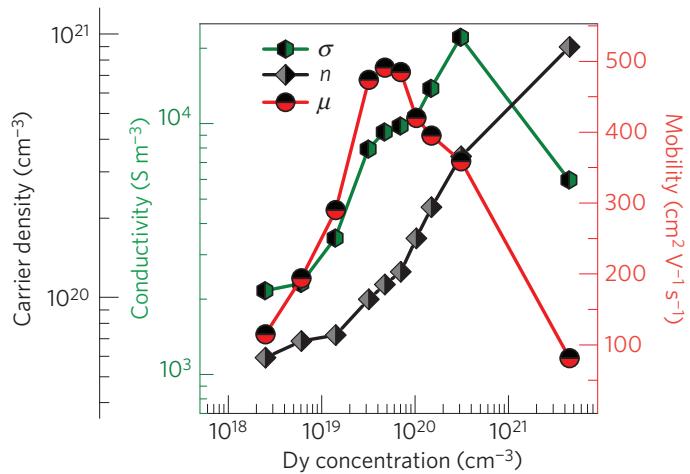
- Excited electrons in metal from pulse do not thermalize with lattice and deposit their energy to lattice in sub-surface layer
- Ballistic transport of electron energy through gold into titanium



When would we see this effect?

1. Metal/metal or metal/non-metal interfaces with large differences in electron-phonon coupling factor
2. Films with thicknesses less than electron-phonon mean free path
3. Interfaces with very little electron-electron thermal resistance

CdO – a gateway for mid-IR plasmonics



ACS Photonics **4**, 1885

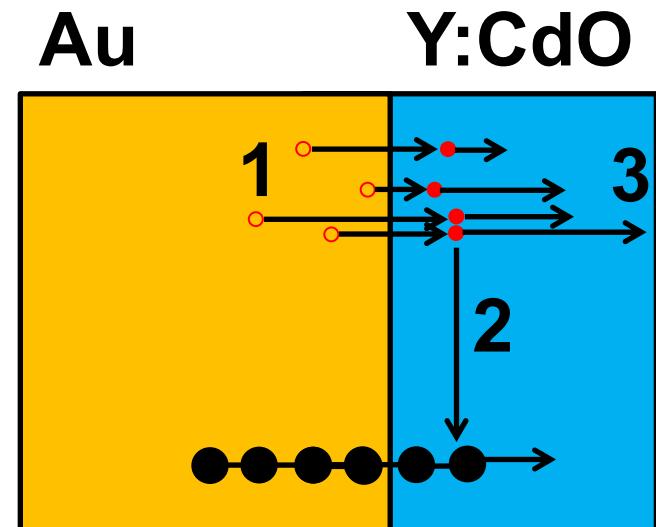
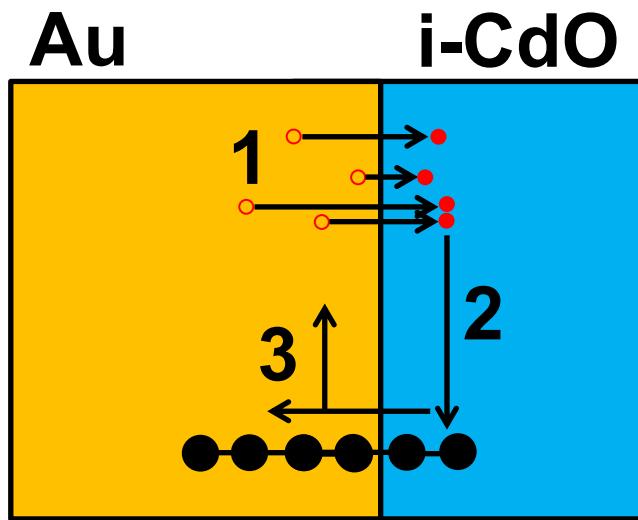
- Large electron mobility in CdO results in large electronic thermal conductivity
- Doping concentration tunes electronic conductivity and IR absorption

Nat. Mat. **14**, 414

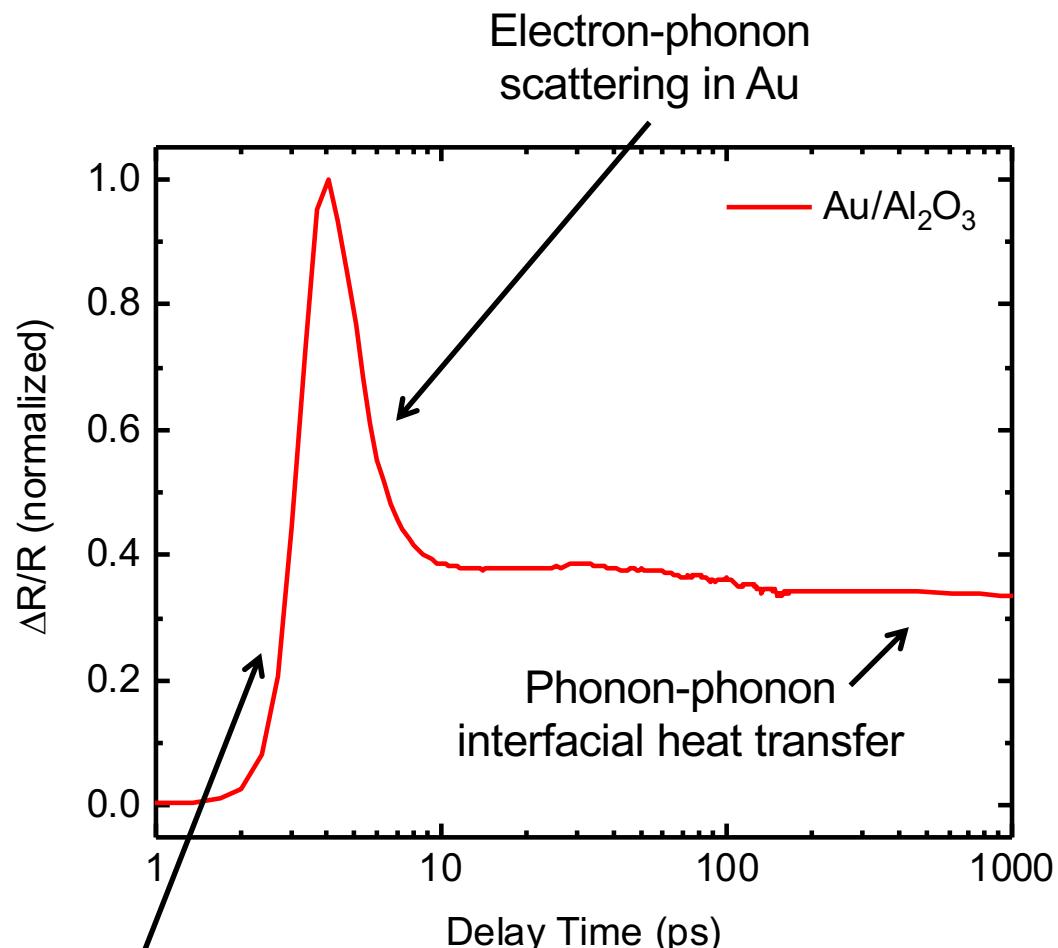
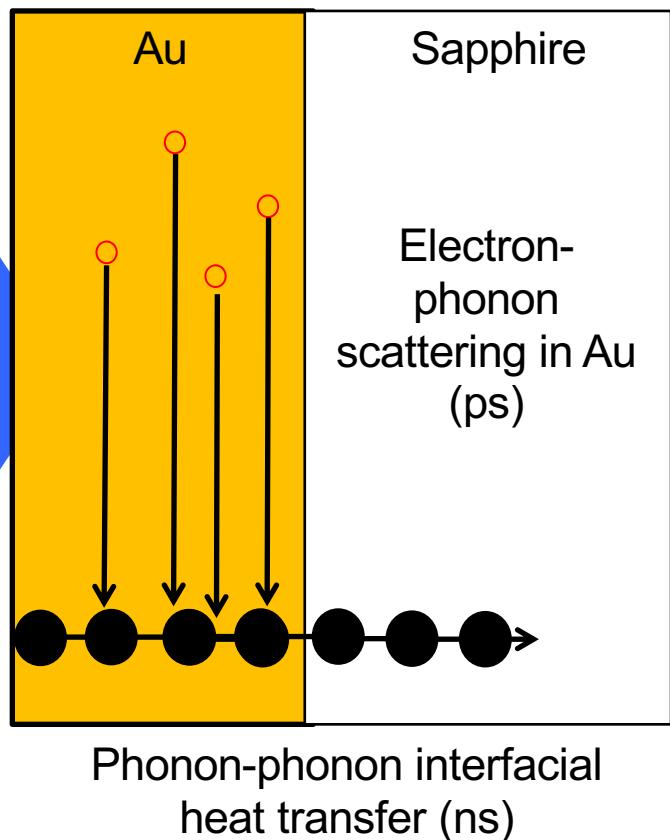
Appl. Phys. Lett. **108**, 021901

Nonequilibrium processes at Au/CdO interfaces

Doping will control electron-electron TBC and electron thermal conductivity in CdO, vary “back heating”

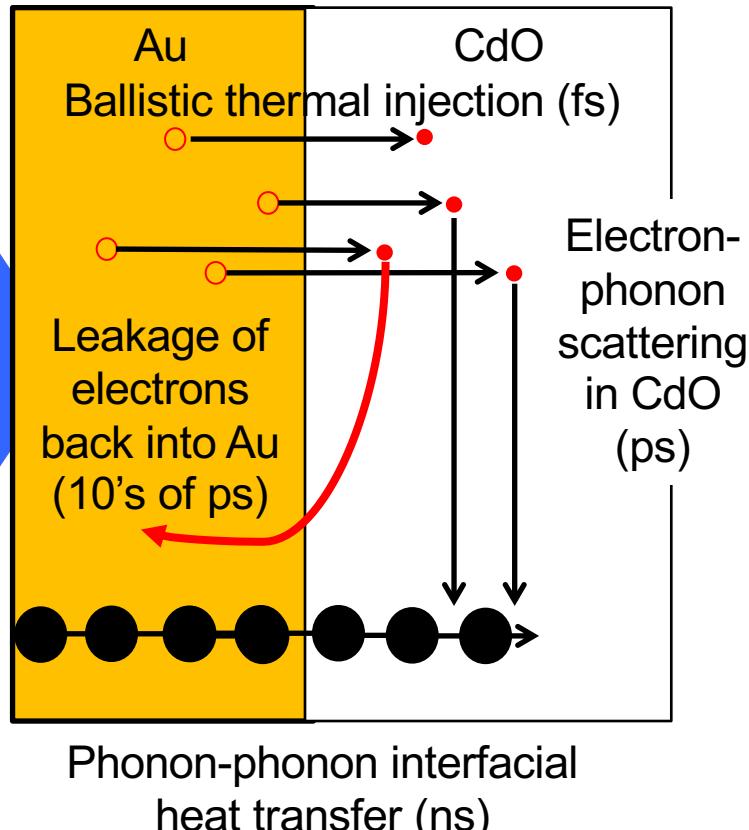


Nonequilibrium processes at Au/CdO interfaces

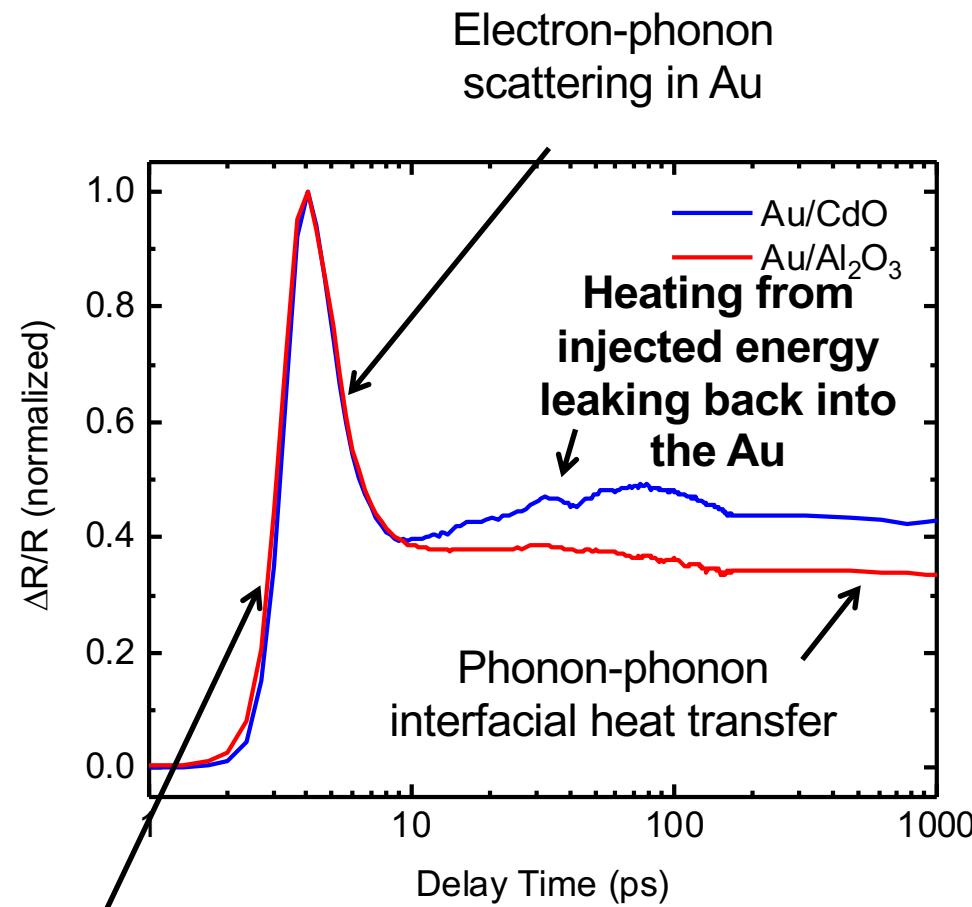


~sub picosecond pulsed laser absorption in Au

Nonequilibrium processes at Au/CdO interfaces



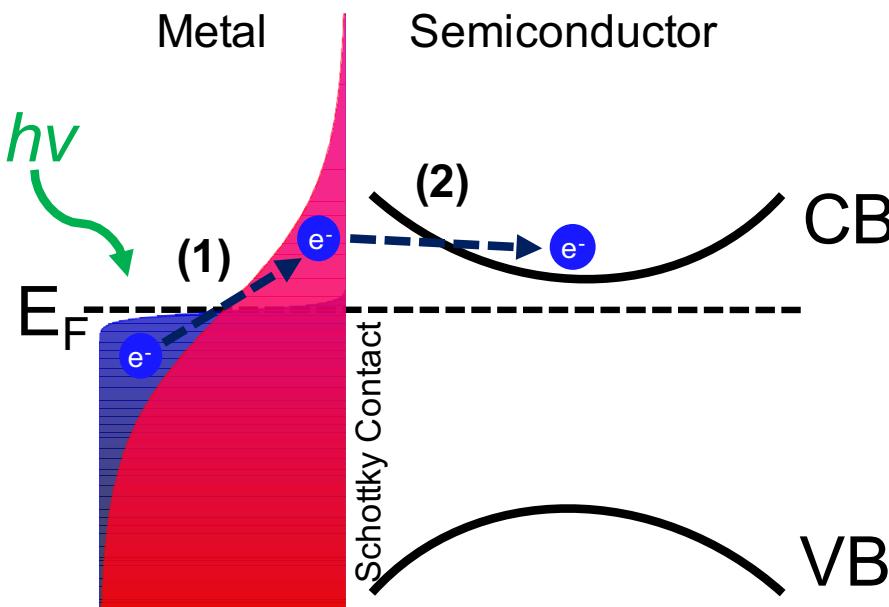
~sub picosecond pulsed laser absorption in Au + charge injection into CdO



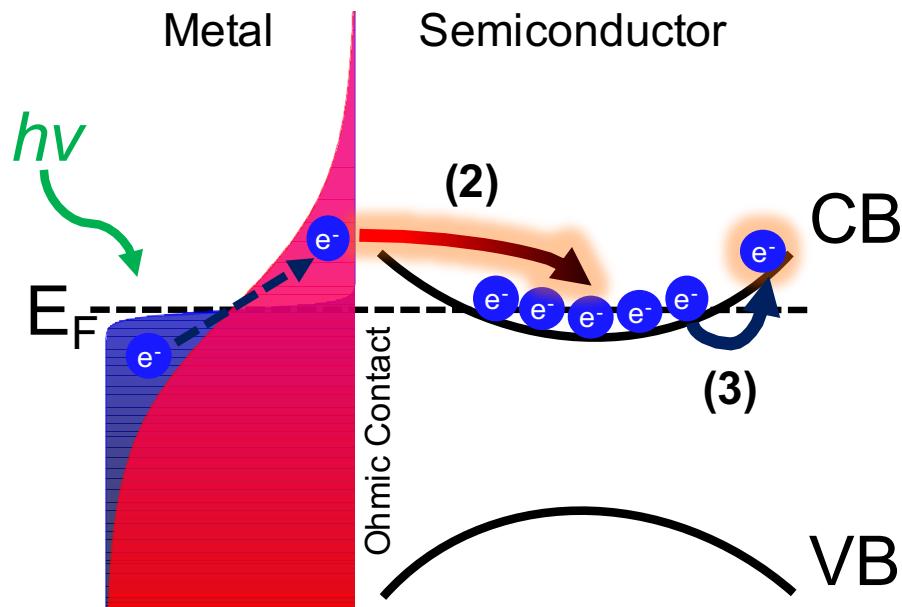
Ballistic thermal injection

- Can enable a “transient thermal diode” effect
- Energy easily transmitted across interface when traveling ballistically
- Slowly “goes back” across the interface when diffusive
- Is this just hot electron injection (charge)?
 - Too slow of process
 - Can further rule this out by monitoring CdO plasmon response

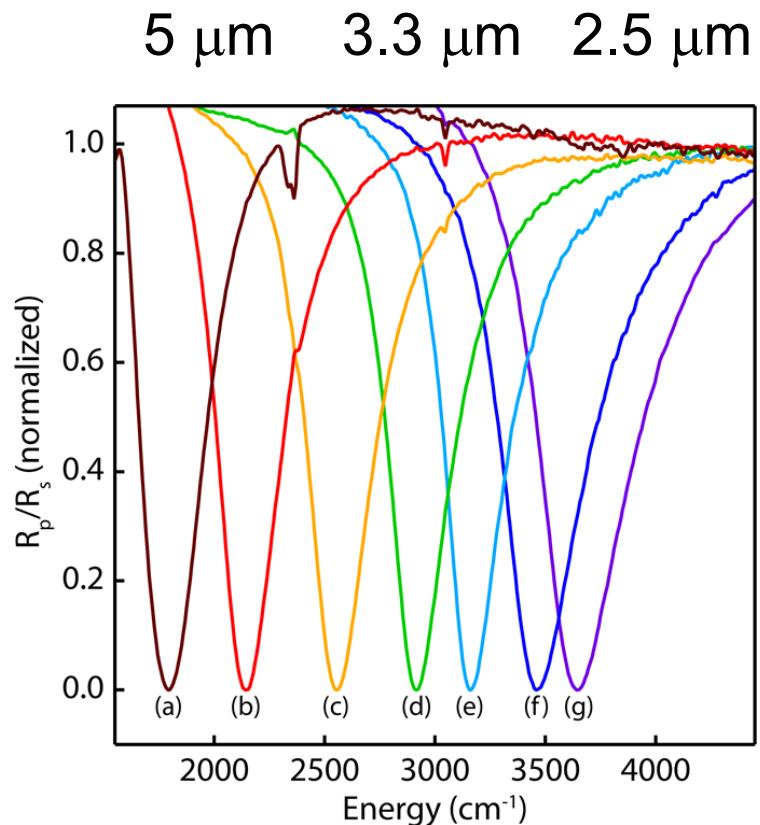
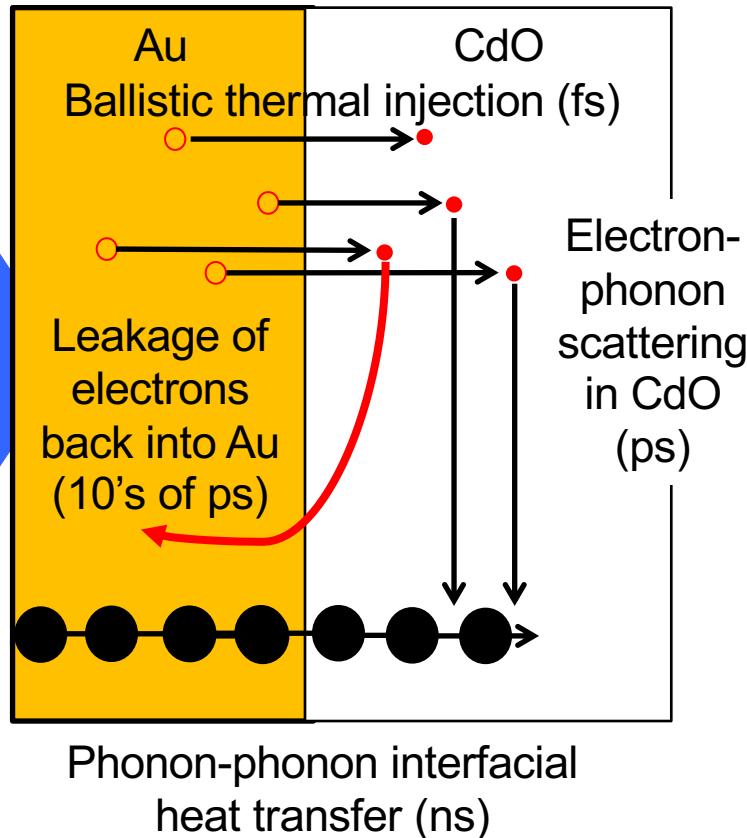
a) Hot electron injection
(Charge transfer)



b) Ballistic thermal injection
(Energy transfer)



Nonequilibrium electrons to control CdO plasmons

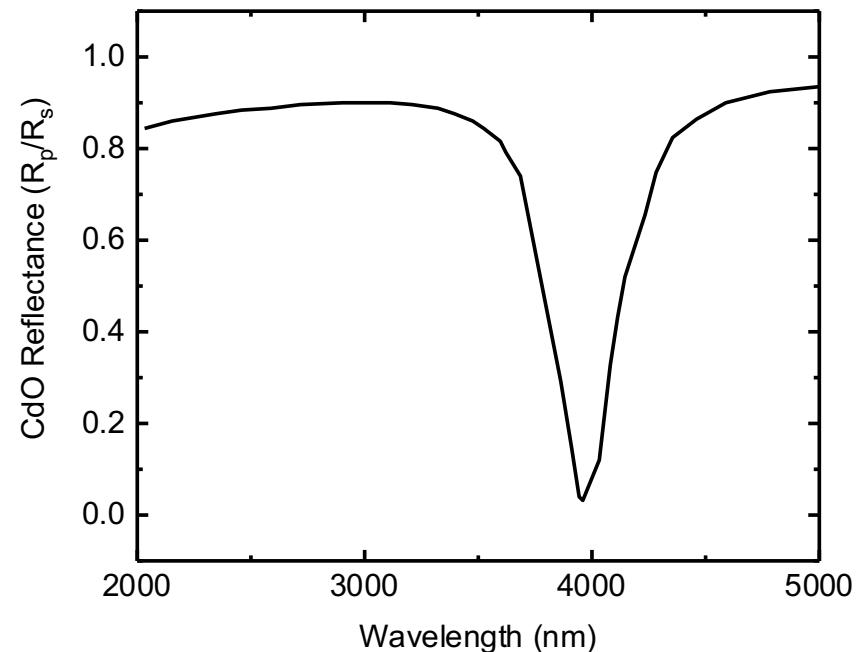
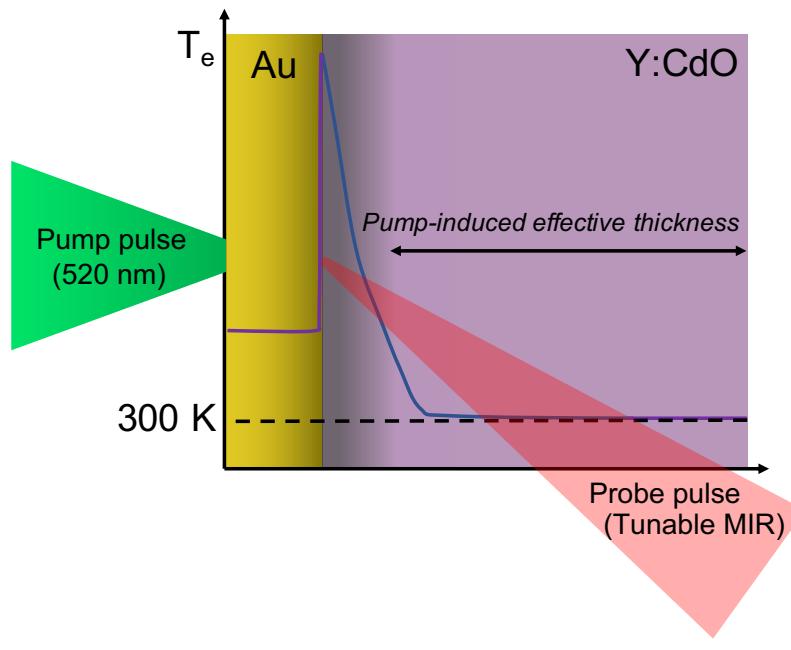


Increasing carrier concentration

Pump electrons in Au, probe plasmon in CdO

How is the IR plasmon response of CdO impacted by ballistic thermal injection?

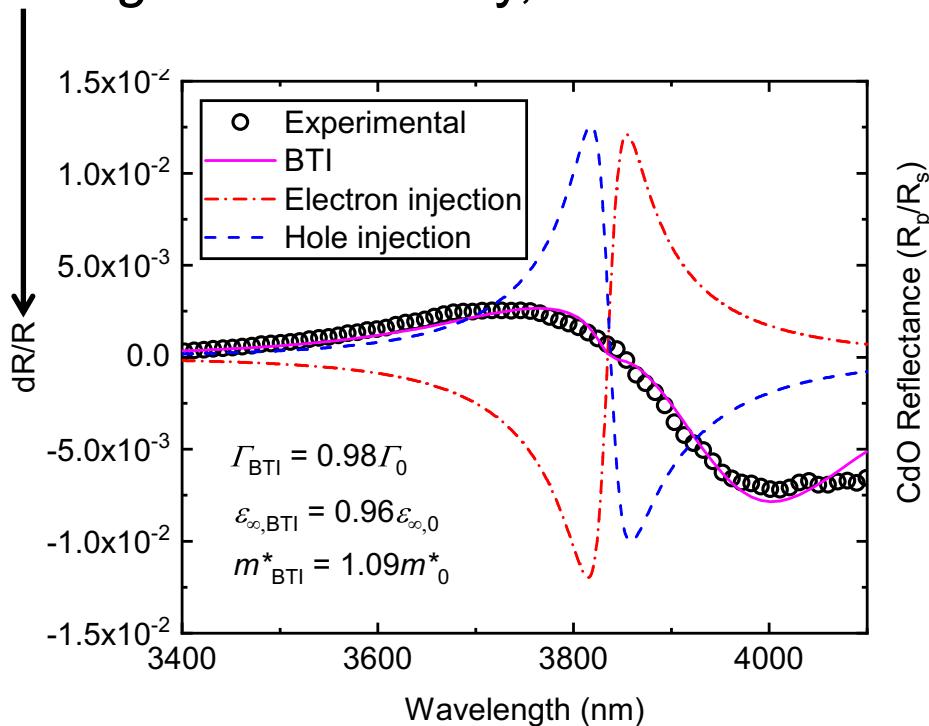
Au/CdO/sapphire absorption response



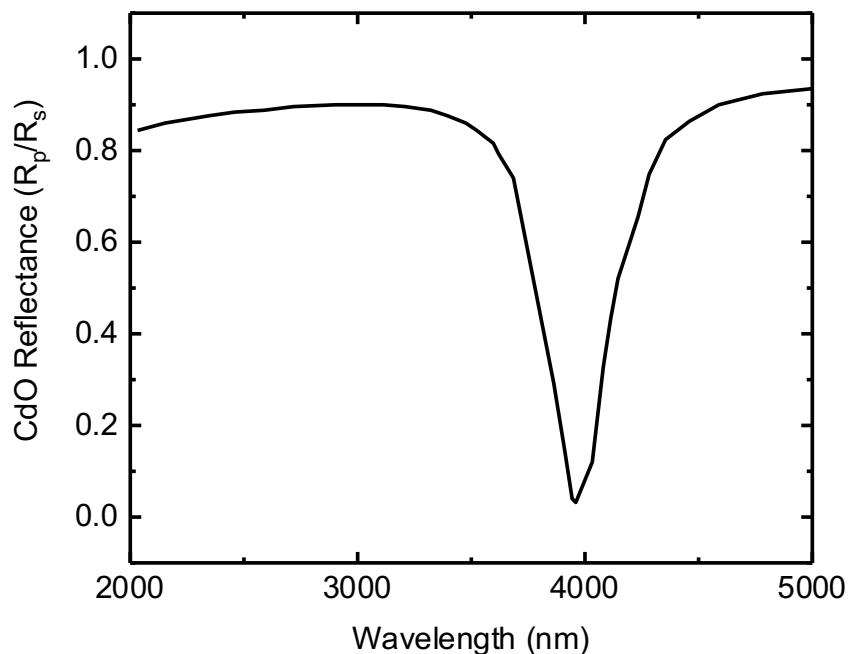
Pump electrons in Au, probe plasmon in CdO

Asymmetric red shift in ENZ plasmon mode due to BTI

Note we are measuring
change in reflectivity, dR

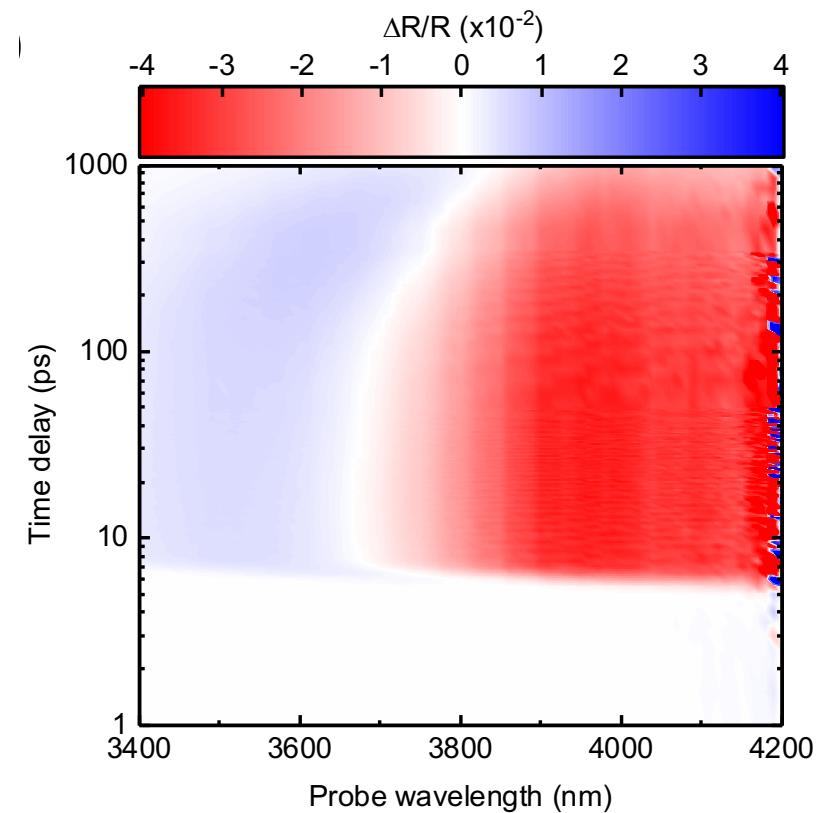
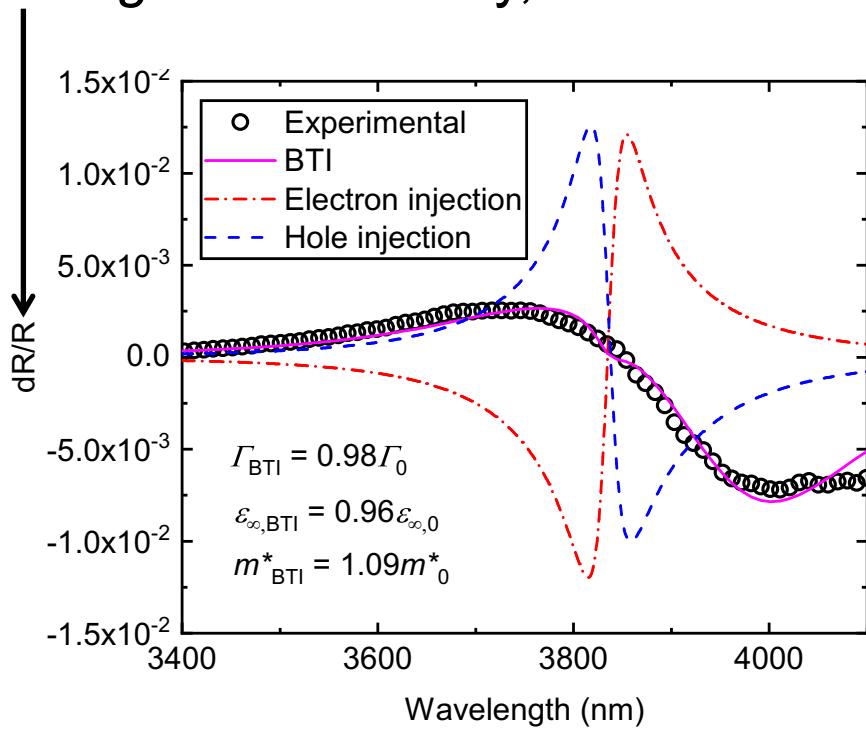


Au/CdO/sapphire absorption response

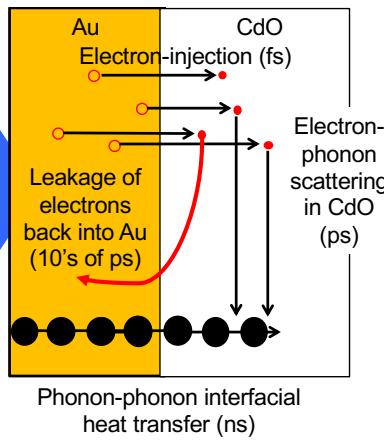


Asymmetric red shift in ENZ plasmon mode due to BTI

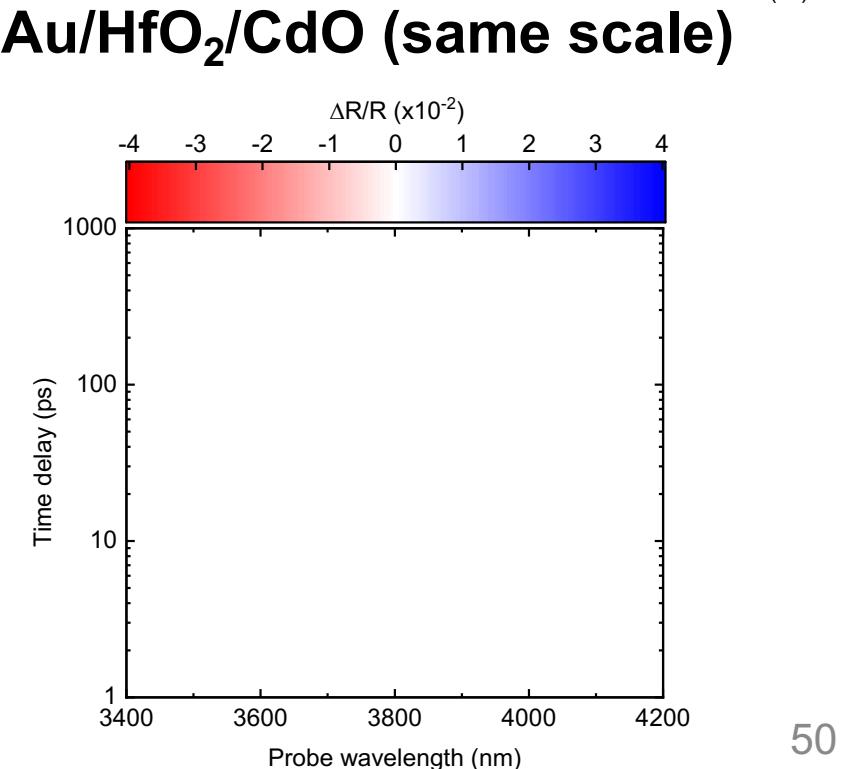
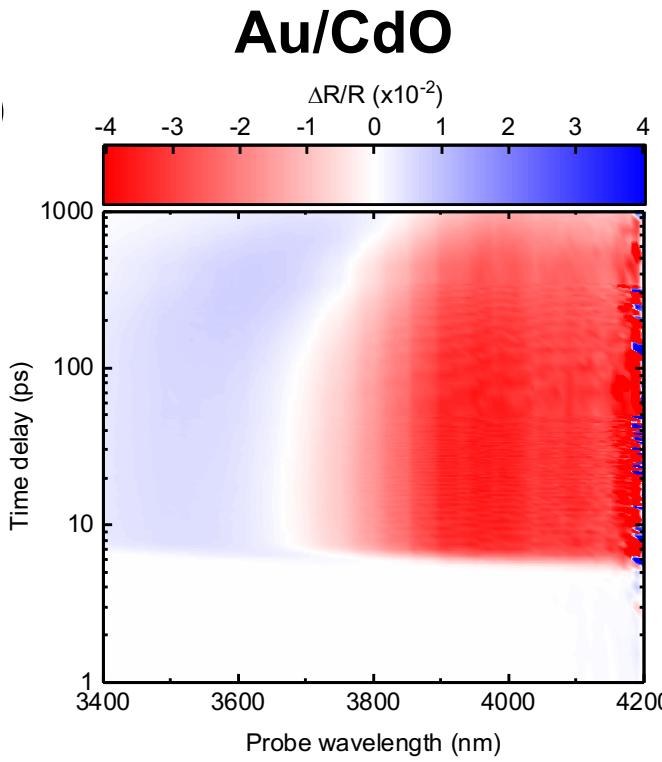
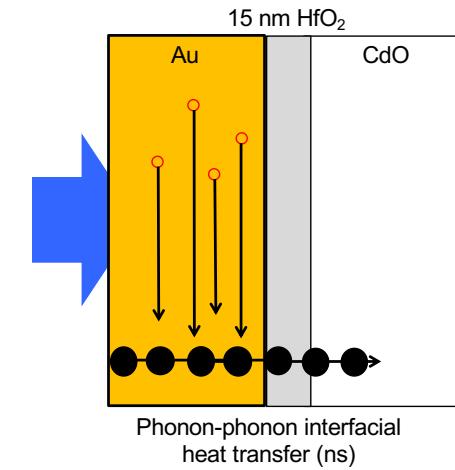
Note we are measuring
change in reflectivity, dR



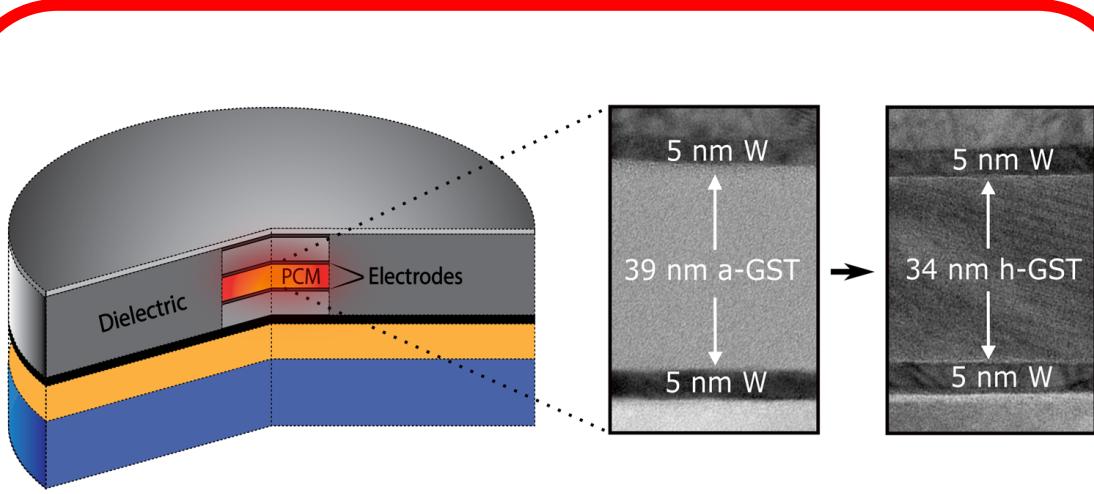
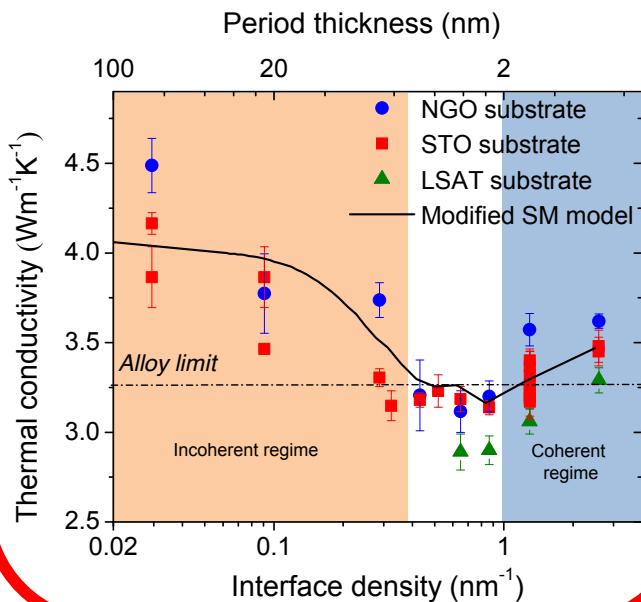
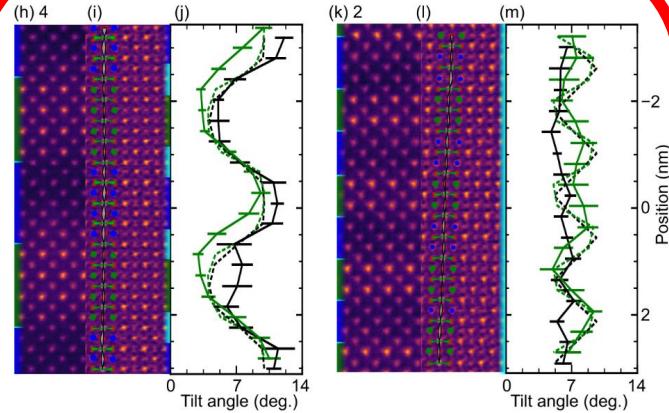
And it's not an optical artifact



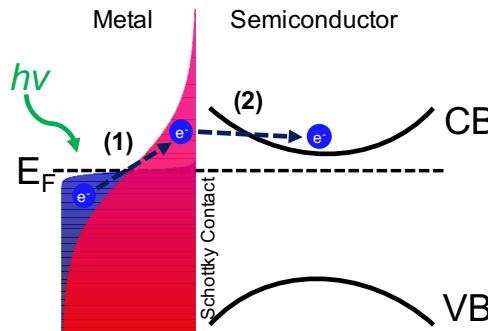
15 nm HfO_2 layer prevents any electron energy from moving from **Au** to **CdO**, resulting in no measurable response



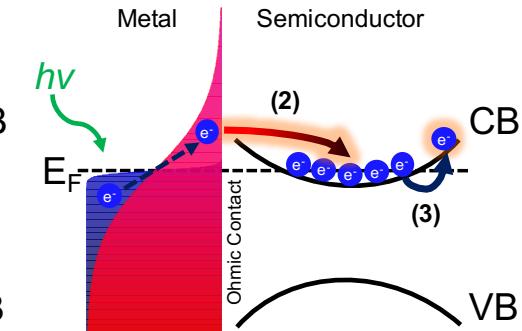
Summary: Interfaces can change the nature and behavior of electron and phonon transport, dictating how they interact with other carriers and impacting thermal transport



a) Hot electron injection
(Charge transfer)

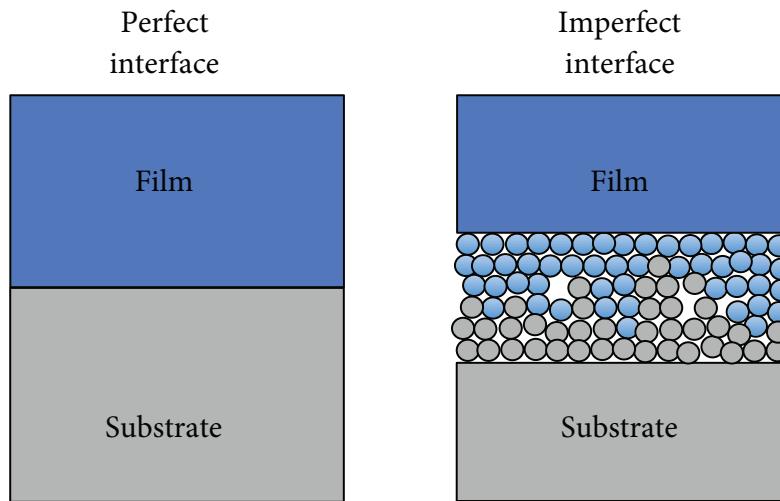


b) Ballistic thermal injection
(Energy transfer)

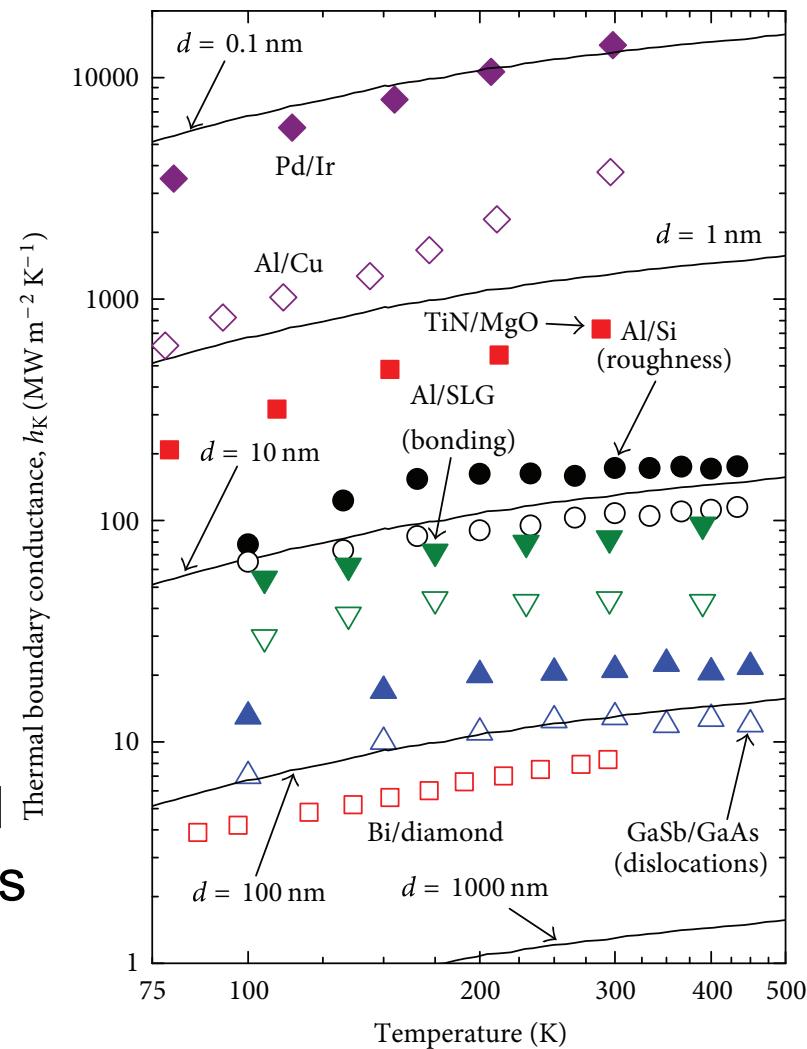


Thermal boundary conductance – quality & carriers matters

Metal/metal = electron dominated
Ultrahigh TBC (ultralow TBR)

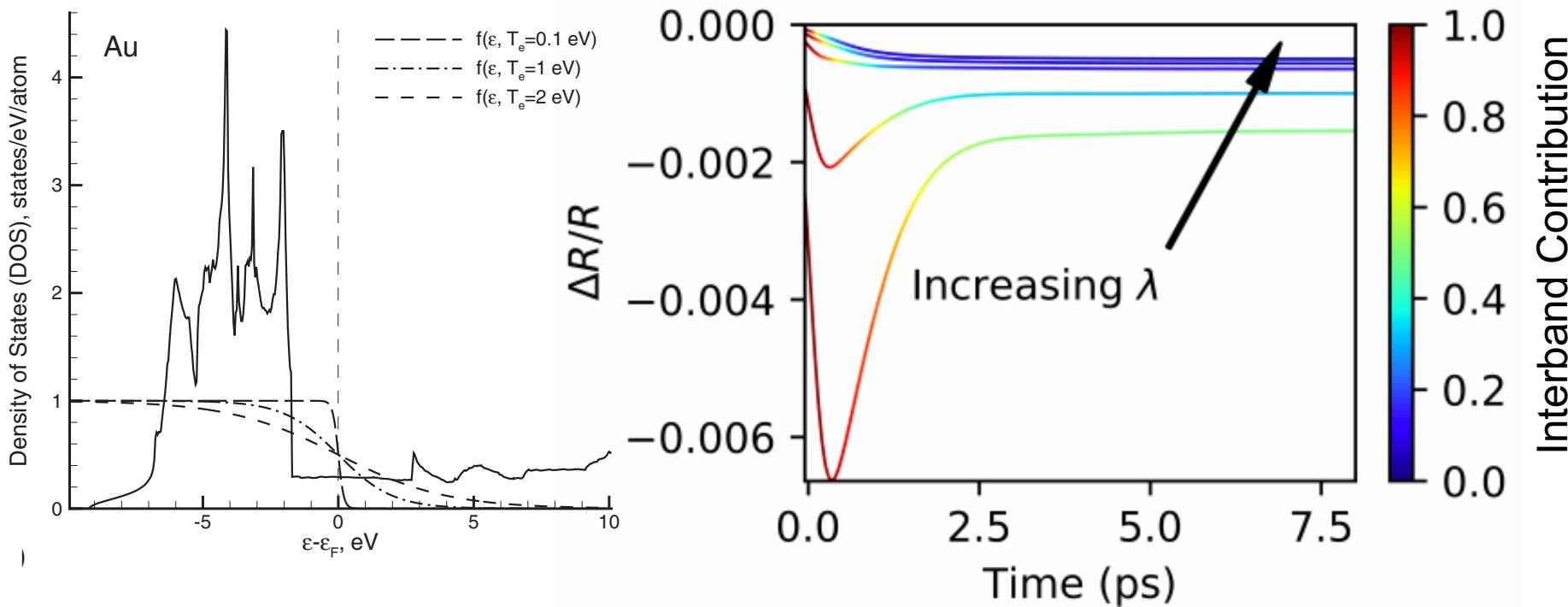


Metal/non-metal = Phonon dominated
High thermal conductivity material does
not necessarily translate to high TBC
(e.g., diamond)



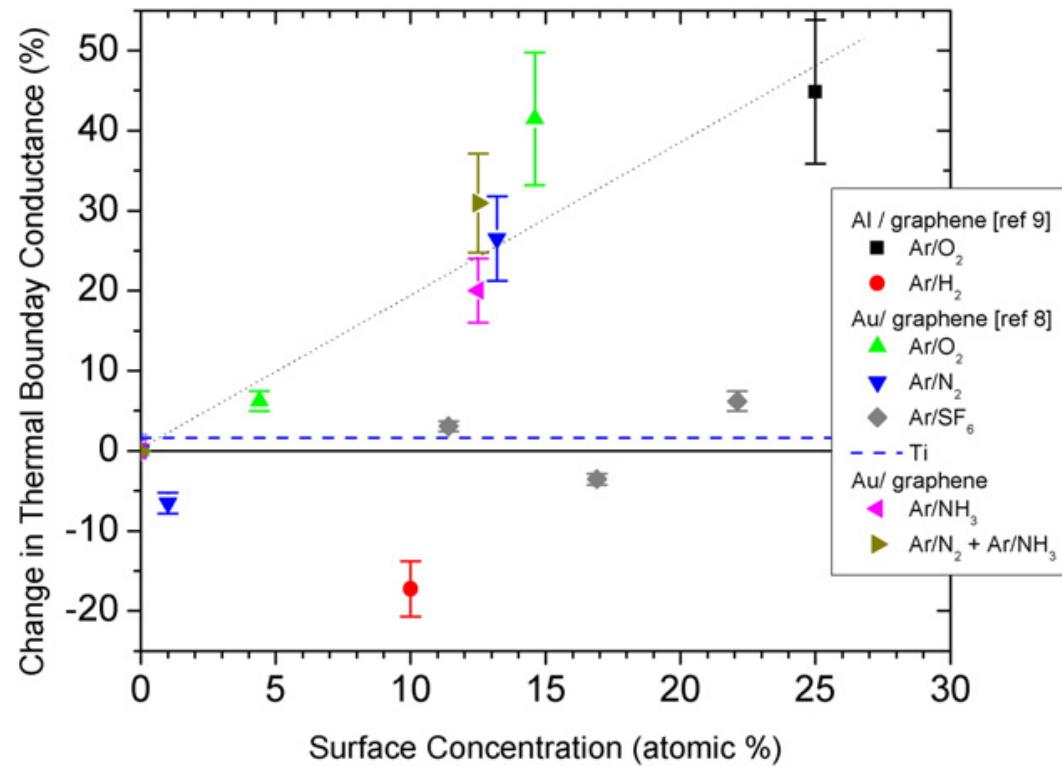
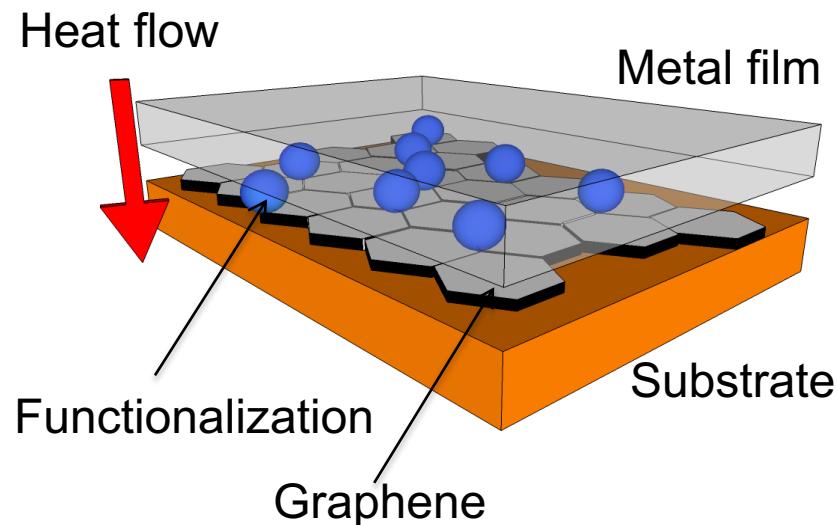
Tunable wavelength probes: turn to the IR

- The stage is set from the earlier works here at UIUC!
- Could our use of visible wavelengths be over complicating things by measuring “aggregate” scattering rates of electrons (including, but not limited to, electron-phonon scattering)?
- Low enough energy should just probe around Fermi energy



Chemistry dictates TBC

Chemical interactions at metal/graphene interfaces controls via plasma treatment can increase TBC



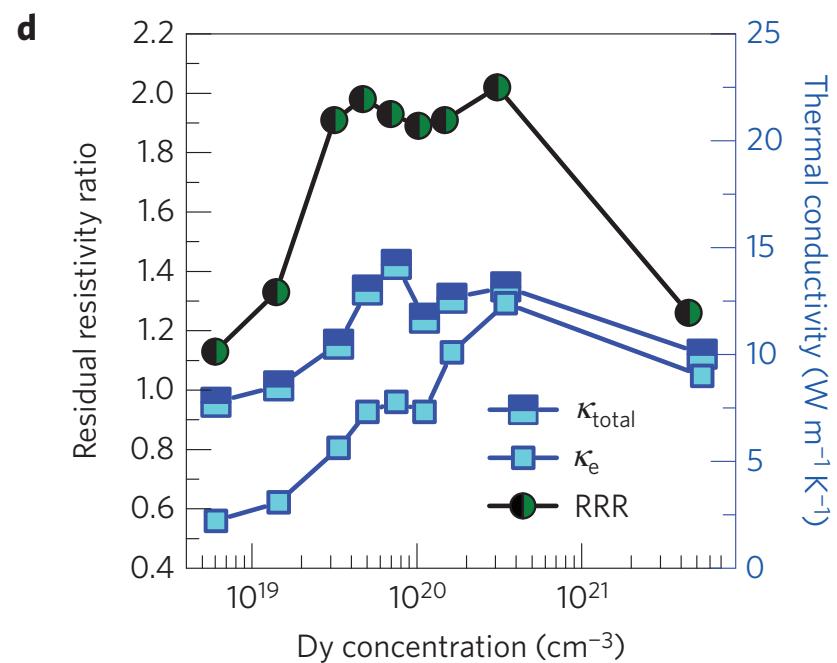
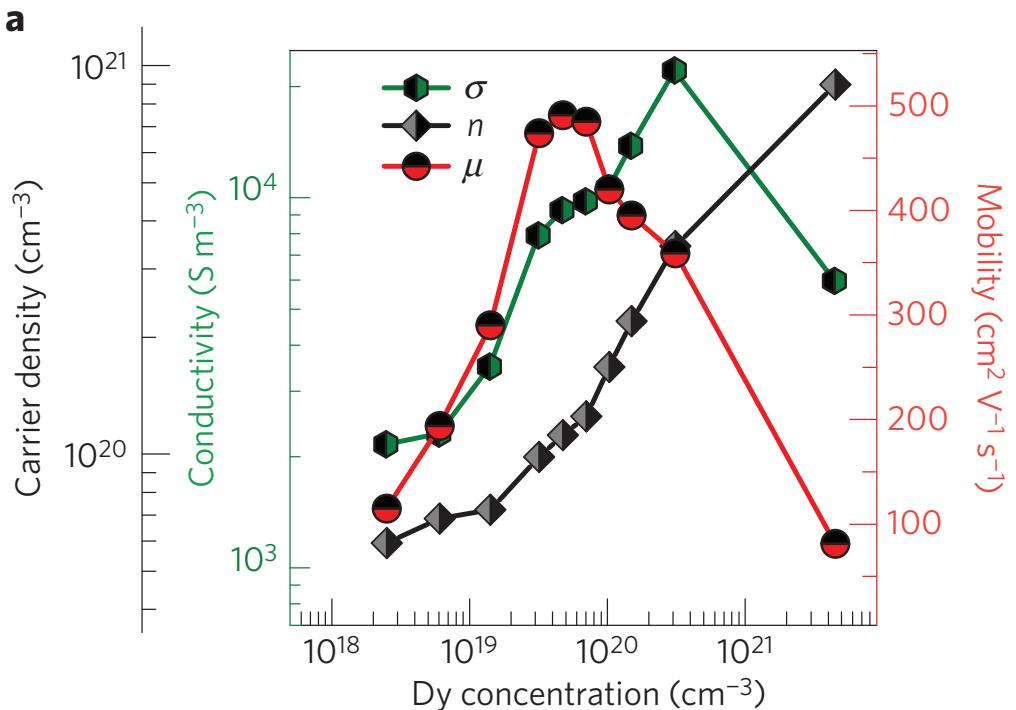
Collaboration with Scott Walton (NRL)

Nano Lett. **12**, 590 (2012)

Nano Lett. **15**, 4876 (2015)

Surf. Coat. & Tech. **314**, 148 (2017)

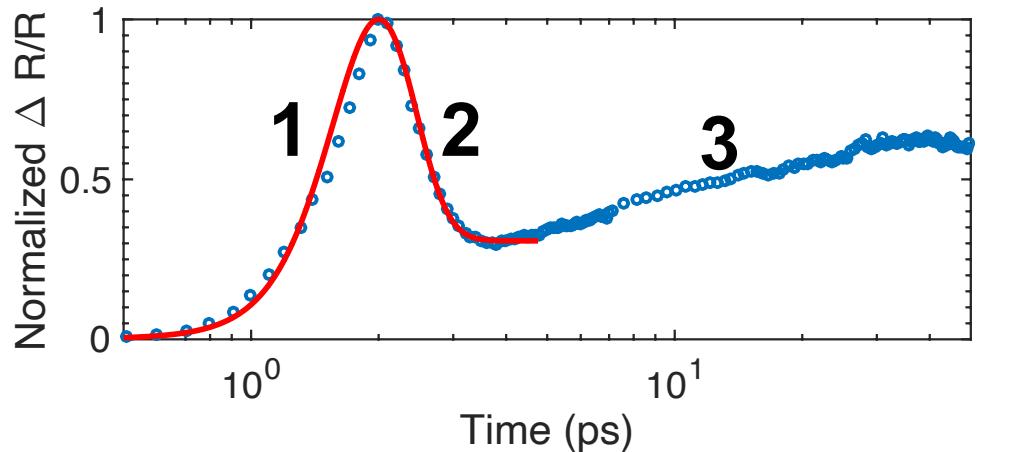
CdO – a gateway for mid-IR plasmonics



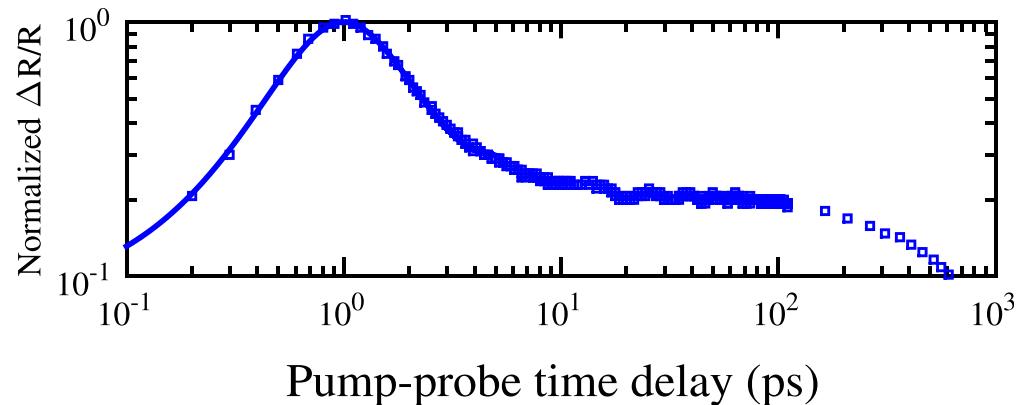
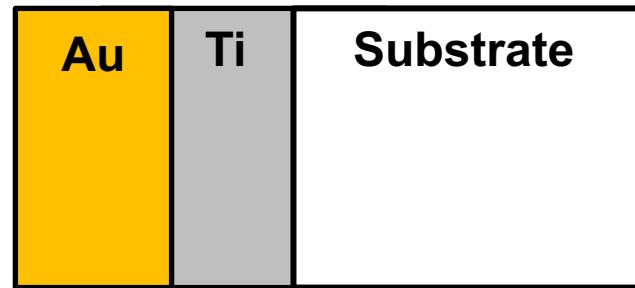
Nat. Mat. **14**, 414
Appl. Phys. Lett. **108**, 021901

TDTR measurements of time scales of noneq. transport

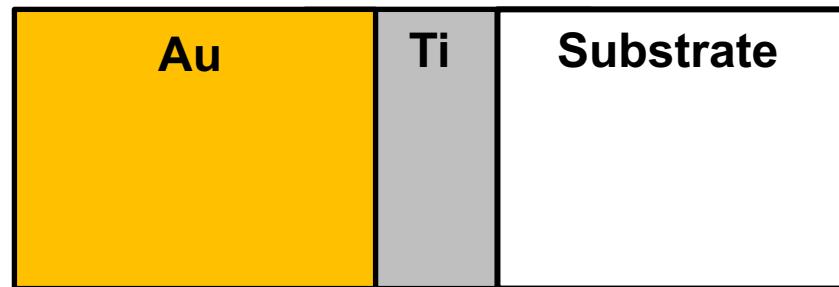
Hypothesis: If Au thickness (d_{Au}) is thicker than electron-phonon mean free path (λ_{ep}), nonequilibrium at interface will be negligible and “back heating” (time regime 3) will not be observed



$$d_{\text{Au}} < \lambda_{\text{ep}}$$

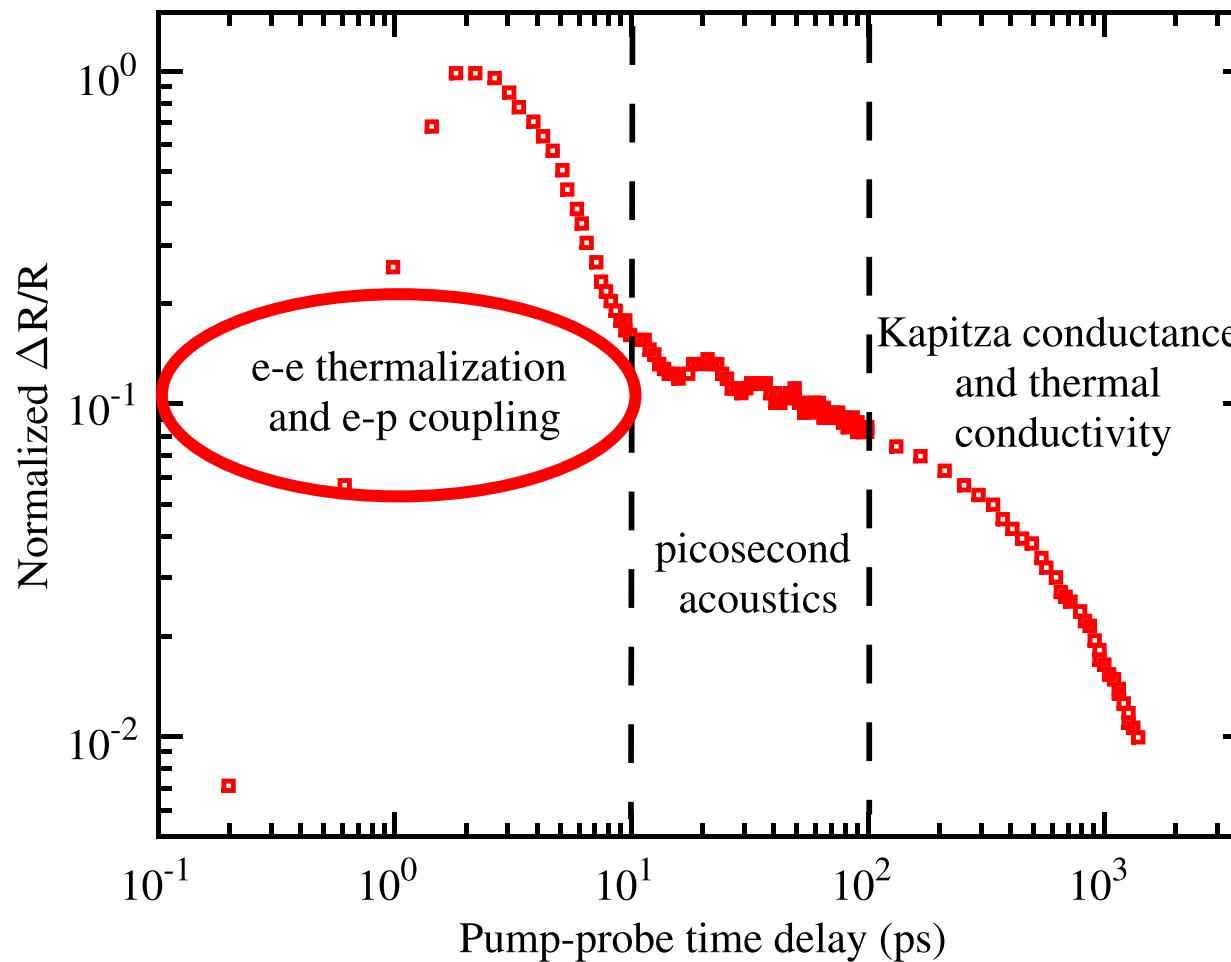


$$d_{\text{Au}} > \lambda_{\text{ep}}$$



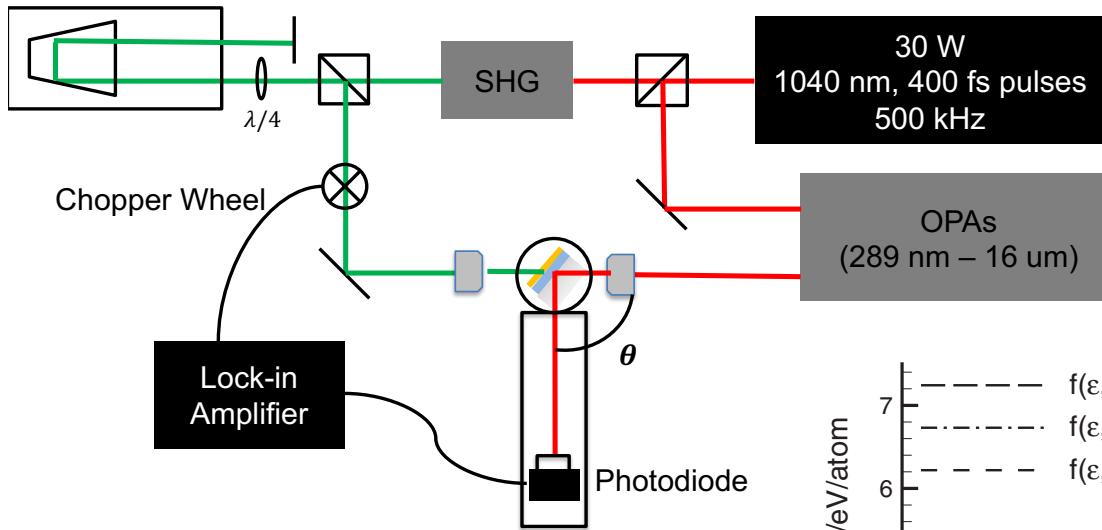
Gain insight with ultrafast electron relaxation

Recall TDTR and the “ultrafast” picosecond time scales



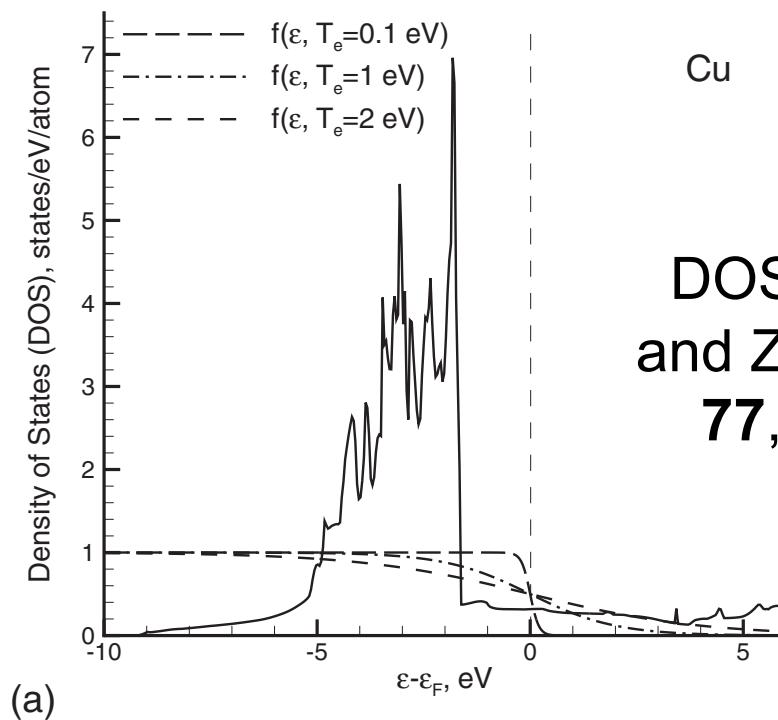
Data from: Giri *et al.* *J. Appl. Phys.* **117**, 105105 (2015)

Wavelength tunable pump-probe into the IR



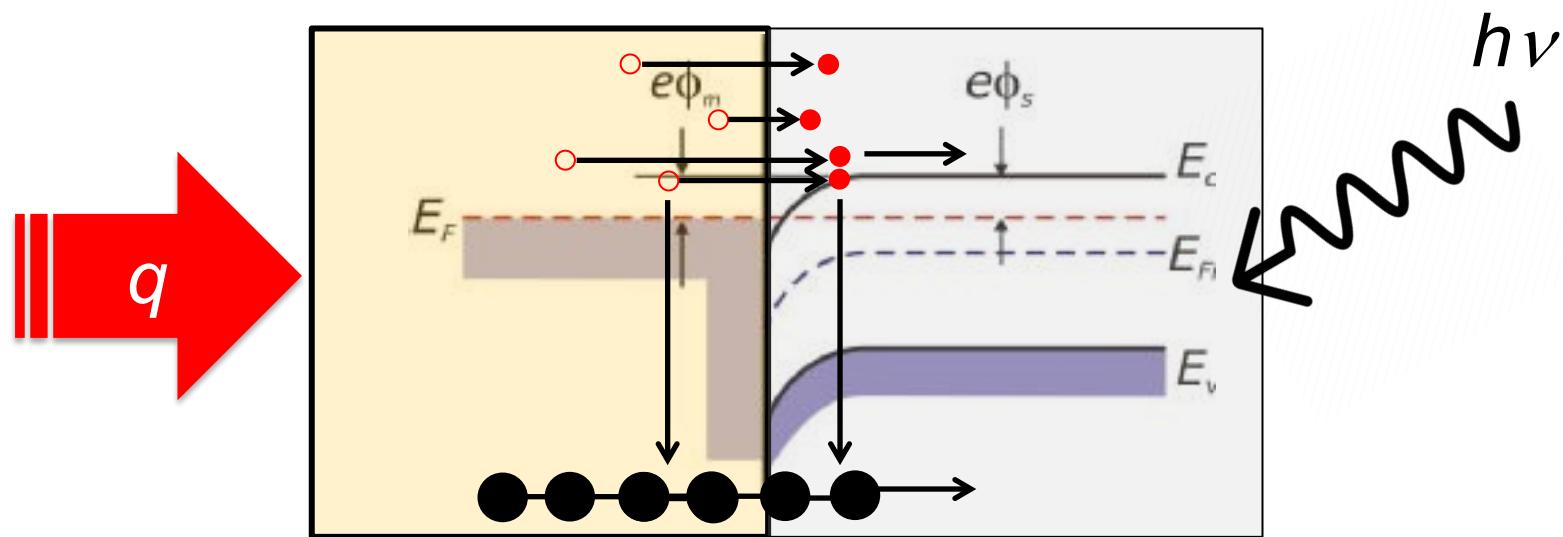
- Ultrafast pump-probe measurement (sub-picosecond resolution)
- Variable wavelength from 288 nm to 16 microns
- High-precision goniometer for angular measurements

Can now optically probe specific electronic transitions



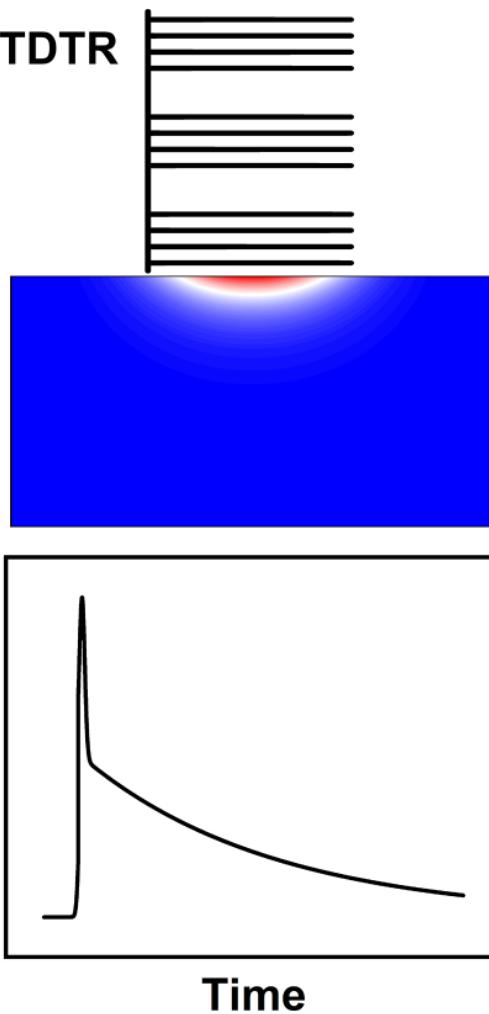
DOS from Lin
and Zhiglei *PRB*
77, 075133

Electron energy transfer at metal/nonmetal interfaces

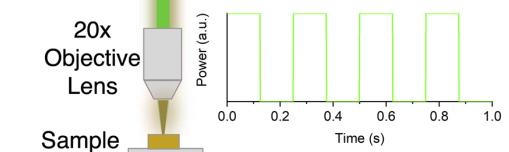
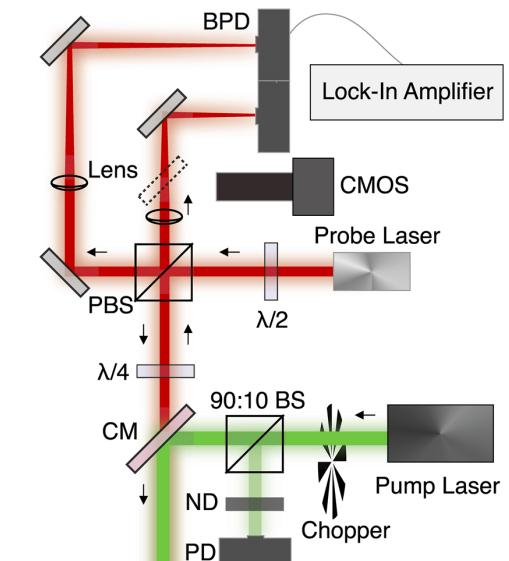
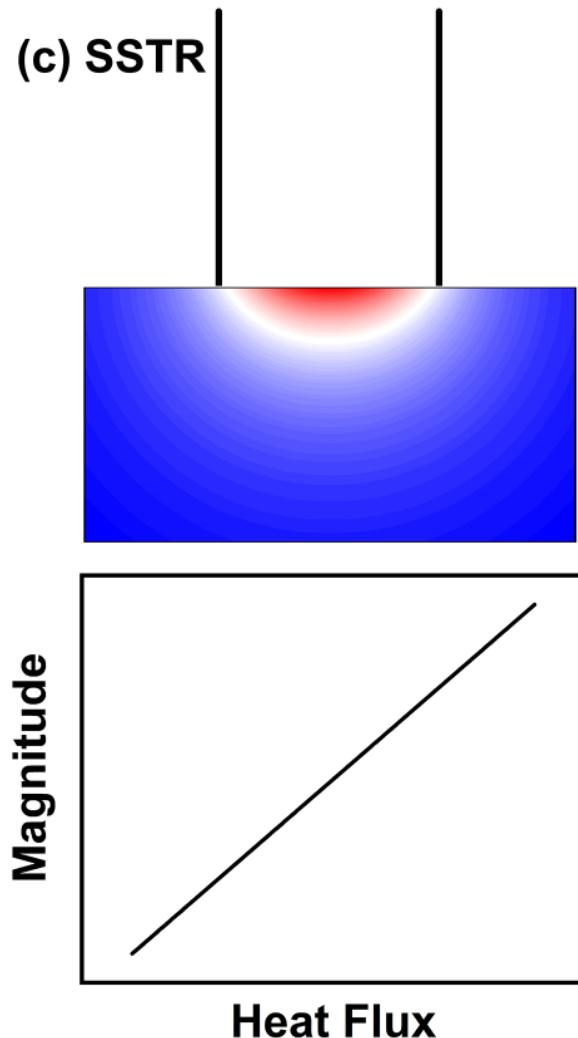


Steady state thermoreflectance: direct measure of κ

(a) TDTR

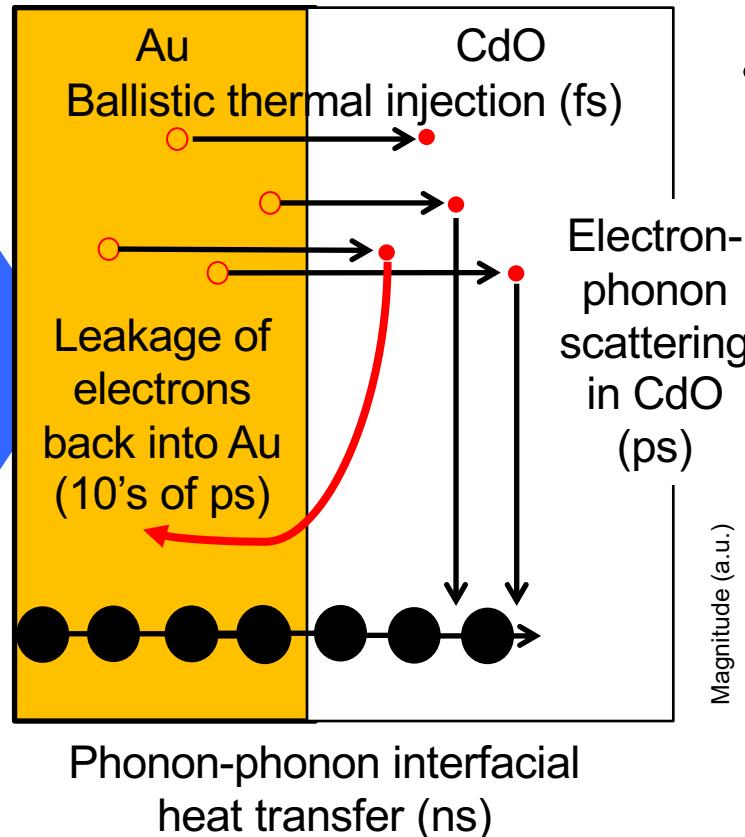


(c) SSTR

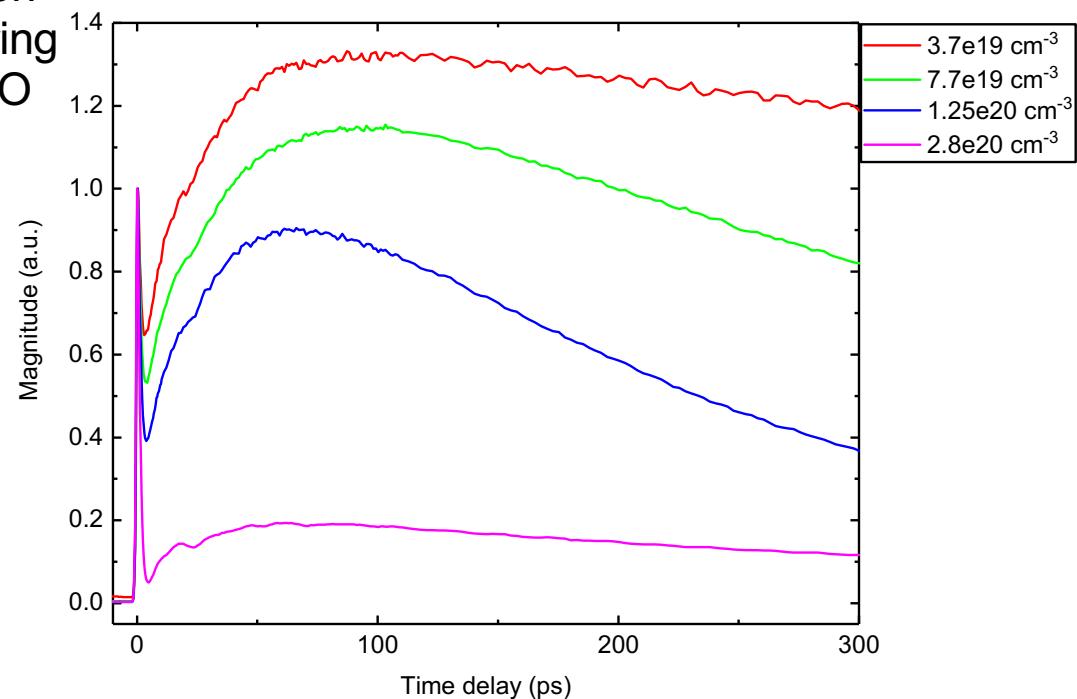


Nonequilibrium processes at Au/CdO interfaces

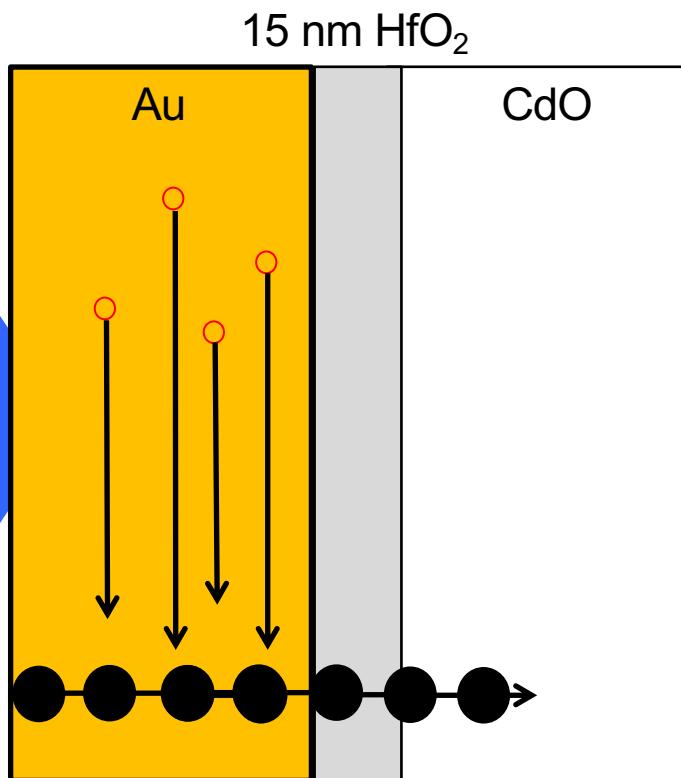
- Doping of CdO dictates amount of “electron leakage” back into Au



- Lower resistivity + higher e-ph coupling in CdO, less electronic back heating into gold contact



Nonequilibrium processes at Au/CdO interfaces



- Transparent buffer layer stops ballistic electrons, but allows light to transmit
- No back-heating observed for any dopant concentration!

